

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182 – FEBRUARY 1997

- Direct Upgrades to TL05x, TL07x, and TL08x BiFET Operational Amplifiers
- Greater Than 2× Bandwidth (10 MHz) and 3× Slew Rate (45 V/ μ s) Than TL08x
- On-Chip Offset Voltage Trimming for Improved DC Performance
- Wider Supply Rails Increase Dynamic Signal Range to ±19 V

description

The TLE208x series of JFET-input operational amplifiers more than double the bandwidth and triple the slew rate of the TL07x and TL08x families of BiFET operational amplifiers. The TLE208x also have wider supply-voltage rails, increasing the dynamic-signal range for BiFET circuits to ±19 V. On-chip zener trimming of offset voltage yields precision grades for greater accuracy in dc-coupled applications. The TLE208x are pin-compatible with lower performance BiFET operational amplifiers for ease in improving performance in existing designs.

BiFET operational amplifiers offer the inherently higher input impedance of the JFET-input transistors, without sacrificing the output drive associated with bipolar amplifiers. This makes these amplifiers better suited for interfacing with high-impedance sensors or very low level ac signals. They also feature inherently better ac response than bipolar or CMOS devices having comparable power consumption.

Because BiFET operational amplifiers are designed for use with dual power supplies, care must be taken to observe common-mode input-voltage limits and output voltage swing when operating from a single supply. DC biasing of the input signal is required and loads should be terminated to a virtual ground node at mid-supply. Texas Instruments TLE2426 integrated virtual ground generator is useful when operating BiFET amplifiers from single supplies.

The TLE208x are fully specified at ±15 V and ±5 V. For operation in low-voltage and/or single-supply systems, Texas Instruments LinCMOS™ families of operational amplifiers (TLC- and TLV-prefix) are recommended. When moving from BiFET to CMOS amplifiers, particular attention should be paid to slew rate and bandwidth requirements and output loading.

For BiFET circuits requiring low noise and/or tighter dc precision, the TLE207x offer the same ac response as the TLE208x with more stringent dc and noise specifications.



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TLE2081 AVAILABLE OPTIONS

T _A	V _{I0max} AT 25°C	PACKAGED DEVICES				CHIP FORM (Y)
		SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	
0°C to 70°C	3 mV 6 mV	TLE2081ACD TLE2081CD	—	—	TLE2081ACP TLE2081CP	— TLE2081Y
–55°C to 125°C	3 mV 6 mV	—	TLE2081AMFK TLE2081MFK	TLE2081AMJG TLE2081MJG	—	—

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLE2081ACDR).

‡ Chip forms are tested at T_A = 25°C only.

TLE2082 AVAILABLE OPTIONS

T _A	V _{I0max} AT 25°C	PACKAGED DEVICES				CHIP FORM (Y)
		SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	
0°C to 70°C	4 mV 7 mV	TLE2082ACD TLE2082CD	—	—	TLE2082ACP TLE2082CP	—
–40°C to 85°C	4 mV 7 mV	TLE2082AID TLE2082ID	—	—	TLE2082AIP TLE2082IP	TLE2082Y
–55°C to 125°C	4 mV 7 mV	TLE2082AMD TLE2082MD	TLE2082AMFK TLE2082MFK	TLE2082AMJG TLE2082MJG	TLE2082AMP TLE2082MP	—

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLE2082ACDR).

‡ Chip forms are tested at T_A = 25°C only.

TLE2084 AVAILABLE OPTIONS

T _A	V _{I0max} AT 25°C	PACKAGED DEVICES				CHIP FORM (Y)
		SMALL OUTLINE (DW)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)	
0°C to 70°C	4 mV 7 mV	TLE2084ACDW TLE2084CDW	—	—	TLE2084ACN TLE2084CN	— TLE2084Y
–55°C to 125°C	4 mV 7 mV	—	TLE2084AMFK TLE2084MFK	TLE2084AMJ TLE2084MJ	—	—

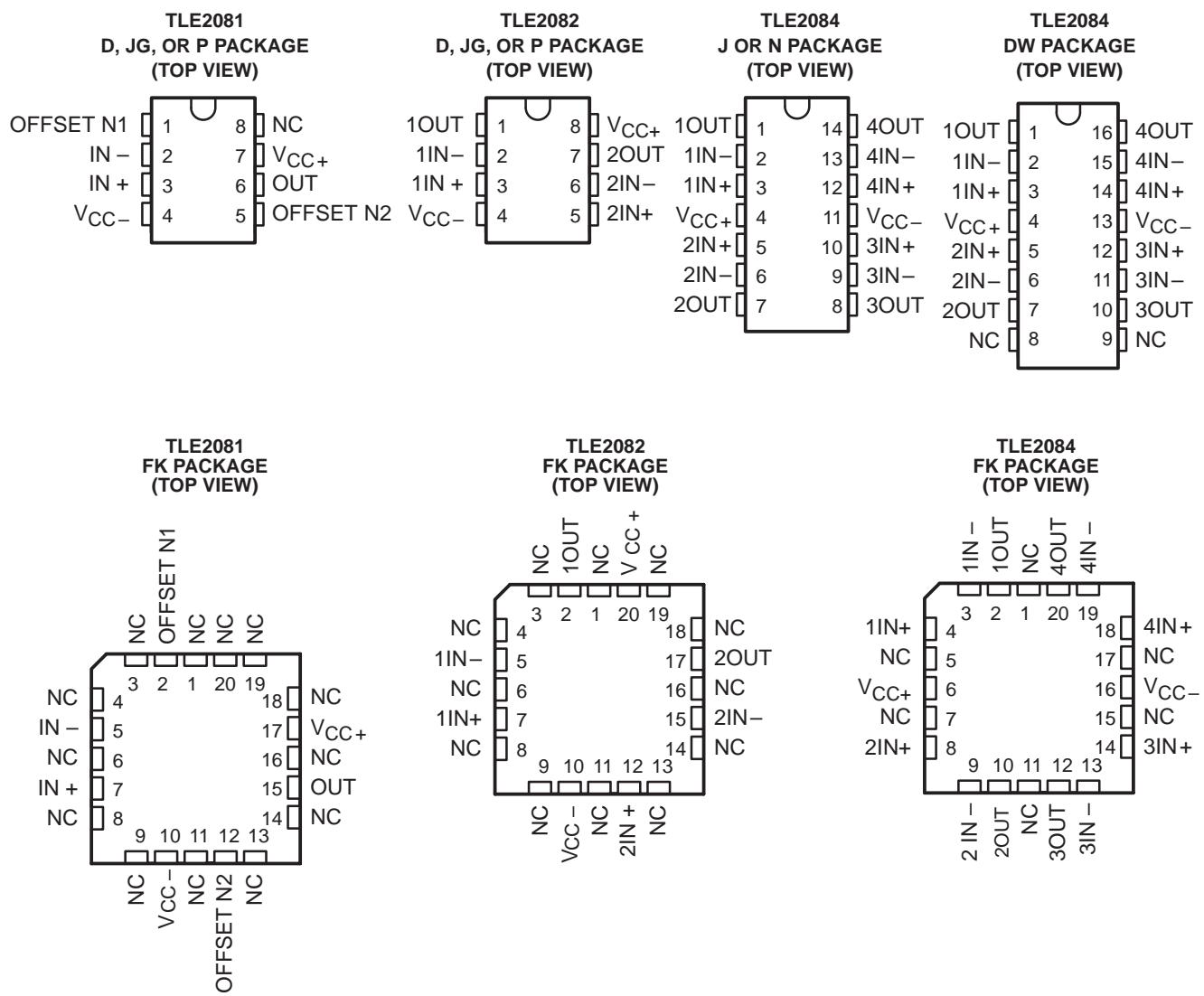
† The DW packages are available taped and reeled. Add R suffix to device type (e.g., TLE2084ACDWR).

‡ Chip forms are tested at T_A = 25°C only.



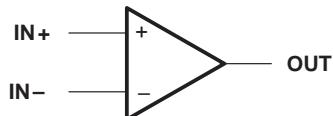
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NC – No internal connection

symbol

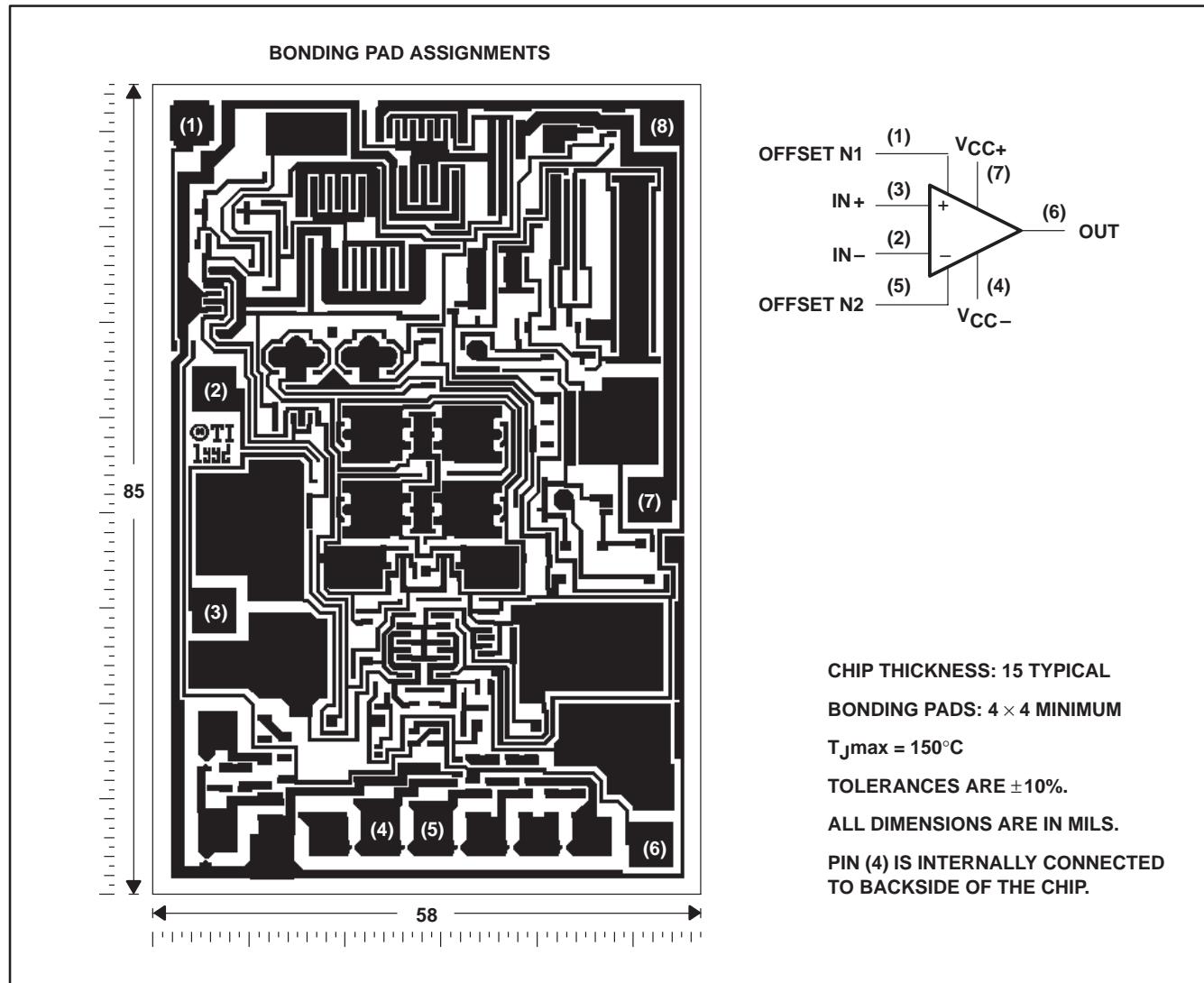


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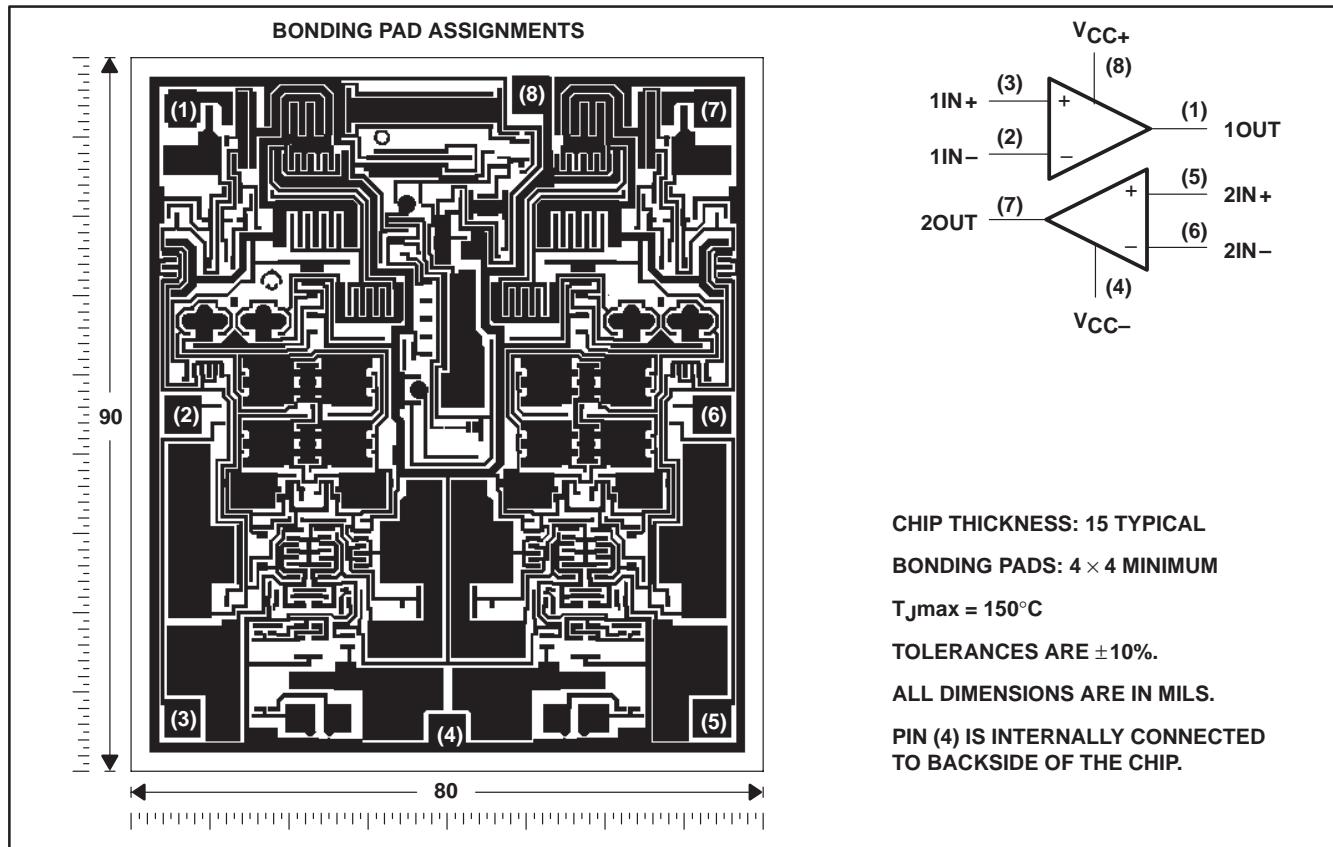
TLE2081Y chip information

This chip, when properly assembled, displays characteristics similar to the TLE2081. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.



TLE2082Y chip information

This chip, when properly assembled, displays characteristics similar to the TLE2082. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.

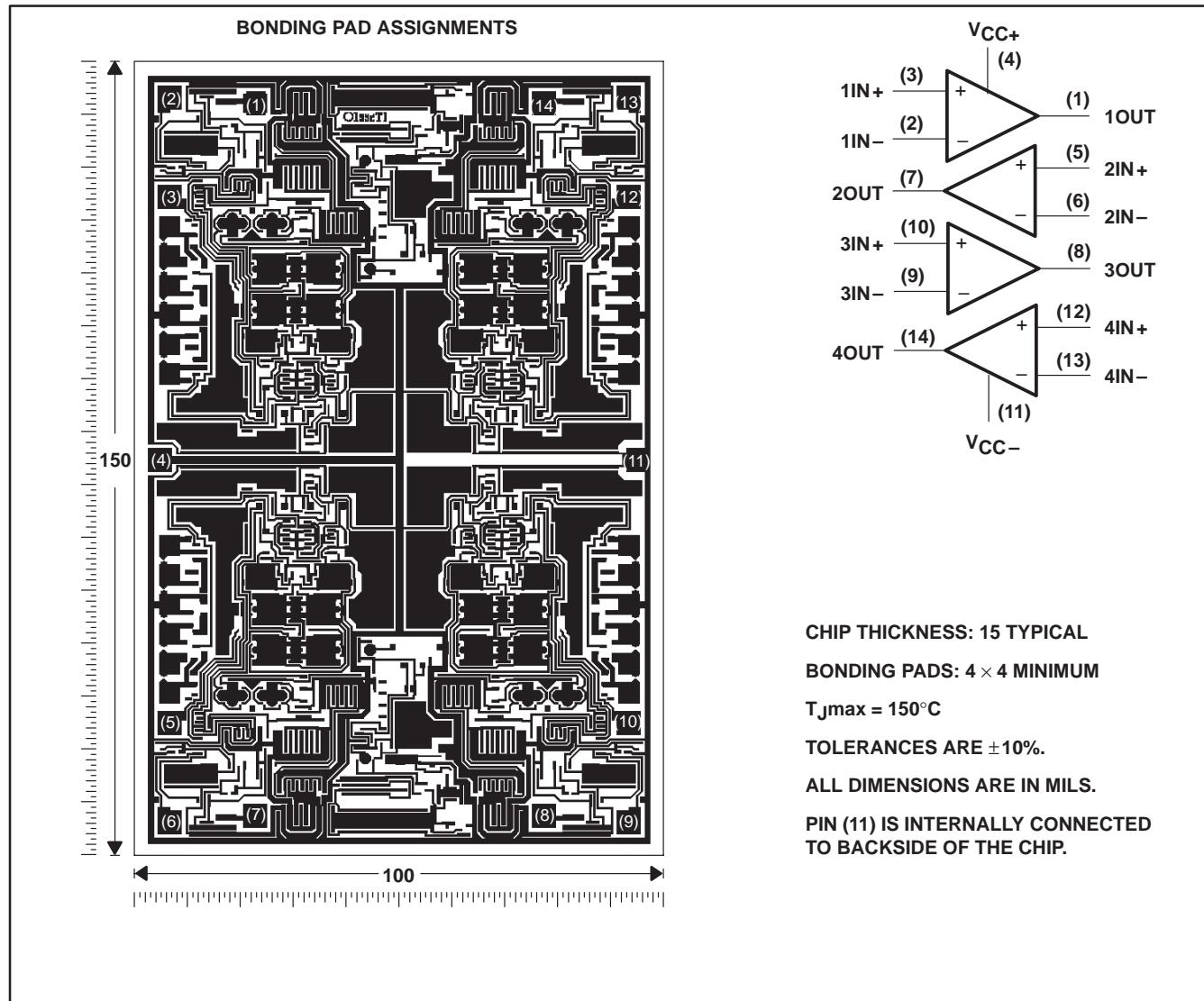


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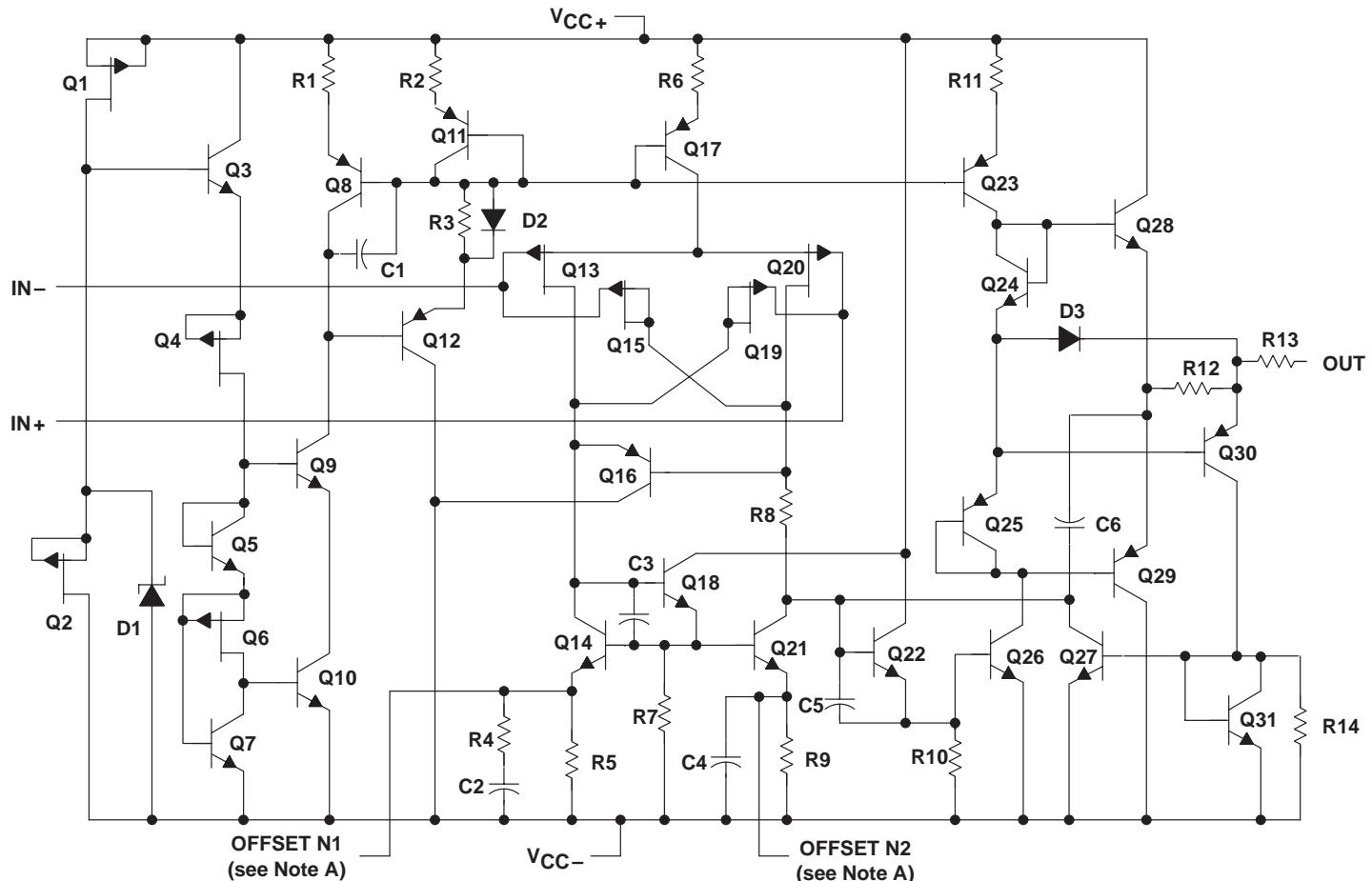
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TLE2084Y chip information

This chip, when properly assembled, displays characteristics similar to the TLE2084. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.



equivalent schematic (each channel)



NOTE A: OFFSET N1 AND OFFSET N2 are only available on the TLE2081x devices.

ACTUAL DEVICE COMPONENT COUNT			
COMPONENT	TLE2081	TLE2082	TLE2084
Transistors	33	57	114
Resistors	25	37	74
Diodes	8	5	10
Capacitors	6	11	22

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{CC+} (see Note 1)	19 V
Supply voltage, V_{CC-} (see Note 1)	-19 V
Differential input voltage range, V_{ID} (see Note 2)	V_{CC+} to V_{CC-}
Input voltage range, V_I (any input)	V_{CC+} to V_{CC-}
Input current, I_I (each input)	± 1 mA
Output current, I_O (each output)	± 80 mA
Total current into V_{CC+}	160 mA
Total current out of V_{CC-}	160 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	-40°C to 85°C
M suffix	-55°C to 125°C
Storage temperature range	-65°C to 150°C
Case temperature for 60 seconds: FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DW or N package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J package	300°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
 2. Differential voltages are at IN+ with respect to IN-.
 3. The output can be shorted to either supply. Temperatures and/or supply voltages must be limited to ensure that the maximum dissipation rate is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING		$T_A = 125^\circ\text{C}$ POWER RATING
				MIN	MAX	
D	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW	
DW	1025 mW	8.2 mW/°C	656 mW	533 mW	205 mW	
FK	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW	
J	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW	
JG	1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW	
N	1150 mW	9.2 mW/°C	736 mW	598 mW	230 mW	
P	1000 mW	8.0 mW/°C	640 mW	344 mW	200 mW	

recommended operating conditions

		C SUFFIX		I SUFFIX		M SUFFIX		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
Supply voltage, $V_{CC\pm}$		± 2.25	± 19	± 2.25	± 19	± 2.25	± 19	V
Common-mode input voltage, V_{IC}	$V_{CC\pm} = \pm 5$ V	-0.9	5	-0.8	5	-0.8	5	V
	$V_{CC\pm} = \pm 15$ V	-10.9	15	-10.8	15	-10.8	15	
Operating free-air temperature, T_A		0	70	-40	85	-55	125	°C

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TLE2081C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2081C			TLE2081AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	25°C	0.34	6	0.3	3			mV	
		Full range		8			5			
		Full range	3.2	29		3.2	29			
αV_{IO} Temperature coefficient of input offset voltage									$\mu V/^{\circ}C$	
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4	25°C	5	100		5	100		nA	
		Full range		1.4			1.4			
I_{IB} Input bias current		25°C	15	175		15	175		nA	
		Full range		5			5			
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9		V	
		Full range	5 to -0.9			5 to -0.9				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	3.8	4.1		3.8	4.1		V	
		Full range	3.7			3.7				
	$I_O = -2 \text{ mA}$	25°C	3.5	3.9		3.5	3.9			
		Full range	3.4			3.4				
	$I_O = -20 \text{ mA}$	25°C	1.5	2.3		1.5	2.3			
		Full range	1.5			1.5				
	$I_O = 200 \mu A$	25°C	-3.5	-4.2		-3.5	-4.2		V	
		Full range	-3.4			-3.4				
V_{OM-} Maximum negative peak output voltage swing	$I_O = 2 \text{ mA}$	25°C	-3.7	-4.1		-3.7	-4.1			
		Full range	-3.6			-3.6				
	$I_O = 20 \text{ mA}$	25°C	-1.5	-2.4		-1.5	-2.4			
		Full range	-1.5			-1.5				
	$R_L = 600 \Omega$	25°C	80	91		80	91		dB	
		Full range	79			79				
	$R_L = 2 \text{ k}\Omega$	25°C	90	100		90	100			
		Full range	89			89				
	$R_L = 10 \text{ k}\Omega$	25°C	95	106		95	106			
		Full range	94			94				
r_i Input resistance	$V_{IC} = 0$	25°C	1012			1012			Ω	
c_i Input capacitance	$V_{IC} = 0$, See Figure 5	25°C Common mode	11			11			pF	
		25°C Differential	2.5			2.5				
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	70	89		70	89		dB	
		Full range	68			68				
k_{SVR} Supply-voltage rejection ratio($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	82	99		82	99		dB	
		Full range	80			80				

† Full range is 0°C to 70°C.

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TLE2081C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2081C			TLE2081AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current $V_O = 0$, No load	25°C	1.35	1.6	2.2	1.35	1.6	2.2	mA
		Full range			2.2			2.2	
I_{OS}	Short-circuit output current $V_O = 0$	$V_{ID} = 1$ V $V_{ID} = -1$ V	25°C		-35		-35		mA
					45		45		

† Full range is 0°C to 70°C.

TLE2081C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2081C			TLE2081AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate $V_O(PP) = \pm 2.3$ V, $AVD = -1$, $R_L = 2$ kΩ, $C_L = 100$ pF, See Figure 1	25°C		35			35		V/μs
		Full range		23			23		
		25°C		38			38		V/μs
		Full range		23			23		
t_s	Settling time $AVD = -1$, 2-V step, $R_L = 1$ kΩ, $C_L = 100$ pF	To 10 mV To 1 mV	25°C		0.25		0.25		μs
					0.4		0.4		
V_n	Equivalent input noise voltage	$f = 10$ Hz $f = 10$ kHz	25°C		28		28		nV/√Hz
					11.6		11.6		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20$ Ω, See Figure 3	$f = 10$ Hz to 10 kHz $f = 0.1$ Hz to 10 Hz	25°C			6		μV
							0.6		
I_n	Equivalent input noise current	$V_{IC} = 0$, $f = 10$ kHz	25°C		2.8		2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_O(PP) = 5$ V, $AVD = 10$, $f = 1$ kHz, $R_L = 2$ kΩ, $R_S = 25$ Ω	25°C		0.013%		0.013%		
B_1	Unity-gain bandwidth	$V_I = 10$ mV, $R_L = 2$ kΩ, $C_L = 25$ pF, See Figure 2	25°C		9.4		9.4		MHz
B_{OM}	Maximum output-swing bandwidth	$V_O(PP) = 4$ V, $AVD = -1$, $R_L = 2$ kΩ, $C_L = 25$ pF	25°C		2.8		2.8		MHz
ϕ_m	Phase margin at unity gain	$V_I = 10$ mV, $R_L = 2$ kΩ, $C_L = 25$ pF, See Figure 2	25°C		56°		56°		

† Full range is 0°C to 70°C.



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TLE2081C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2081C			TLE2081AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	25°C	0.49	6	0.47	3	0.47	3	mV	
		Full range		8		5		5		
		Full range	3.2	29		3.2	29			
αV_{IO} Temperature coefficient of input offset voltage									$\mu V/^{\circ}C$	
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4	25°C	6	100		6	100		nA	
		Full range		1.4		1.4		1.4		
I_{IB} Input bias current		25°C	20	175		20	175		nA	
		Full range		5		5		5		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9		V	
		Full range	15 to -10.9			15 to -10.9				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	13.8	14.1		13.8	14.1		V	
		Full range	13.7			13.7				
	$I_O = -2 mA$	25°C	13.5	13.9		13.5	13.9			
		Full range	13.4			13.4				
	$I_O = -20 mA$	25°C	11.5	12.3		11.5	12.3			
		Full range	11.5			11.5				
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-13.8	-14.2		-13.8	-14.2		V	
		Full range	-13.7			-13.7				
	$I_O = 2 mA$	25°C	-13.5	-14		-13.5	-14			
		Full range	-13.4			-13.4				
	$I_O = 20 mA$	25°C	-11.5	-12.4		-11.5	-12.4			
		Full range	-11.5			-11.5				
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 V$	$R_L = 600 \Omega$	25°C	80	96	80	96		dB	
			Full range	79		79				
		$R_L = 2 k\Omega$	25°C	90	109	90	109			
		$R_L = 10 k\Omega$	Full range	89		89				
			25°C	95	118	95	118			
			Full range	94		94				
r_i Input resistance	$V_{IC} = 0$	25°C	1012			1012			Ω	
c_i Input capacitance	$V_{IC} = 0$, See Figure 5	Common mode	25°C	7.5		7.5			pF	
		Differential	25°C	2.5		2.5				
z_o Open-loop output impedance	$f = 1 MHz$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	80	98		80	98		dB	
		Full range	79			79				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5 V$ to $\pm 15 V$, $V_O = 0$, $R_S = 50 \Omega$	25°C	82	99		82	99		dB	
		Full range	80			81				

[†] Full range is 0°C to 70°C.



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TLE2081C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2081C			TLE2081AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.7	2.2	1.35	1.7	2.2	mA
		Full range			2.2			2.2	
I_{OS} Short-circuit output current	$V_O = 0$	25°C	-30	-45		-30	-45		mA
			$V_{ID} = 1$ V	30	48	30	48		
[†] Full range is 0°C to 70°C.									

TLE2081C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2081C			TLE2081AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_O(PP) = 10$ V, $A_{VD} = -1$, $R_L = 2$ kΩ, $C_L = 100$ pF, See Figure 1	25°C	30	40	30	40		V/μs
			Full range	27		27			
SR-	Negative slew rate		25°C	30	45	30	45		V/μs
			Full range	27		27			
t_s	Settling time	$A_{VD} = -1$, 10-V step, $R_L = 1$ kΩ, $C_L = 100$ pF	To 10 mV	25°C	0.4	0.4			μs
			To 1 mV		1.5	1.5			
V_n	Equivalent input noise voltage		$f = 10$ Hz	25°C	28	28			nV/√Hz
			$f = 10$ kHz		11.6	11.6			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20$ Ω, See Figure 3	$f = 10$ Hz to 10 kHz	25°C	6	6			μV
			$f = 0.1$ Hz to 10 Hz		0.6	0.6			
I_n	Equivalent input noise current	$V_{IC} = 0$, $f = 10$ kHz	25°C		2.8	2.8			fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_O(PP) = 20$ V, $A_{VD} = 10$, $f = 1$ kHz, $R_L = 2$ kΩ, $R_S = 25$ Ω	25°C		0.008%		0.008%		
B_1	Unity-gain bandwidth	$V_I = 10$ mV, $R_L = 2$ kΩ, $C_L = 25$ pF, See Figure 2	25°C		8 10		8 10		MHz
B_{OM}	Maximum output-swing bandwidth	$V_O(PP) = 20$ V, $A_{VD} = -1$, $R_L = 2$ kΩ, $C_L = 25$ pF	25°C		478 637		478 637		kHz
ϕ_m	Phase margin at unity gain	$V_I = 10$ mV, $R_L = 2$ kΩ, $C_L = 25$ pF, See Figure 2	25°C		57°		57°		

[†] Full range is 0°C to 70°C.

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TLE2081M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2081M			TLE2081AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50\Omega$	25°C	0.34	6	0.3	3	0.3	3	mV	
		Full range		11.2			8.2			
		Full range	3.2	29*		3.2	29*			
αV_{IO} Temperature coefficient of input offset voltage									$\mu V/^{\circ}C$	
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4	25°C	5	100	5	100	5	100	pA	
		Full range		20		20	20	20	nA	
I_{IB} Input bias current		25°C	15	175	15	175	15	175	pA	
		Full range		65		65	65	65	nA	
V_{ICR} Common-mode input voltage range	$R_S = 50\Omega$	25°C	5	5	5	5	5	5	V	
		to	to		to	to	to			
		-1	-1.9		-1	-1.9				
		Full range	5		5		5			
			to		to		to			
			-0.8		-0.8		-0.8			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\mu A$	25°C	3.8	4.1	3.8	4.1	3.8	4.1	V	
		Full range	3.6		3.6		3.6			
	$I_O = -2\text{ mA}$	25°C	3.5	3.9	3.5	3.9	3.5	3.9		
		Full range	3.3		3.3		3.3			
	$I_O = -20\text{ mA}$	25°C	1.5	2.3	1.5	2.3	1.5	2.3		
		Full range	1.4		1.4		1.4			
	$I_O = 200\mu A$	25°C	-3.8	-4.2	-3.8	-4.2	-3.8	-4.2		
		Full range	-3.6		-3.6		-3.6			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 2\text{ mA}$	25°C	-3.5	-4.1	-3.5	-4.1	-3.5	-4.1	V	
		Full range	-3.3		-3.3		-3.3			
	$I_O = 20\text{ mA}$	25°C	-1.5	-2.4	-1.5	-2.4	-1.5	-2.4		
		Full range	-1.4		-1.4		-1.4			
	$R_L = 600\Omega$ $V_O = \pm 2.3\text{ V}$	25°C	80	91	80	91	80	91	dB	
		Full range	78		78		78			
		25°C	90	100	90	100	90	100		
		Full range	88		88		88			
A_{VD} Large-signal differential voltage amplification	$R_L = 2\text{ k}\Omega$ $R_L = 10\text{ k}\Omega$	25°C	95	106	95	106	95	106	dB	
		Full range	93		93		93			
r_i Input resistance	$V_{IC} = 0$	25°C	1012		1012		1012		Ω	
c_i Input capacitance	$V_{IC} = 0$, See Figure 5	25°C Common mode	11		11		11		pF	
		25°C Differential	2.5		2.5		2.5			
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C	80		80		80		Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50\Omega$	25°C	70	89	70	89	70	89	dB	
		Full range	68		68		68			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\text{ V to } \pm 15\text{ V}$, $V_O = 0$, $R_S = 50\Omega$	25°C	82	99	82	99	82	99	dB	
		Full range	80		80		80			

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C .



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TLE2081M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2081M			TLE2081AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.6	2.2	1.35	1.6	2.2	mA
		Full range			2.2			2.2	
I_{OS} Short-circuit output current	$V_O = 0$	25°C			-35			-35	mA
					45			45	

† Full range is -55°C to 125°C.

TLE2081M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2081M			TLE2081AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR+ Positive slew rate	$V_O(PP) = \pm 2.3$ V, $A_{VD} = -1$, $R_L = 2$ kΩ, $C_L = 100$ pF, See Figure 1	25°C		35			35		V/μs	
		Full range		20*			20*			
SR- Negative slew rate		25°C		38			38		V/μs	
		Full range		20*			20*			
t_s Settling time	$A_{VD} = -1$, 2-V step, $R_L = 1$ kΩ, $C_L = 100$ pF	To 10 mV	25°C		0.25		0.25		μs	
					0.4		0.4			
V_n Equivalent input noise voltage	$R_S = 20$ Ω, See Figure 3	$f = 10$ Hz	25°C		28		28		nV/√Hz	
		$f = 10$ kHz			11.6		11.6			
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage		$f = 10$ Hz to 10 kHz	25°C		6		6		μV	
		$f = 0.1$ Hz to 10 Hz			0.6		0.6			
I_n Equivalent input noise current	$V_{IC} = 0$,	$f = 10$ kHz	25°C		2.8		2.8		fA/√Hz	
THD + N Total harmonic distortion plus noise	$V_O(PP) = 5$ V, $f = 1$ kHz, $R_S = 25$ Ω		25°C		0.013%		0.013%			
B ₁ Unity-gain bandwidth	$V_I = 10$ mV, $C_L = 25$ pF, See Figure 2		25°C		9.4		9.4		MHz	
B _{OM} Maximum output-swing bandwidth	$V_O(PP) = 4$ V, $R_L = 2$ kΩ, $C_L = 25$ pF		25°C		2.8		2.8		MHz	
φ _m Phase margin at unity gain	$V_I = 10$ mV, $C_L = 25$ pF, See Figure 2		25°C		56°		56°			

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† Full range is -55°C to 125°C.



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TLE2081M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2081M			TLE2081AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	25°C	0.49	6	0.47	3	0.47	3	mV
		Full range		11.2				8.2	
		Full range	3.2	29*		3.2	29*		
αV_{IO} Temperature coefficient of input offset voltage									$\mu V/^\circ C$
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4	25°C	6	100	6	100	6	100	pA
		Full range		20			20	20	nA
		25°C	20	175	20	175	20	175	pA
I_{IB} Input bias current		Full range		65			65	65	nA
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9	15 to -11.9	15 to -11	15 to -11.9		V
		Full range	15 to -10.8		15 to -10.8	15	15		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	13.8	14.1	13.8	14.1	13.8	14.1	V
		Full range	13.6		13.6		13.6		
	$I_O = -2 \text{ mA}$	25°C	13.5	13.9	13.5	13.9	13.5	13.9	
		Full range	13.3		13.3		13.3		
	$I_O = -20 \text{ mA}$	25°C	11.5	12.3	11.5	12.3	11.5	12.3	
		Full range	11.4		11.4		11.4		
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-13.8	-14.2	-13.8	-14.2	-13.8	-14.2	V
		Full range	-13.6		-13.6		-13.6		
	$I_O = 2 \text{ mA}$	25°C	-13.5	-14	-13.5	-14	-13.5	-14	
		Full range	-13.3		-13.3		-13.3		
	$I_O = 20 \text{ mA}$	25°C	-11.5	-12.4	-11.5	-12.4	-11.5	-12.4	
		Full range	-11.4		-11.4		-11.4		
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96	80	96		dB
			Full range	78		78			
		$R_L = 2 \text{ k}\Omega$	25°C	90	109	90	109		
			Full range	88		88			
		$R_L = 10 \text{ k}\Omega$	25°C	95	118	95	118		
			Full range	93		93			
r_i Input resistance	$V_{IC} = 0$	25°C		1012		1012			Ω
c_i Input capacitance	$V_{IC} = 0$, See Figure 5	Common mode	25°C		7.5		7.5		pF
		Differential	25°C		2.5		2.5		
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C		80		80			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	80	98	80	98		dB	
		Full range	78		78				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	82	99	82	99		dB	
		Full range	80		80				

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is $-55^\circ C$ to $125^\circ C$.



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TLE2081M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)(continued)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2081M			TLE2081AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	Supply current $V_O = 0$, No load	25°C	1.35	1.7	2.2	1.35	1.7	2.2	mA
		Full range			2.2			2.2	
I_{OS}	Short-circuit output current $V_O = 0$	$V_{ID} = 1$ V $V_{ID} = -1$ V	25°C	-30	-45	-30	-45		mA
				30	48	30	48		

[†] Full range is -55°C to 125°C.

TLE2081M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2081M			TLE2081AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate $V_O(PP) = 10$ V, $A_{VD} = -1$,	$R_L = 2$ kΩ, $C_L = 100$ pF, See Figure 1	25°C	30	40	30	40		V/μs
			Full range	22		22			
SR-	Negative slew rate		25°C	30	45	30	45		V/μs
			Full range	22		22			
t_s	Settling time $A_{VD} = -1$, 10-V step, $R_L = 1$ kΩ, $C_L = 100$ pF	To 10 mV To 1 mV	25°C		0.4		0.4		μs
					1.5		1.5		
V_n	Equivalent input noise voltage	$f = 10$ Hz $f = 10$ kHz	25°C		28		28		nV/√Hz
					11.6		11.6		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20$ Ω, See Figure 3	$f = 10$ Hz to 10 kHz $f = 0.1$ Hz to 10 Hz	25°C	6		6		μV
					0.6		0.6		
I_n	Equivalent input noise current	$V_{IC} = 0$, $f = 10$ kHz	25°C		2.8		2.8		fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_O(PP) = 20$ V, $A_{VD} = 10$, $f = 1$ kHz, $R_L = 2$ kΩ, $R_S = 25$ Ω	25°C		0.008%		0.008%		
B ₁	Unity-gain bandwidth	$V_I = 10$ mV, $C_L = 25$ pF, See Figure 2	25°C	8*	10	8*	10		MHz
B _{OM}	Maximum output-swing bandwidth	$V_O(PP) = 20$ V, $A_{VD} = -1$, $R_L = 2$ kΩ, $C_L = 25$ pF	25°C	478*	637	478*	637		kHz
ϕ_m	Phase margin at unity gain	$V_I = 10$ mV, $C_L = 25$ pF, See Figure 2	25°C		57°		57°		

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

[†] Full range is -55°C to 125°C.



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TLE2081Y electrical characteristics at $V_{CC\pm} = \pm 15$ V, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	TLE2081Y			UNIT
		MIN	TYP	MAX	
V_{IO}	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	0.49	6	6	mV
I_{IO}	$V_{IC} = 0$, $V_O = 0$, See Figure 4	6	100	100	pA
I_{IB}		20	175	175	
V_{ICR}	$R_S = 50 \Omega$	15 to −11	15 to 11.9	15 to 11.9	V
V_{OM+}	$I_O = -200 \mu\text{A}$	13.8	14.1	14.1	V
	$I_O = -2 \text{ mA}$	13.5	13.9	13.9	
	$I_O = -20 \text{ mA}$	11.5	12.3	12.3	
V_{OM-}	$I_O = 200 \mu\text{A}$	−13.8	−14.2	−14.2	V
	$I_O = 2 \text{ mA}$	−13.5	−14	−14	
	$I_O = 20 \text{ mA}$	−11.5	−12.4	−12.4	
A_{VD}	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	80	96	dB
		$R_L = 2 \text{ k}\Omega$	90	109	
		$R_L = 10 \text{ k}\Omega$	95	118	
r_i	$V_{IC} = 0$	10 ¹²			Ω
c_i	$V_{IC} = 0$, See Figure 5	Common mode	7.5	7.5	pF
		Differential	2.5	2.5	
Z_0	$f = 1 \text{ MHz}$	80			Ω
CMRR	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	80	98	98	dB
k_{SVR}	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}$, $V_O = 0$, $R_S = 50 \Omega$	82	99	99	dB
I_{CC}	$V_O = 0$, No load	1.35	1.7	2.2	mA
I_{OS}	$V_O = 0$	$V_{ID} = 1 \text{ V}$	−30	−45	mA
		$V_{ID} = −1 \text{ V}$	30	48	

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TLE2082C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2082C			TLE2082AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	25°C	0.9	6		0.65	4		mV	
		Full range		8.1			5.1			
		Full range	2.3	25		2.3	25			
αV_{IO} Temperature coefficient of input offset voltage									$\mu V/^\circ C$	
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4	25°C	5	100		5	100		pA	
		Full range		1.4			1.4		nA	
		25°C	15	175		15	175		pA	
I_{IB} Input bias current		Full range		5			5		nA	
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	5	5		5	5		V	
		to	to			to	to			
		-1	-1.9			-1	-1.9			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	Full range	5			5			V	
		to				to				
		-0.9				-0.9				
V_{OM-} Maximum negative peak output voltage swing	$I_O = -2 \text{ mA}$	25°C	3.8	4.1		3.8	4.1		V	
		Full range	3.7			3.7				
		25°C	3.5	3.9		3.5	3.9			
V_{OM-} Maximum negative peak output voltage swing	$I_O = -20 \text{ mA}$	Full range	3.4			3.4			V	
		25°C	1.5	2.3		1.5	2.3			
		Full range	1.5			1.5				
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-3.8	-4.2		-3.8	-4.2		V	
		Full range	-3.7			-3.7				
		25°C	-3.5	-4.1		-3.5	-4.1			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 2 \text{ mA}$	Full range	-3.4			-3.4			V	
		25°C	-1.5	-2.4		-1.5	-2.4			
		Full range	-1.5			-1.5				
AVD Large-signal differential voltage amplification	$V_O = \pm 2.3 \text{ V}$	$R_L = 600 \Omega$	25°C	80	91	80	91		dB	
			Full range	79		79				
		$R_L = 2 \text{ k}\Omega$	25°C	90	100	90	100			
AVD Large-signal differential voltage amplification		$R_L = 10 \text{ k}\Omega$	Full range	89		89				
			25°C	95	106	95	106			
		Full range	94			94				
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}		10^{12}				Ω	
c_i Input capacitance	Common mode Differential	$V_{IC} = 0$, See Figure 5	25°C	11		11			pF	
			25°C	2.5		2.5				
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80			80			Ω	
$CMRR$ Common-mode rejection ratio	$V_{IC} = V_{ICR\min},$ $V_O = 0$, $R_S = 50 \Omega$	25°C	70	89		70	89		dB	
		Full range	68			68				
k_{SVR} Supply-voltage rejection ratio($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V},$ $V_O = 0$, $R_S = 50 \Omega$	25°C	82	99		82	99		dB	
		Full range	80			80				
I_{CC} Supply current (both channels)	$V_O = 0$, No load	25°C	2.7	2.9	3.6	2.7	2.9	3.6	mA	
		Full range			3.6			3.6		

† Full range is 0°C to 70°C.



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TLE2082C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	TA	TLE2082C			TLE2082AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C	120			120			dB
I_{OS}	$V_O = 0$	25°C	–35			–35			mA
			45			45			

TLE2082C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER	TEST CONDITIONS	TA	TLE2082C			TLE2082AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate $V_O(PP) = \pm 2.3$ V, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C	35			35			V/ μ s
		Full range	22			22			
		25°C	38			38			
		Full range	22			22			
t_S	Settling time $A_{VD} = -1$, 2-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	To 10 mV	25°C	0.25		0.25			μ s
		To 1 mV		0.4		0.4			
V_n	Equivalent input noise voltage	f = 10 Hz	25°C	28		28			nV/ $\sqrt{\text{Hz}}$
		f = 10 kHz		11.6		11.6			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage RS = 20 Ω , See Figure 3	f = 10 Hz to 10 kHz	25°C	6		6			μ V
		f = 0.1Hz to 10 Hz		0.6		0.6			
I_n	Equivalent input noise current	$V_{IC} = 0$, f = 10 kHz	25°C	2.8		2.8			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_O(PP) = 5$ V, f = 1 kHz, RS = 25 Ω	$A_{VD} = 10$, $R_L = 2\text{ k}\Omega$,	25°C	0.013%		0.013%		
B1	Unity-gain bandwidth	$V_I = 10$ mV, $C_L = 25\text{ pF}$, See Figure 2	25°C	9.4		9.4			MHz
B _{OM}	Maximum output-swing bandwidth	$V_O(PP) = 4$ V, $R_L = 2\text{ k}\Omega$, CL = 25 pF	25°C	2.8		2.8			MHz
ϕ_m	Phase margin at unity gain	$V_I = 10$ mV, $C_L = 25\text{ pF}$, See Figure 2	25°C	56°		56°			

† Full range is 0°C to 70°C.

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TLE2082C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2082C			TLE2082AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	25°C	1.1	7		0.7	4		mV	
		Full range		8.1			5.1			
αV_{IO} Temperature coefficient of input offset voltage		Full range	2.4	25		2.4	25		$\mu\text{V}/^\circ\text{C}$	
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4	25°C	6	100		6	100		pA	
		Full range		1.4			1.4		nA	
I_{IB} Input bias current		25°C	20	175		20	175		pA	
		Full range		5			5		nA	
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9		V	
		Full range	15 to -10.9			15 to -10.9				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu\text{A}$	25°C	13.8	14.1		13.8	14.1		V	
		Full range	13.6			13.6				
	$I_O = -2 \text{ mA}$	25°C	13.5	13.9		13.5	13.9			
		Full range	13.4			13.4				
	$I_O = -20 \text{ mA}$	25°C	11.5	12.3		11.5	12.3			
		Full range	11.5			11.5				
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu\text{A}$	25°C	-13.8	-14.2		-13.8	-14.2		V	
		Full range	-13.7			-13.7				
	$I_O = 2 \text{ mA}$	25°C	-13.5	-14		-13.5	-14			
		Full range	-13.4			-13.4				
	$I_O = 20 \text{ mA}$	25°C	-11.5	-12.4		-11.5	-12.4			
		Full range	-11.5			-11.5				
AVD Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96	80	96		dB	
			Full range	79		79				
		$R_L = 2 \text{ k}\Omega$	25°C	90	109	90	109			
			Full range	89		89				
		$R_L = 10 \text{ k}\Omega$	25°C	95	118	95	118			
			Full range	94		94				
r_i Input resistance	$V_{IC} = 0$	25°C	10 ¹²			10 ¹²			Ω	
c_i Input capacitance	Common mode See Figure 5	25°C	7.5			7.5			pF	
		25°C	2.5			2.5				
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80			80			Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	80	98		80	98		dB	
		Full range	79			79				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	82	99		82	99		dB	
		Full range	81			81				

[†] Full range is 0°C to 70°C.



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TLE2082C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	TA	TLE2082C			TLE2082AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	$V_O = 0$, No load	25°C	2.7	3.1	3.6	2.7	3.1	3.6	mA
		Full range			3.6			3.6	
Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2$ kΩ	25°C		120			120		dB
I_{OS}	$V_O = 0$	$V_{ID} = 1$ V	25°C	-30	-45	-30	-45		mA
		$V_{ID} = -1$ V		30	48	30	48		

TLE2082C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER	TEST CONDITIONS	TA†	TLE2082C			TLE2082AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_O(PP) = 10$ V, $AVD = -1$, $R_L = 2$ kΩ, $C_L = 100$ pF, See Figure 1	25°C	28	40	28	40		V/μs
			Full range	25		25			
SR-	Negative slew rate		25°C	30	45	30	45		V/μs
			Full range	25		25			
t_s	Settling time	$AVD = -1$, 10-V step, $R_L = 1$ kΩ, $C_L = 100$ pF	To 10 mV	25°C	0.4	0.4			μs
			To 1 mV		1.5	1.5			
V_n	Equivalent input noise voltage		$f = 10$ Hz	25°C	28	28			nV/√Hz
			$f = 10$ kHz		11.6	11.6			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$R_S = 20$ Ω, See Figure 3	$f = 10$ Hz to 10 kHz	25°C	6	6			μV
			$f = 0.1$ Hz to 10 Hz		0.6	0.6			
I_n	Equivalent input noise current	$V_{IC} = 0$, $f = 10$ kHz	25°C		2.8	2.8			fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_O(PP) = 20$ V, $AVD = 10$, $f = 1$ kHz, $R_L = 2$ kΩ, $R_S = 25$ Ω	25°C		0.008%		0.008%		
B ₁	Unity-gain bandwidth	$V_I = 10$ mV, $R_L = 2$ kΩ, $C_L = 25$ pF, See Figure 2	25°C	8	10	8	10		MHz
B _{OM}	Maximum output-swing bandwidth	$V_O(PP) = 20$ V, $AVD = -1$, $R_L = 2$ kΩ, $C_L = 25$ pF	25°C	478	637	478	637		kHz
ϕ_m	Phase margin at unity gain	$V_I = 10$ mV, $R_L = 2$ kΩ, $C_L = 25$ pF, See Figure 2	25°C		57°		57°		

† Full range is 0°C to 70°C.

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TLE2082I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2082I			TLE2082AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	25°C	0.9	7	0.65	4			mV
		Full range		8.5			5.5		
αV_{IO} Temperature coefficient of input offset voltage		Full range	2.4	25		2.4	25		$\mu V/^\circ C$
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4	25°C	5	100		5	100		pA
		Full range		5			5		nA
I_{IB} Input bias current		25°C	15	175		15	175		pA
		Full range		10			10		nA
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9		V
		Full range	5 to -0.8			5 to -0.8			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	3.8	4.1		3.8	4.1		V
		Full range	3.7			3.7			
	$I_O = -2 mA$	25°C	3.5	3.9		3.5	3.9		
		Full range	3.4			3.4			
	$I_O = -20 mA$	25°C	1.5	2.3		1.5	2.3		
		Full range	1.5			1.5			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-3.8	-4.2		-3.8	-4.2		V
		Full range	-3.7			-3.7			
	$I_O = 2 mA$	25°C	-3.5	-4.1		-3.5	-4.1		
		Full range	-3.4			-3.4			
	$I_O = 20 mA$	25°C	-1.5	-2.4		-1.5	-2.4		
		Full range	-1.5			-1.5			
AVD Large-signal differential voltage amplification	$V_O = \pm 2.3$ V	$R_L = 600 \Omega$	25°C	80	91	80	91		dB
			Full range	79		79			
		$R_L = 2 k\Omega$	25°C	90	100	90	100		
			Full range	89		89			
		$R_L = 10 k\Omega$	25°C	95	106	95	106		
			Full range	94		94			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}		10^{12}				Ω
c_i Input capacitance	Common mode See Figure 5	25°C	11		11				pF
		25°C	2.5		2.5				
z_o Open-loop output impedance	$f = 1$ MHz	25°C	80		80				Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	70	89	70	89			dB
		Full range	68		68				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5$ V to ± 15 V, $V_O = 0$, $R_S = 50 \Omega$	25°C	82	99	82	99			dB
		Full range	80		80				
I_{CC} Supply current (both channels)	$V_O = 0$, No load	25°C	2.7	2.9	3.6	2.7	2.9	3.6	mA
		Full range		3.6			3.6		

† Full range is $-40^\circ C$ to $85^\circ C$.



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TLE2082I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	TA	TLE2082I			TLE2082AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2 \text{ k}\Omega$	25°C	120			120			dB
I_{OS}	$V_O = 0$	25°C	–35			–35			mA
			45			45			

TLE2082I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER	TEST CONDITIONS	TA	TLE2082I			TLE2082AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_O(\text{PP}) = \pm 2.3$ V, $\text{AVD} = -1$, $R_L = 2 \text{ k}\Omega$, $C_L = 100 \text{ pF}$, See Figure 1	25°C	35		35			V/ μ s
			Full range	20		20			
SR–	Negative slew rate	25°C	38			38			V/ μ s
			Full range	20		20			
t_s	Settling time	$\text{AVD} = -1$, 2-V step, $R_L = 1 \text{ k}\Omega$, $C_L = 100 \text{ pF}$	To 10 mV	25°C	0.25		0.25		μ s
			To 1 mV		0.4		0.4		
V_n	Equivalent input noise voltage	$f = 10 \text{ Hz}$ $f = 10 \text{ kHz}$	25°C	28		28			nV/ $\sqrt{\text{Hz}}$
				11.6		11.6			
$V_{N(\text{PP})}$	Peak-to-peak equivalent input noise voltage	$R_S = 20 \Omega$, See Figure 3	$f = 10 \text{ Hz}$ to 10 kHz	25°C	6		6		μ V
			$f = 0.1 \text{ Hz}$ to 10 Hz		0.6		0.6		
I_n	Equivalent input noise current	$V_{IC} = 0$,	$f = 10 \text{ kHz}$	25°C	2.8		2.8		fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_O(\text{PP}) = 5$ V, $f = 1 \text{ kHz}$, $R_S = 25 \Omega$	$\text{AVD} = 10$, $R_L = 2 \text{ k}\Omega$,	25°C	0.013%		0.013%		
B ₁	Unity-gain bandwidth	$V_I = 10 \text{ mV}$, $C_L = 25 \text{ pF}$,	$R_L = 2 \text{ k}\Omega$, See Figure 2	25°C	9.4		9.4		MHz
B _{OM}	Maximum output-swing bandwidth	$V_O(\text{PP}) = 4$ V, $R_L = 2 \text{ k}\Omega$,	$\text{AVD} = -1$, $C_L = 25 \text{ pF}$	25°C	2.8		2.8		MHz
ϕ_m	Phase margin at unity gain	$V_I = 10 \text{ mV}$, $C_L = 25 \text{ pF}$,	$R_L = 2 \text{ k}\Omega$, See Figure 2	25°C	56°		56°		

† Full range is 40°C to 85°C.

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TLE2082I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2082I			TLE2082AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	25°C	1.1	7		0.7	4		mV
		Full range		8.5			5.5		
αV_{IO} Temperature coefficient of input offset voltage	See Figure 4	Full range	2.4	25		2.4	25		$\mu V/^\circ C$
		25°C	6	100		6	100		
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4	Full range	5			5			nA
		25°C	20	175		20	175		
I_{IB} Input bias current		Full range		10			10		nA
		25°C	15	15		15	15		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	to	to			to	to		V
		-11	-11.9			-11	-11.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	Full range	15			15			V
		25°C	13.8	14.1		13.8	14.1		
V_{OM-} Maximum negative peak output voltage swing	$I_O = -2 m A$	Full range	13.7			13.7			V
		25°C	13.5	13.9		13.5	13.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -20 m A$	Full range	13.4			13.4			V
		25°C	11.5	12.3		11.5	12.3		
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	Full range	11.5			11.5			V
		25°C	-13.8	-14.2		-13.8	-14.2		
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 V$	Full range	-13.7			-13.7			dB
		25°C	80	96		80	96		
r_i Input resistance	$V_{IC} = 0$	$R_L = 600 \Omega$	Full range	79		79			dB
		25°C	90	109		90	109		
c_i Input capacitance	$V_{IC} = 0$, See Figure 5	$R_L = 2 k\Omega$	Full range	89		89			pF
		25°C	95	118		95	118		
z_o Open-loop output impedance	$f = 1 MHz$	$R_L = 10 k\Omega$	Full range	94		94			dB
		25°C	80			80			
$CMRR$ Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	80	98		80	98		dB
		Full range	79			79			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5 V$ to $\pm 15 V$, $V_O = 0$, $R_S = 50 \Omega$	25°C	82	99		82	99		dB
		Full range	80			80			

[†] Full range is $-40^\circ C$ to $85^\circ C$.



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TLE2082I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	TA	TLE2082I			TLE2082AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
I_{CC}	$V_O = 0$, Supply current (both channels)	No load	25°C	2.7	3.1	3.6	2.7	3.1	3.6	mA
			Full range			3.6			3.6	
Crosstalk attenuation	$V_{IC} = 0$,	$R_L = 2\text{ k}\Omega$	25°C		120		120		dB	
I_{OS}	$V_O = 0$	$V_{ID} = 1\text{ V}$	25°C	-30	-45		-30	-45	mA	
		$V_{ID} = -1\text{ V}$		30	48		30	48		

TLE2082I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER	TEST CONDITIONS	TA†	TLE2082I			TLE2082AI			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR+	Positive slew rate	$V_O(\text{PP}) = 10\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C	28	40		28	40	V/ μ s	
			Full range		22		22			
SR-	Negative slew rate		25°C	30	45		30	45	V/ μ s	
			Full range		22		22			
t_s	Settling time	$A_{VD} = -1$, 10-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	To 10 mV	25°C	0.4		0.4		μ s	
			To 1 mV		1.5		1.5			
V_n	Equivalent input noise voltage		$f = 10\text{ Hz}$	25°C	28		28		nV/ $\sqrt{\text{Hz}}$	
			$f = 10\text{ kHz}$		11.6		11.6			
$V_{N(\text{PP})}$	Peak-to-peak equivalent input noise voltage	$R_S = 20\text{ }\Omega$, See Figure 3	$f = 10\text{ Hz}$ to 10 kHz	25°C	6		6		μ V	
			$f = 0.1\text{ Hz}$ to 10 Hz		0.6		0.6			
I_n	Equivalent input noise current	$V_{IC} = 0$,	$f = 10\text{ kHz}$	25°C	2.8		2.8		fA/ $\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise	$V_O(\text{PP}) = 20\text{ V}$, $A_{VD} = 10$, $f = 1\text{ kHz}$, $R_S = 25\text{ }\Omega$		25°C	0.008%		0.008%			
B ₁	Unity-gain bandwidth	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, See Figure 2		25°C	8	10		8	10	MHz
B _{OM}	Maximum output-swing bandwidth	$V_O(\text{PP}) = 20\text{ V}$, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$		25°C	478	637		478	637	kHz
ϕ_m	Phase margin at unity gain	$V_I = 10\text{ mV}$, $C_L = 25\text{ pF}$, See Figure 2		25°C	57°		57°			

† Full range is -40°C to 85°C .

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TLE2082M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2082M			TLE2082AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50\Omega$	25°C	0.9	7		0.65	4		mV
		Full range		9.5			6.5		
		Full range	2.3	25*		2.3	25*		
αV_{IO} Temperature coefficient of input offset voltage		25°C	5	100		5	100		$\mu V/^{\circ}C$
		Full range		20			20		
		25°C	15	175		15	175		
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4	Full range		60			60		nA
		25°C	5	100		5	100		
		Full range	20			20			
I_{IB} Input bias current		25°C	15	175		15	175		pA
		Full range		60			60		
		25°C	5	100		5	100		
V_{ICR} Common-mode input voltage range	$R_S = 50\Omega$	Full range	5	100		5	100		V
		25°C	to	to		to	to		
		Full range	-1	-1.9		-1	-1.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\mu A$	25°C	3.8	4.1		3.8	4.1		V
		Full range	3.6			3.6			
		25°C	3.5	3.9		3.5	3.9		
V_{OM-} Maximum negative peak output voltage swing	$I_O = -2 mA$	Full range	3.3			3.3			V
		25°C	1.5	2.3		1.5	2.3		
		Full range	1.4			1.4			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\mu A$	25°C	-3.8	-4.2		-3.8	-4.2		V
		Full range	-3.6			-3.6			
		25°C	-3.5	-4.1		-3.5	-4.1		
V_{OM-} Maximum negative peak output voltage swing	$I_O = 2 mA$	Full range	-3.3			-3.3			V
		25°C	-1.5	-2.4		-1.5	-2.4		
		Full range	-1.4			-1.4			
AVD Large-signal differential voltage amplification	$V_O = \pm 2.3 V$	$R_L = 600\Omega$	25°C	80	91	80	91		dB
			Full range	78		78			
			25°C	90	100	90	100		
c_i Input capacitance	$V_{IC} = 0$, Common mode	See Figure 5	Full range	88		88			pF
			25°C	95	106	95	106		
			Full range	93		93			
r_i	Input resistance	$V_{IC} = 0$	25°C	10^{12}		10^{12}		Ω	
z_o	Open-loop output impedance	$f = 1$ MHz	25°C	80		80		Ω	
			25°C	11		11			
$CMRR$	Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50\Omega$	25°C	2.5		2.5			
			Full range	68		68			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5$ V to ± 15 V, $V_O = 0$, $R_S = 50\Omega$	25°C	82		82			
			Full range	99		99			
			25°C	80		80			

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is $-55^{\circ}C$ to $125^{\circ}C$.



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PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2082M			TLE2082AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	$V_O = 0$, No load	25°C	2.7	2.9	3.6	2.7	2.9	3.6	mA
		Full range			3.6			3.6	
Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C		120			120		dB
I_{OS}	$V_O = 0$	25°C		-35			-35		mA
					45			45	

† Full range is -55°C to 125°C.

TLE2082M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2082M			TLE2082AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate $V_O(\text{PP}) = \pm 2.3$ V, $\text{AVD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C		35			35		V/ μ s
		Full range		18*			18*		
SR-	Negative slew rate $\text{AVD} = -1$, 2-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	25°C		38			38		V/ μ s
		Full range		18*			18*		
t_s	Settling time $\text{AVD} = -1$, 2-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	To 10 mV To 1 mV	25°C		0.25		0.25		μ s
					0.4		0.4		
V_n	Equivalent input noise voltage $R_S = 20\Omega$, See Figure 3	$f = 10\text{ Hz}$ $f = 10\text{ kHz}$	25°C		28		28		nV/ $\sqrt{\text{Hz}}$
					11.6		11.6		
$V_{N(\text{PP})}$	Peak-to-peak equivalent input noise voltage $f = 10\text{ Hz to } 10\text{ kHz}$ $f = 0.1\text{ Hz to } 10\text{ Hz}$	$f = 10\text{ Hz to } 10\text{ kHz}$ $f = 0.1\text{ Hz to } 10\text{ Hz}$	25°C		6		6		μ V
					0.6		0.6		
I_n	Equivalent input noise current $V_{IC} = 0$, $f = 10\text{ kHz}$		25°C		2.8		2.8		fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise $V_O(\text{PP}) = 5$ V, $\text{AVD} = 10$, $f = 1\text{ kHz}$, $R_L = 2\text{ k}\Omega$, $R_S = 25\Omega$		25°C		0.013%		0.013%		
B_1	Unity-gain bandwidth $V_I = 10\text{ mV}$, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$, See Figure 2		25°C		9.4		9.4		MHz
B_{OM}	Maximum output-swing bandwidth $V_O(\text{PP}) = 4$ V, $\text{AVD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$		25°C		2.8		2.8		MHz
ϕ_m	Phase margin at unity gain $V_I = 10\text{ mV}$, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$, See Figure 2		25°C		56°		56°		

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C.

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TLE2082M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2082M			TLE2082AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	25°C	1.1	7		0.7	4		mV
		Full range		9.5			6.5		
αV_{IO} Temperature coefficient of input offset voltage		Full range	2.4	25*		2.4	25*		$\mu V/^\circ C$
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4	25°C	6	100		6	100		pA
		Full range		20			20		
I_{IB} Input bias current		25°C	20	175		20	175		pA
		Full range		65			65		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15	15		15	15		V
			to	to		to	to		
			-11	-11.9		-11	-11.9		
		Full range	15			15			V
			to			to			
			-10.8			-10.8			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	13.8	14.1		13.8	14.1		V
		Full range	13.6			13.6			
	$I_O = -2 \text{ mA}$	25°C	13.5	13.9		13.5	13.9		
		Full range	13.3			13.3			
	$I_O = -20 \text{ mA}$	25°C	11.5	12.3		11.5	12.3		
		Full range	11.4			11.4			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-13.8	-14.2		-13.8	-14.2		V
		Full range	-13.6			-13.6			
	$I_O = 2 \text{ mA}$	25°C	-13.5	-14		-13.5	-14		
		Full range	-13.3			-13.3			
	$I_O = 20 \text{ mA}$	25°C	-11.5	-12.4		-11.5	-12.4		
		Full range	-11.4			-11.4			
AVD Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96	80	96		dB
			Full range	78		78			
		$R_L = 2 \text{ k}\Omega$	25°C	90	109	90	109		
			Full range	88		88			
		$R_L = 10 \text{ k}\Omega$	25°C	95	118	95	118		
			Full range	93		93			
r_i	Input resistance	$V_{IC} = 0$	25°C	10 ¹²		10 ¹²			Ω
c_i Input capacitance	Common mode	$V_{IC} = 0$, See Figure 5	25°C	7.5		7.5			pF
			25°C	2.5		2.5			
z_o	Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80		80			Ω
$CMRR$ Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	80	98		80	98		dB
		Full range	78			78			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	82	99		82	99		dB
		Full range	80			80			

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C.



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TLE2082M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)
(continued)

PARAMETER	TEST CONDITIONS	TA†	TLE2082M			TLE2082AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC}	$V_O = 0$, No load	25°C	2.7	3.1	3.6	2.7	3.1	3.6	mA
		Full range			3.6			3.6	
Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2 \text{ k}\Omega$	25°C		120			120		dB
I_{OS}	$V_O = 0$	$V_{ID} = 1 \text{ V}$	25°C	-30	-45	-30	-45		mA
		$V_{ID} = -1 \text{ V}$		30	48	30	48		

† Full range is -55°C to 125°C.

TLE2082M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER	TEST CONDITIONS	TA†	TLE2082M			TLE2082AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$V_O(\text{PP}) = 10 \text{ V}$, $\text{AVD} = -1$, $R_L = 2 \text{ k}\Omega$, $C_L = 100 \text{ pF}$, See Figure 1	25°C	28	40	28	40		V/ μ s
			Full range	20		20			
SR-	Negative slew rate		25°C	30	45	30	45		V/ μ s
			Full range	20		20			
t_s	Settling time	$\text{AVD} = -1$, 10-V step, $R_L = 1 \text{ k}\Omega$, $C_L = 100 \text{ pF}$	To 10 mV	25°C	0.4	0.4			μ s
			To 1 mV		1.5	1.5			
V_n	Equivalent input noise voltage		$f = 10 \text{ Hz}$	25°C	28	28			nV/ $\sqrt{\text{Hz}}$
			$f = 10 \text{ kHz}$		11.6	11.6			
$V_{N(\text{PP})}$	Peak-to-peak equivalent input noise voltage	$R_S = 20 \Omega$, See Figure 3	$f = 10 \text{ Hz}$ to 10 kHz	25°C	6	6			μ V
			$f = 0.1 \text{ Hz}$ to 10 Hz		0.6	0.6			
I_n	Equivalent input noise current	$V_{IC} = 0$, $f = 10 \text{ kHz}$	25°C		2.8	2.8			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_O(\text{PP}) = 20 \text{ V}$, $\text{AVD} = 10$, $f = 1 \text{ kHz}$, $R_L = 2 \text{ k}\Omega$, $R_S = 25 \Omega$	25°C		0.008%	0.008%			
B ₁	Unity-gain bandwidth	$V_I = 10 \text{ mV}$, $C_L = 25 \text{ pF}$, See Figure 2	25°C	8*	10	8*	10		MHz
B _{OM}	Maximum output-swing bandwidth	$V_O(\text{PP}) = 20 \text{ V}$, $\text{AVD} = -1$, $R_L = 2 \text{ k}\Omega$, $C_L = 25 \text{ pF}$	25°C	478*	637	478*	637		kHz
ϕ_m	Phase margin at unity gain	$V_I = 10 \text{ mV}$, $C_L = 25 \text{ pF}$, See Figure 2	25°C		57°		57°		

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C.

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TLE2082Y electrical characteristics at $V_{CC\pm} = \pm 15$ V, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	TLE2082Y			UNIT
		MIN	TYP	MAX	
V_{IO}	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	1.1	6	6	mV
I_{IO}	$V_{IC} = 0$, $V_O = 0$, See Figure 4	6	100	100	pA
I_{IB}		20	175	175	pA
V_{ICR}	$R_S = 50 \Omega$	15 to -11	15 to 11.9	15 to 11.9	V
V_{OM+}	$I_O = -200 \mu\text{A}$	13.8	14.1	14.1	V
	$I_O = -2 \text{ mA}$	13.5	13.9	13.9	
	$I_O = -20 \text{ mA}$	11.5	12.3	12.3	
V_{OM-}	$I_O = 200 \mu\text{A}$	-13.8	-14.2	-14.2	V
	$I_O = 2 \text{ mA}$	-13.5	-14	-14	
	$I_O = 20 \text{ mA}$	-11.5	-12.4	-12.4	
A_{VD}	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	80	96	dB
		$R_L = 2 \text{ k}\Omega$	90	109	
		$R_L = 10 \text{ k}\Omega$	95	118	
r_i	$V_{IC} = 0$		10^{12}	10^{12}	Ω
c_i	Common mode Differential	$V_O = 0$, See Figure 5	7.5	7.5	pF
			2.5	2.5	
z_o	$f = 1 \text{ MHz}$		80	80	Ω
$CMRR$	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	80	98	98	dB
k_{SVR}	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}$, $V_O = 0$, $R_S = 50 \Omega$	82	99	99	dB
I_{CC}	$V_O = 0$, No load	2.7	3.1	3.6	mA
I_{OS}	$V_O = 0$	$V_{ID} = 1 \text{ V}$	-30	-45	mA
		$V_{ID} = -1 \text{ V}$	30	48	

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TLE2084C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2084C			TLE2084AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	25°C	-1.6	7		-0.5	4		mV	
		Full range		9.1			6.1			
αV_{IO} Temperature coefficient of input offset voltage		Full range	10.1	30		10.1	30		$\mu\text{V}/^\circ\text{C}$	
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4	25°C	15	100		15	100		pA	
		Full range		1.4			1.4		nA	
I_{IB} Input bias current		25°C	20	175		20	175		pA	
		Full range		5			5		nA	
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9		V	
		Full range	5 to -0.9			5 to -0.9				
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu\text{A}$	25°C	3.8	4.1		3.8	4.1		V	
		Full range	3.7			3.7				
	$I_O = -2 \text{ mA}$	25°C	3.5	3.9		3.5	3.9			
		Full range	3.4			3.4				
	$I_O = -20 \text{ mA}$	25°C	1.5	2.3		1.5	2.3			
		Full range	1.5			1.5				
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu\text{A}$	25°C	-3.8	-4.2		-3.8	-4.2		V	
		Full range	-3.7			-3.7				
	$I_O = 2 \text{ mA}$	25°C	-3.5	-4.1		-3.5	-4.1			
		Full range	-3.4			-3.4				
	$I_O = 20 \text{ mA}$	25°C	-1.5	-2.4		-1.5	-2.4			
		Full range	-1.5			-1.5				
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3 \text{ V}$	$R_L = 600 \Omega$	25°C	80	91	80	91		dB	
			Full range	79		79				
		$R_L = 2 \text{ k}\Omega$	25°C	90	100	90	100			
			Full range	89		89				
		$R_L = 10 \text{ k}\Omega$	25°C	95	106	95	106			
			Full range	94		94				
r_i Input resistance	$V_{IC} = 0$	25°C	10 ¹²		10 ¹²				Ω	
c_i Input capacitance	$V_{IC} = 0$, See Figure 5	25°C Common mode	11		11				pF	
		25°C Differential	2.5		2.5					
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80		80				Ω	
$CMRR$ Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	70	89		70	89		dB	
		Full range	68			68				
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	82	99		82	99		dB	
		Full range	80			80				
I_{CC} Supply current (four amplifiers)	$V_O = 0$, No load	25°C	5.2	6.3	7.5	5.2	6.3	7.5	mA	
		Full range			7.5			7.5		
a_x Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2 \text{ k}\Omega$	25°C	120		120				dB	

[†] Full range is 0°C to 70°C.

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TLE2084C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2084C			TLE2084AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{OS}	Short-circuit output current	$V_O = 0$	$V_{ID} = 1$ V	25°C	-35	45	-35	45	mA
			$V_{ID} = -1$ V		45		45		

[†] Full range is 0°C to 70°C.

TLE2084C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2084C			TLE2084AC			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR+	Positive slew rate	$V_O(PP) = \pm 2.3$ V, $AVD = -1$, $R_L = 2$ kΩ, $C_L = 100$ pF, See Figure 1	25°C	35		35			V/μs	
			Full range	22		22				
	Negative slew rate		25°C	38		38			V/μs	
			Full range	22		22				
t_s	Settling time	$AVD = -1$, 2-V step, $R_L = 1$ kΩ, $C_L = 100$ pF	To 10 mV	25°C	0.25	0.25			μs	
			To 1 mV		0.4	0.4				
V_n	Equivalent input noise voltage	$R_S = 20$ Ω, See Figure 3	$f = 10$ Hz	25°C	28	28			nV/√Hz	
			$f = 10$ kHz		11.6	11.6				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage		$f = 10$ Hz to 10 kHz	25°C	6	6			μV	
			$f = 0.1$ Hz to 10 Hz		0.6	0.6				
I_n	Equivalent input noise current	$V_{IC} = 0$,	$f = 10$ kHz	25°C	2.8	2.8			fA/√Hz	
THD + N	Total harmonic distortion plus noise	$V_O(PP) = 5$ V, $f = 1$ kHz, $R_S = 25$ Ω	$AVD = 10$, $R_L = 2$ kΩ,	25°C	0.013%	0.013%				
B ₁	Unity-gain bandwidth	$V_I = 10$ mV, $C_L = 25$ pF,	$R_L = 2$ kΩ, See Figure 2	25°C	9.4	9.4			MHz	
B _{OM}	Maximum output-swing bandwidth	$V_O(PP) = 4$ V, $R_L = 2$ kΩ ,	$AVD = -1$, $C_L = 25$ pF	25°C	2.8	2.8			MHz	
φ _m	Phase margin at unity gain	$V_I = 10$ mV, $C_L = 25$ pF,	$R_L = 2$ kΩ, See Figure 2	25°C	56°	56°				

[†] Full range is 0°C to 70°C.

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PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2084C			TLE2084AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	25°C	-1.6	7		-0.5	4		mV
		Full range		9.1			6.1		
		Full range	10.1	30		10.1	30		
αV_{IO} Temperature coefficient of input offset voltage									$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4	25°C	15	100		15	100		pA
		Full range		1.4			1.4		
		25°C	25	175		25	175		
I_{IB} Input bias current		Full range		5			5		nA
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9		V
		Full range	15 to -10.9			15 to -10.9			
		25°C	13.8	14.1		13.8	14.1		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu\text{A}$	Full range	13.7			13.7			V
		25°C	13.5	13.9		13.5	13.9		
	$I_O = -2 \text{ mA}$	Full range	13.4			13.4			
		25°C	11.5	12.3		11.5	12.3		
	$I_O = -20 \text{ mA}$	Full range	11.5			11.5			
		25°C	-13.8	-14.2		-13.8	-14.2		
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu\text{A}$	Full range	-13.7			-13.7			V
		25°C	-13.7	-14		-13.7	-14		
	$I_O = 2 \text{ mA}$	Full range	-13.6			-13.6			
		25°C	-11.5	-12.4		-11.5	-12.4		
	$I_O = 20 \text{ mA}$	Full range	-11.5			-11.5			
		25°C	-11.5			-11.5			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96	80	96		dB
			Full range	79		79			
		$R_L = 2 \text{ k}\Omega$	25°C	90	109	90	109		
			Full range	89		89			
		$R_L = 10 \text{ k}\Omega$	25°C	95	118	95	118		
			Full range	94		94			
r_i Input resistance	$V_{IC} = 0$	25°C	1012			1012			Ω
c_i Input capacitance	$V_{IC} = 0$, See Figure 5	25°C Common mode	7.5			7.5			pF
		25°C Differential	2.5			2.5			
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80			80			Ω
$CMRR$ Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	80	98		80	98		dB
		Full range	79			79			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	82	99		82	99		dB
		Full range	81			81			
I_{CC} Supply current (four amplifiers)	$V_O = 0$, No load	25°C	5.2	6.5	7.5	5.2	6.5	7.5	mA
		Full range			7.5			7.5	
a_x Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2 \text{ k}\Omega$	25°C	120			120			dB

[†] Full range is 0°C to 70°C.

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TLE2084C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2084C			TLE2084AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{OS}	Short-circuit output current $V_O = 0$	$V_{ID} = 1$ V $V_{ID} = -1$ V	25°C	-30	-45	-30	-45	-30	mA
				30	48	30	48	30	

† Full range is 0°C to 70°C.

TLE2084C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2084C			TLE2084AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate $V_{O(PP)} = 10$ V, $A_{VD} = -1$, $R_L = 2$ kΩ, $C_L = 100$ pF, See Figure 1	25°C	25	40		25	40		V/μs
		Full range	22			22			
SR-	Negative slew rate $A_{VD} = -1$, 10-V step, $R_L = 1$ kΩ, $C_L = 100$ pF	25°C	30	45		30	45		V/μs
		Full range	25			25			
t_s	Settling time $A_{VD} = -1$, 10-V step, $R_L = 1$ kΩ, $C_L = 100$ pF	To 10 mV	25°C	0.4		0.4			μs
		To 1 mV		1.5		1.5			
V_n	Equivalent input noise voltage $R_S = 20$ Ω, See Figure 3	f = 10 Hz	25°C	28		28			nV/√Hz
		f = 10 kHz		11.6		11.6			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage $R_S = 20$ Ω, See Figure 3	f = 10 Hz to 10 kHz	25°C	6		6			μV
		f = 0.1 Hz to 10 Hz		0.6		0.6			
I_n	Equivalent input noise current	$V_{IC} = 0$, $f = 10$ kHz	25°C	2.8		2.8			fA/√Hz
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20$ V, $A_{VD} = 10$, $f = 1$ kHz, $R_L = 2$ kΩ, $R_S = 25$ Ω	25°C	0.008%		0.008%			
B1	Unity-gain bandwidth	$V_I = 10$ mV, $R_L = 2$ kΩ, $C_L = 25$ pF, See Figure 2	25°C	8	10	8	10		MHz
B _{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20$ V, $A_{VD} = -1$, $R_L = 2$ kΩ, $C_L = 25$ pF	25°C	478	637	478	637		kHz
ϕ_m	Phase margin at unity gain	$V_I = 10$ mV, $R_L = 2$ kΩ, $C_L = 25$ pF, See Figure 2	25°C	57°		57°			

† Full range is 0°C to 70°C.

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TLE2084M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2084M			TLE2084AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage $V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	25°C	-1.6	7		-0.5	4		mV
αV_{IO}		Full range		12.5			9.5		
I_{IO}	Input offset current $V_{IC} = 0$, $V_O = 0$, See Figure 4	25°C	15	100		15	100		pA
I_{IB}		Full range		20			20		nA
		25°C	20	175		20	175		pA
		Full range		65			65		nA
V_{ICR}	Common-mode input voltage range $R_S = 50 \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9		V
		Full range	5 to -0.8			5 to -0.8			
V_{OM+}	$I_O = -200 \mu A$	25°C	3.8	4.1		3.8	4.1		V
		Full range	3.6			3.6			
	$I_O = -2 mA$	25°C	3.5	3.9		3.5	3.9		
		Full range	3.3			3.3			
	$I_O = -20 mA$	25°C	1.5	2.3		1.5	2.3		
		Full range	1.4			1.4			
V_{OM-}	$I_O = 200 \mu A$	25°C	-3.8	-4.2		-3.8	-4.2		V
		Full range	-3.6			-3.6			
	$I_O = 2 mA$	25°C	-3.5	-4.1		-3.5	-4.1		
		Full range	-3.3			-3.3			
	$I_O = 20 mA$	25°C	-1.5	-2.4		-1.5	-2.4		
		Full range	-1.4			-1.4			
A_{VD}	$V_O = \pm 2.3 V$	$R_L = 600 \Omega$	25°C	80	91	80	91		dB
			Full range	78		78			
		$R_L = 2 k\Omega$	25°C	90	100	90	100		
			Full range	88		88			
		$R_L = 10 k\Omega$	25°C	95	106	95	106		
			Full range	93		93			
r_i	Input resistance	$V_{IC} = 0$	25°C	10 ¹²		10 ¹²			Ω
c_i	Input capacitance	$V_{IC} = 0$, See Figure 5	25°C Common mode	11		11			pF
			25°C Differential	2.5		2.5			
z_o	Open-loop output impedance	$f = 1$ MHz	25°C	80		80			Ω
$CMRR$	Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	70	89	70	89		dB
			Full range	68		68			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5$ V to ± 15 V, $V_O = 0$, $R_S = 50 \Omega$	25°C	82	99	82	99		dB
			Full range	80		80			
I_{CC}	Supply current (four amplifiers)	$V_O = 0$, No load	25°C	5.2	6.3	7.5	5.2	6.3	mA
			Full range		7.5			7.5	
a_x	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2 k\Omega$	25°C	120		120			dB

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is $-55^\circ C$ to $125^\circ C$.

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TLE2084M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	TA	TLE2084M			TLE2084AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{OS} Short-circuit output current	$V_O = 0$	25°C	–35			–35			mA
				45			45		

TLE2084M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER	TEST CONDITIONS	TA†	TLE2084M			TLE2084AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR + Positive slew rate	$V_O(PP) = \pm 2.3$ V, $A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, See Figure 1	25°C	35			35			V/μs	
		Full range	18*			18*				
SR – Negative slew rate		25°C	38			38			V/μs	
		Full range	18*			18*				
t_s Settling time	$A_{VD} = -1$, 2-V step, $R_L = 1\text{ k}\Omega$, $C_L = 100\text{ pF}$	To 10 mV	25°C	0.25		0.25			μs	
		To 1 mV		0.4		0.4				
V_n Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, See Figure 3	f = 10 Hz	25°C	28		28			nV/√Hz	
		f = 10 kHz		11.6		11.6				
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6		6			μV	
		f = 0.1 Hz to 10 Hz		0.6		0.6				
I_n Equivalent input noise current	$V_{IC} = 0$,	$f = 10$ kHz	25°C	2.8		2.8			fA/√Hz	
THD + N Total harmonic distortion plus noise	$V_O(PP) = 5$ V, $f = 1$ kHz, $R_S = 25\text{ }\Omega$	$A_{VD} = 10$, $R_L = 2\text{ k}\Omega$,	25°C	0.013%		0.013%				
B ₁ Unity-gain bandwidth	$V_I = 10$ mV, $C_L = 25\text{ pF}$, See Figure 2	$R_L = 2\text{ k}\Omega$,	25°C	9.4		9.4			MHz	
B _{OM} Maximum output-swing bandwidth	$V_O(PP) = 4$ V, $R_L = 2\text{ k}\Omega$, $C_L = 25\text{ pF}$	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega$,	25°C	2.8		2.8			MHz	
φ _m Phase margin at unity gain	$V_I = 10$ mV, $C_L = 25\text{ pF}$, See Figure 2	$R_L = 2\text{ k}\Omega$,	25°C	56°		56°				

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is –55°C to 125°C.

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TLE2084M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2084M			TLE2084AM			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{IO}	Input offset voltage $V_{IC} = 0$, $V_O = 0$, $R_S = 50 \Omega$	25°C	-1.6	7		-0.5	4		mV	
αV_{IO}		Full range		12.5			7.5			
I_{IO}	Input offset current $V_{IC} = 0$, $V_O = 0$, See Figure 4	Full range	10.1	30*		10.1	30*		$\mu\text{V}/^\circ\text{C}$	
I_{IB}		25°C	15	100		15	100		pA	
		Full range		20			20		nA	
		25°C	25	175		25	175		pA	
		Full range		65			65		nA	
V_{ICR}	Common-mode input voltage range $R_S = 50 \Omega$	25°C	15	15		15	15		V	
		to	to			to	to			
		-11	-11.9			-11	-11.9			
		Full range	15			15				
		to				to				
		-10.8				-10.8				
V_{OM+}	Maximum positive peak output voltage swing $I_O = -200 \mu\text{A}$	25°C	13.8	14.1		13.8	14.1		V	
		Full range	13.6			13.6				
		25°C	13.5	13.9		13.5	13.9			
		Full range	13.3			13.3				
		25°C	11.5	12.3		11.5	12.3			
		Full range	11.4			11.4				
V_{OM-}	Maximum negative peak output voltage swing $I_O = 200 \mu\text{A}$	25°C	-13.8	-14.2		-13.8	-14.2		V	
		Full range	-13.6			-13.6				
		25°C	-13.5	-14		-13.5	-14			
		Full range	-13.3			-13.3				
		25°C	-11.5	-12.4		-11.5	-12.4			
		Full range	-11.4			-11.4				
A_{VD}	Large-signal differential voltage amplification $V_O = \pm 10$ V	$R_L = 600 \Omega$	25°C	80	96	80	96		dB	
			Full range	78		78				
		$R_L = 2 \text{ k}\Omega$	25°C	90	109	90	109			
			Full range	88		88				
		$R_L = 10 \text{ k}\Omega$	25°C	95	118	95	118			
			Full range	93		93				
r_i	Input resistance	$V_{IC} = 0$	25°C	1012		1012			Ω	
c_i	Input capacitance	$V_{IC} = 0$, See Figure 5	Common mode	25°C	7.5	7.5			pF	
			Differential	25°C	2.5	2.5				
z_o	Open-loop output impedance	$f = 1$ MHz	25°C	80		80			Ω	
$CMRR$	Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50 \Omega$	25°C	80	98	80	98		dB	
			Full range	78		78				
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5$ V to ± 15 V, $V_O = 0$, $R_S = 50 \Omega$	25°C	82	99	82	99		dB	
			Full range	80		80				
I_{CC}	Supply current (four amplifiers)	$V_O = 0$, No load	25°C	5.2	6.5	7.5	5.2	6.5	7.5	mA
			Full range		7.5			7.5		
a_x	Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2 \text{ k}\Omega$	25°C	120		120			dB	

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C .

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TLE2084M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A	TLE2084M			TLE2084AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{OS} Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1$ V	-30	-45	-30	-45	-30	mA
			$V_{ID} = -1$ V	30	48	30	48	30	

TLE2084M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER	TEST CONDITIONS	T_A^\dagger	TLE2084M			TLE2084AM			UNIT		
			MIN	TYP	MAX	MIN	TYP	MAX			
SR+ Positive slew rate	$V_O(PP) = 10$ V, $A_{VD} = -1$, $R_L = 2$ kΩ, $C_L = 100$ pF, See Figure 1	25°C	25	40	40	25	40	40	V/μs		
		Full range	17		17						
SR- Negative slew rate		25°C	30	45	45	30	45	45	V/μs		
		Full range	20		20						
t_s Settling time	$A_{VD} = -1$, 10-V step, $R_L = 1$ kΩ, $C_L = 100$ pF	To 10 mV	25°C	0.4	0.4	0.4	1.5	1.5	μs		
		To 1 mV									
V_n Equivalent input noise voltage	$R_S = 20$ Ω, See Figure 3	$f = 10$ Hz	25°C	28	28	28	11.6	11.6	nV/√Hz		
		$f = 10$ kHz		11.6							
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage		$f = 10$ Hz to 10 kHz	25°C	6	6	6	0.6	0.6			
		$f = 0.1$ Hz to 10 Hz		0.6							
I_n Equivalent input noise current	$V_{IC} = 0$,	$f = 10$ kHz	25°C	2.8		2.8			fA/√Hz		
THD + N Total harmonic distortion plus noise	$V_O(PP) = 20$ V, $A_{VD} = 10$, $f = 1$ kHz, $R_L = 2$ kΩ, $R_S = 25$ Ω		25°C	0.008%		0.008%					
B ₁ Unity-gain bandwidth	$V_I = 10$ mV, $R_L = 2$ kΩ, $C_L = 25$ pF, See Figure 2	25°C	8*	10		8*	10		MHz		
B _{OM} Maximum output-swing bandwidth	$V_O(PP) = 20$ V, $A_{VD} = -1$, $R_L = 2$ kΩ, $C_L = 25$ pF	25°C	478*	637		478*	637		kHz		
ϕ_m Phase margin at unity gain	$V_I = 10$ mV, $R_L = 2$ kΩ, $C_L = 25$ pF, See Figure 2	25°C	57°			57°					

*On products compliant to MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C .

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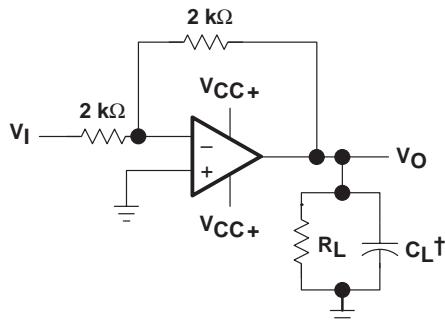
TLE2084Y electrical characteristics at $V_{CC\pm} = \pm 15$ V, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TLE2084Y			UNIT	
		MIN	TYP	MAX		
V_{IO}	$V_{IC} = 0$, $R_S = 50 \Omega$			7	mV	
I_{IO}	$V_{IC} = 0$, $V_O = 0$	15	100		pA	
I_{IB}	See Figure 4		25	175	pA	
V_{ICR}	$R_S = 50 \Omega$	15	15		V	
		to	to			
		-11	11.9			
V_{OM+}	$I_O = -200 \mu\text{A}$	13.8	14.1		V	
	$I_O = -2 \text{ mA}$	13.5	13.9			
	$I_O = -20 \text{ mA}$	11.5	12.3			
V_{OM-}	$I_O = 200 \mu\text{A}$	-13.8	-14.2		V	
	$I_O = 2 \text{ mA}$	-13.5	-14			
	$I_O = 20 \text{ mA}$	-11.5	-12.4			
AVD	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	80	96	dB	
		$R_L = 2 \text{ k}\Omega$	90	109		
		$R_L = 10 \text{ k}\Omega$	95	118		
r_i	$V_{IC} = 0$		10^{12}		Ω	
c_i	$V_{IC} = 0$, See Figure 5	Common mode	7.5		pF	
		Differential	2.5			
z_o	$f = 1 \text{ MHz}$		80		Ω	
$CMRR$	$V_{IC} = V_{ICR\min}$, $R_S = 50 \Omega$	$V_O = 0$	80	98	dB	
k_{SVR}	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}$, $V_O = 0$, $R_S = 50 \Omega$		82	99	dB	
I_{CC}	$V_O = 0$, No load		5.2	6.5	7.5	mA
I_{OS}	$V_O = 0$	$V_{ID} = 1 \text{ V}$	-30	-45		mA
		$V_{ID} = -1 \text{ V}$	30	48		

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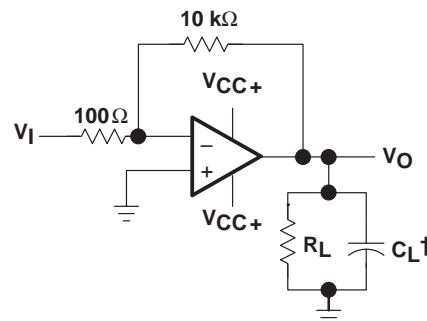
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PARAMETER MEASUREMENT INFORMATION



† Includes fixture capacitance

Figure 1. Slew-Rate Test Circuit



† Includes fixture capacitance

**Figure 2. Unity-Gain Bandwidth
and Phase-Margin Test Circuit**

† Includes fixture capacitance

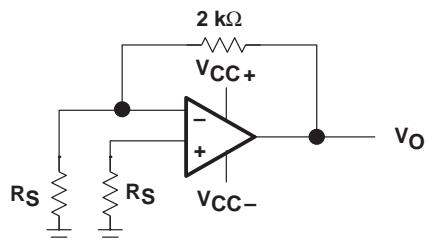
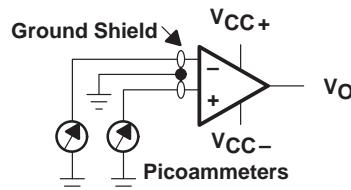


Figure 3. Noise-Voltage Test Circuit



**Figure 4. Input-Bias and Offset-
Current Test Circuit**

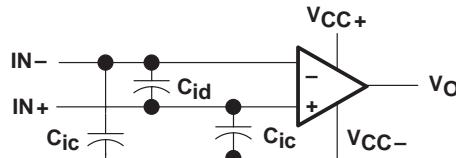


Figure 5. Internal Input Capacitance

typical values

Typical values presented in this data sheet represent the median (50% point) of device parametric performance.

input bias and offset current

At the picoampere bias-current level typical of the TLE208x and TLE208xA, accurate measurement of the bias becomes difficult. Not only does this measurement require a picoammeter, but test socket leakages can easily exceed the actual device bias currents. To accurately measure these small currents, Texas Instruments uses a two-step process. The socket leakage is measured using picoammeters with bias voltages applied but with no device in the socket. The device is then inserted in the socket and a second test is performed that measures both the socket leakage and the device input bias current. The two measurements are then subtracted algebraically to determine the bias current of the device.

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	Distribution	6, 7, 8
αV_{IO}	Input offset voltage temperature coefficient	Distribution	9, 10, 11
I_{IO}	Input offset current	vs Free-air temperature	12 – 15
I_{IB}	Input bias current	vs Free-air temperature vs Supply voltage	12 – 15 16
V_{ICR}	Common-mode input voltage range	vs Free-air temperature	17
V_{ID}	Differential input voltage	vs Output voltage	18, 19
V_{OM+}	Maximum positive peak output voltage	vs Output current vs Free-air temperature vs Supply voltage	20, 21 24, 25 26
V_{OM-}	Maximum negative peak output voltage	vs Output current vs Free-air temperature vs Supply voltage	22, 23 24, 25 26
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	27
V_O	Output voltage	vs Settling time	28
A_{VD}	Large-signal differential voltage amplification	vs Load resistance vs Free-air temperature	29 30, 31
A_{VD}	Small-signal differential voltage amplification	vs Frequency	32, 33
$CMRR$	Common-mode rejection ratio	vs Frequency vs Free-air temperature	34 35
k_{SVR}	Supply-voltage rejection ratio	vs Frequency vs Free-air temperature	36 37
I_{CC}	Supply current	vs Supply voltage vs Free-air temperature vs Differential input voltage	38, 39, 40 41, 42, 43 44 – 49
I_{OS}	Short-circuit output current	vs Supply voltage vs Elapsed time vs Free-air temperature	50 51 52
SR	Slew rate	vs Free-air temperature vs Load resistance vs Differential input voltage	53, 54 55 56
V_n	Equivalent input noise voltage	vs Frequency	57
V_n	Input-referred noise voltage	vs Noise bandwidth frequency Over a 10-second time interval	58 59
	Third-octave spectral noise density	vs Frequency bands	60
$THD + N$	Total harmonic distortion plus noise	vs Frequency	61, 62
B_1	Unity-gain bandwidth	vs Load capacitance	63
	Gain-bandwidth product	vs Free-air temperature vs Supply voltage	64 65
	Gain margin	vs Load capacitance	66
ϕ_m	Phase margin	vs Free-air temperature vs Supply voltage vs Load capacitance	67 68 69
	Phase shift	vs Frequency	32, 33

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TYPICAL CHARACTERISTICS

Table of Graphs (Continued)

		FIGURE
Noninverting large-signal pulse response	vs Time	70
Small-signal pulse response	vs Time	71
z_0	Closed-loop output impedance	72
a_X	Crosstalk attenuation	73

**DISTRIBUTION OF TLE2081
INPUT OFFSET VOLTAGE**

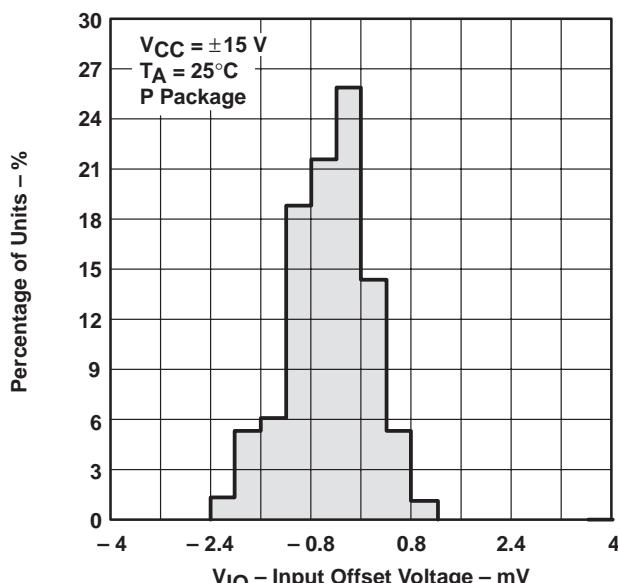


Figure 6

**DISTRIBUTION OF TLE2082
INPUT OFFSET VOLTAGE**

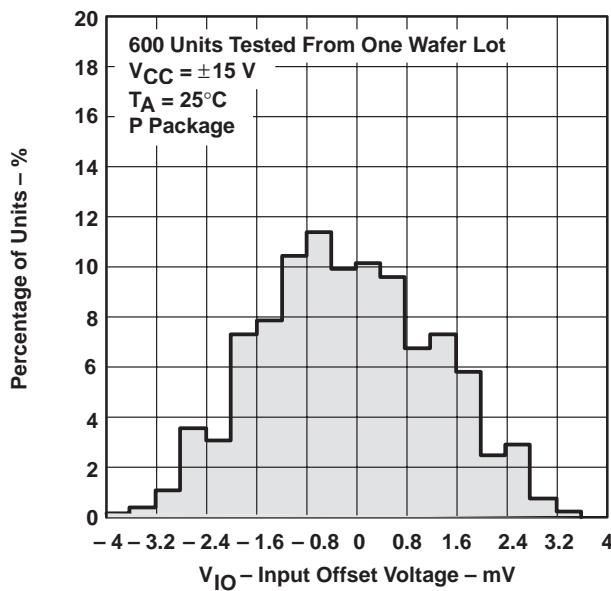


Figure 7

TYPICAL CHARACTERISTICS

DISTRIBUTION OF TLE2084 INPUT OFFSET VOLTAGE

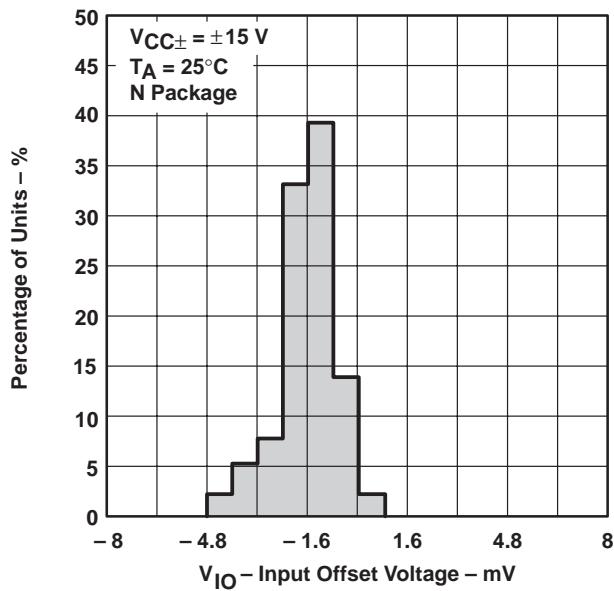


Figure 8

DISTRIBUTION OF TLE2081 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT

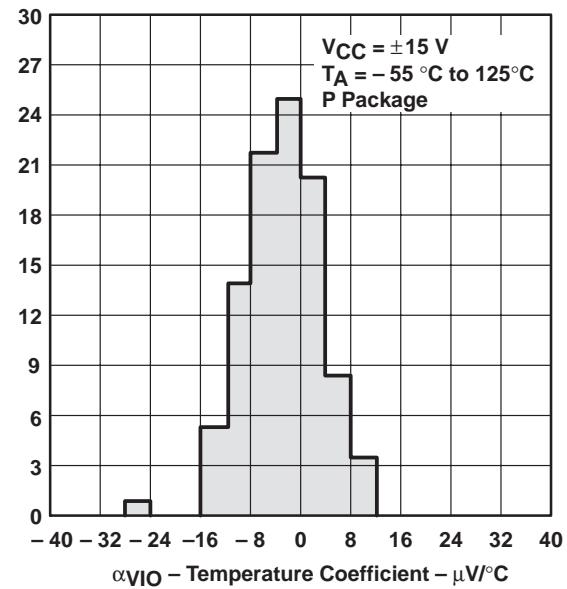


Figure 9

DISTRIBUTION OF TLE2082 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT

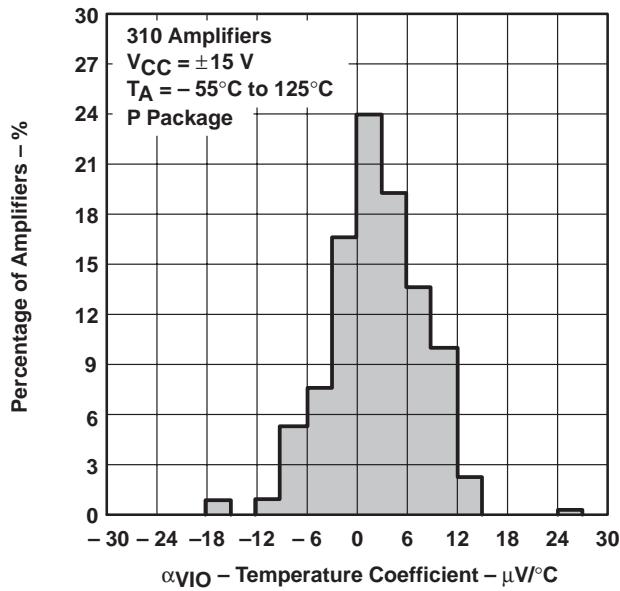


Figure 10

DISTRIBUTION OF TLE2084 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT

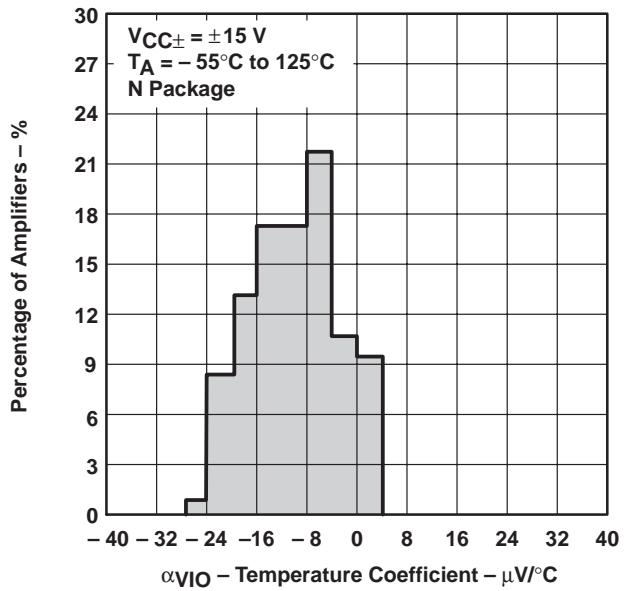


Figure 11

**TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
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TYPICAL CHARACTERISTICS[†]

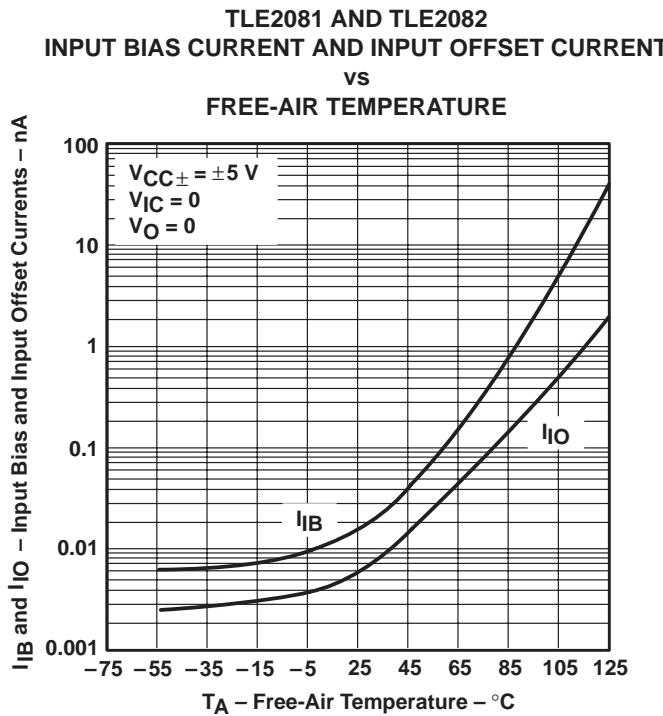


Figure 12

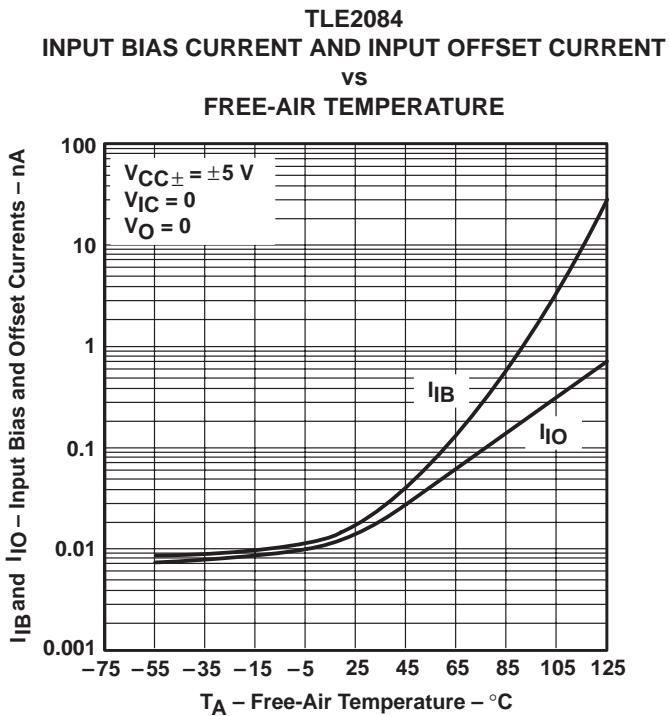


Figure 13

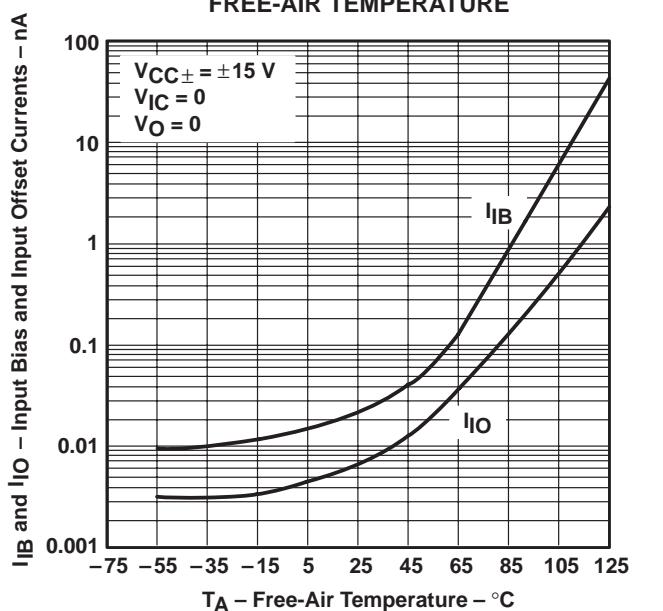


Figure 14

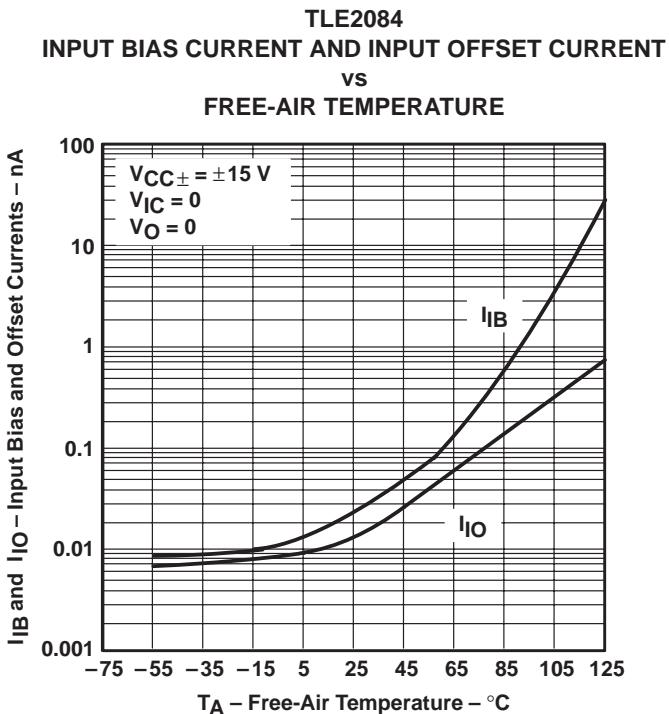


Figure 15

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS[†]

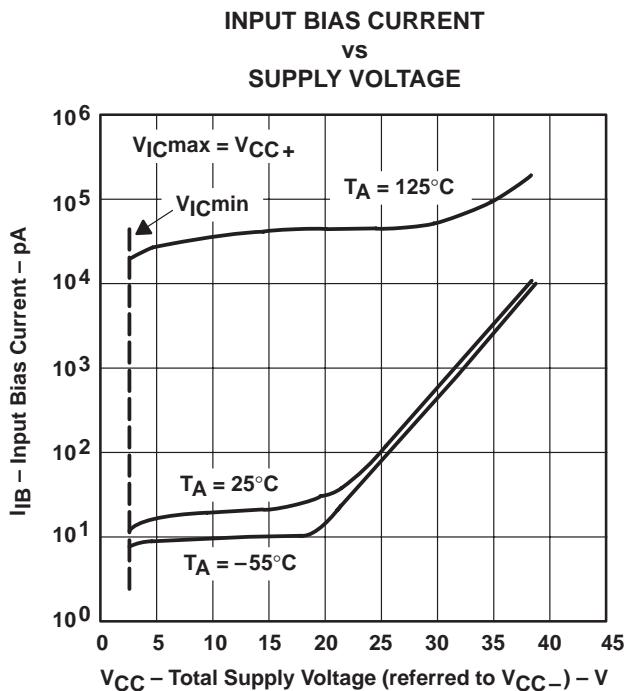


Figure 16

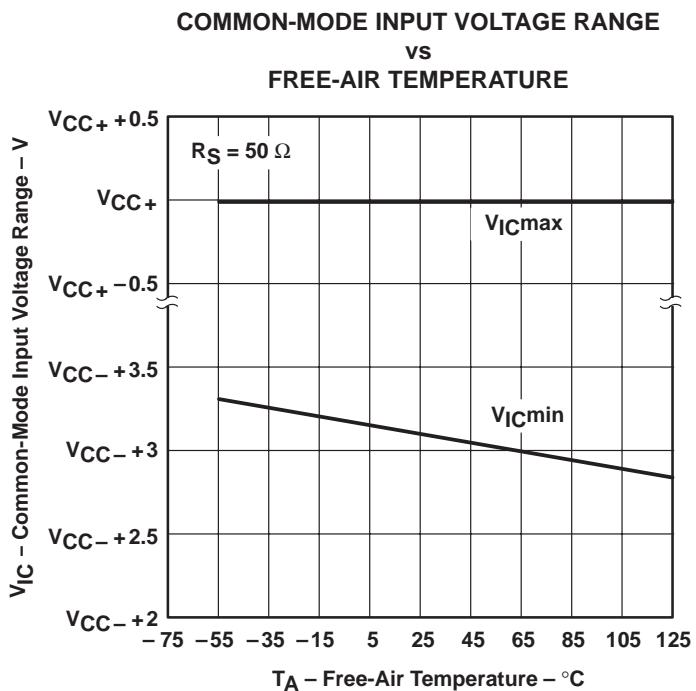


Figure 17

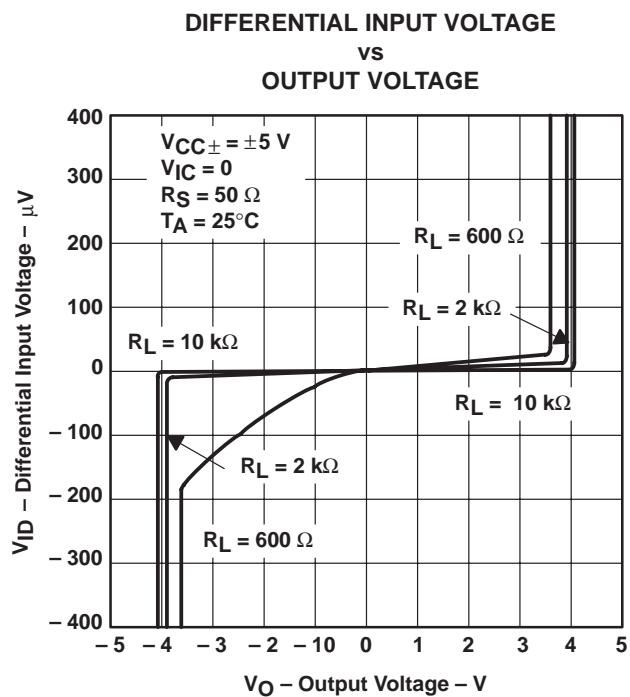


Figure 18

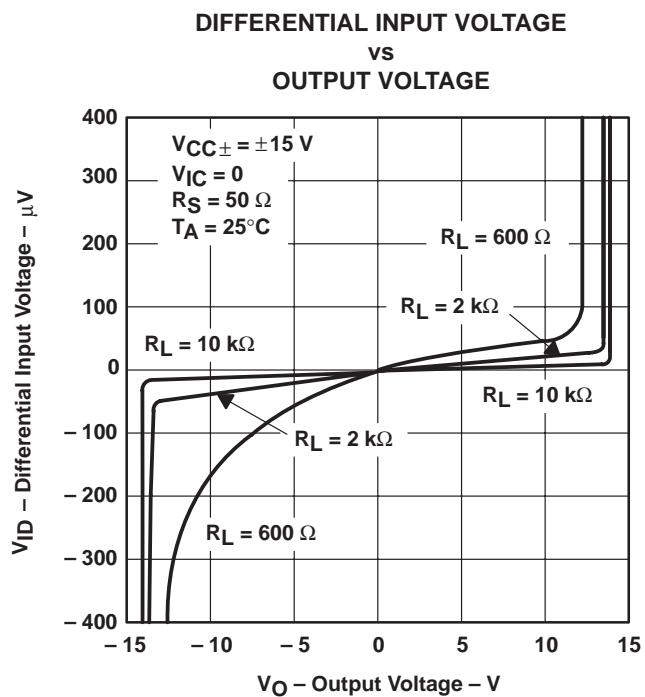


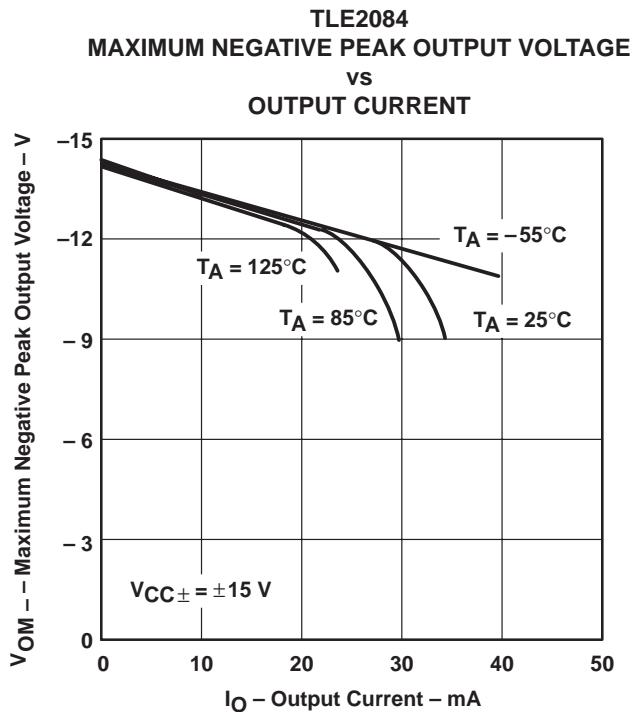
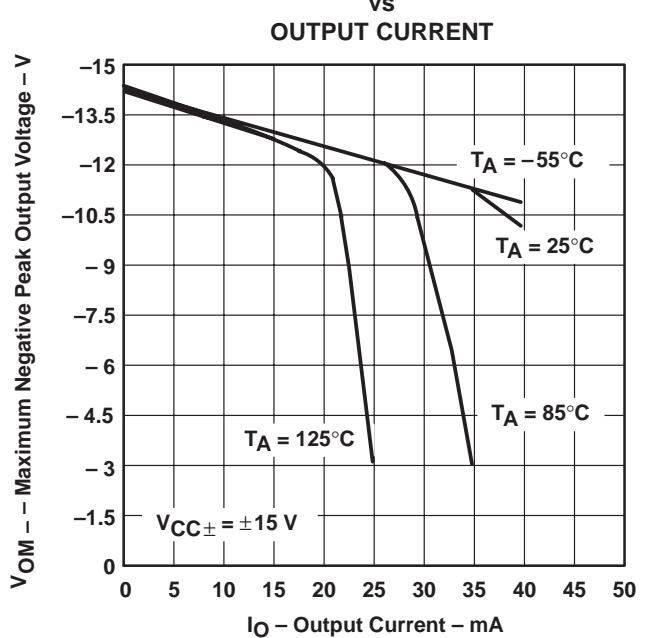
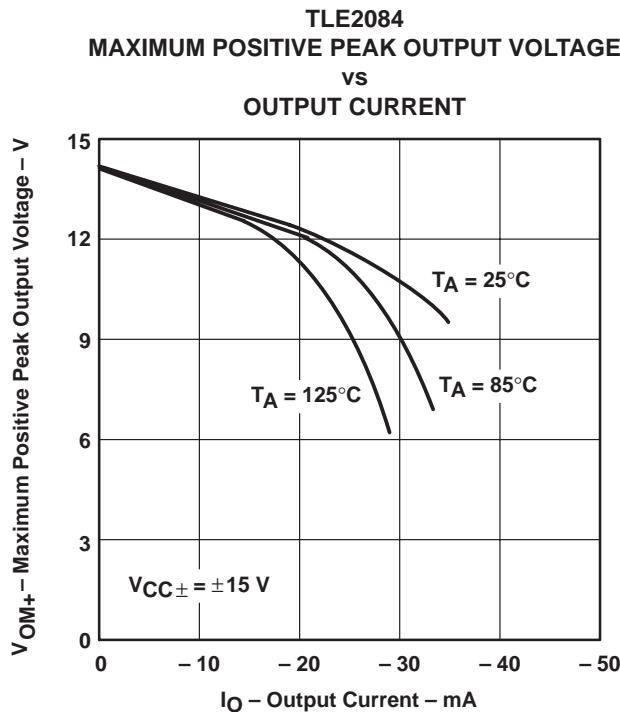
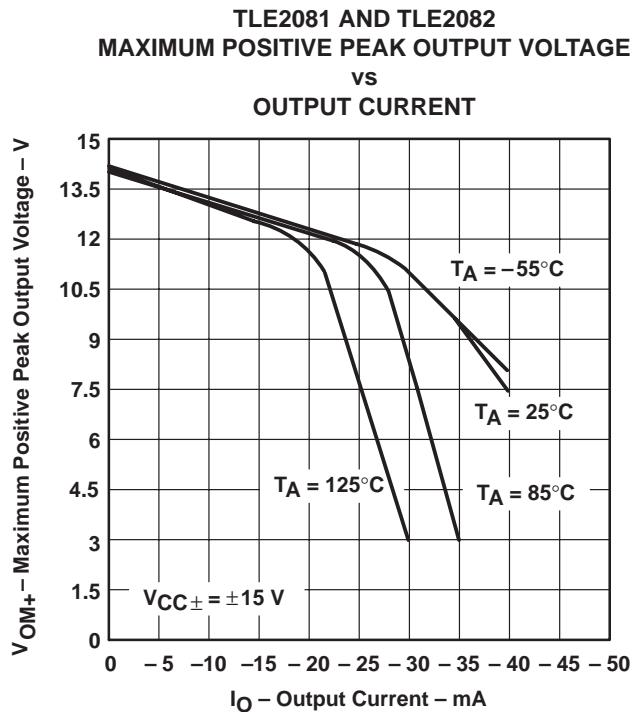
Figure 19

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

**TLE208x, TLE208xA, TLE208xY
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TYPICAL CHARACTERISTICS[†]



[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS[†]

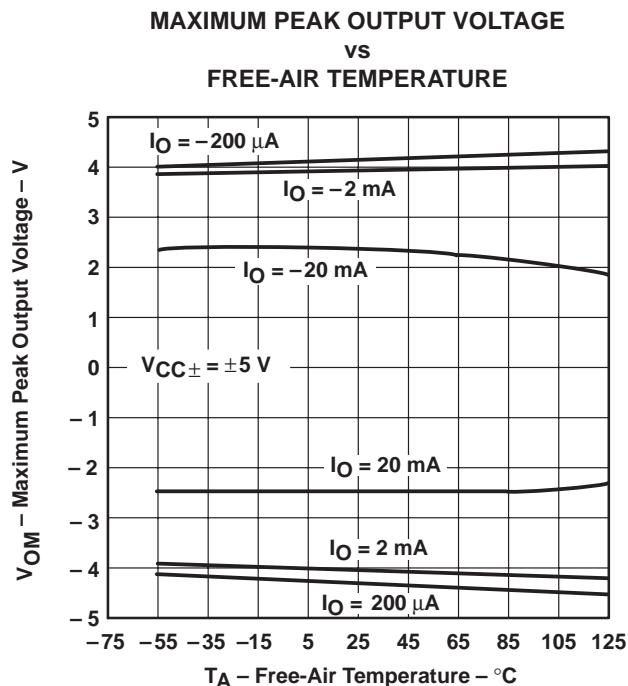


Figure 24

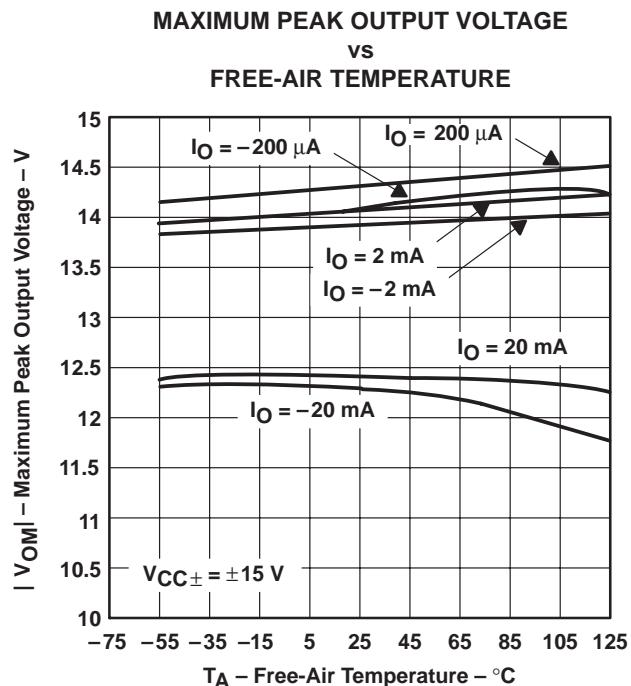


Figure 25

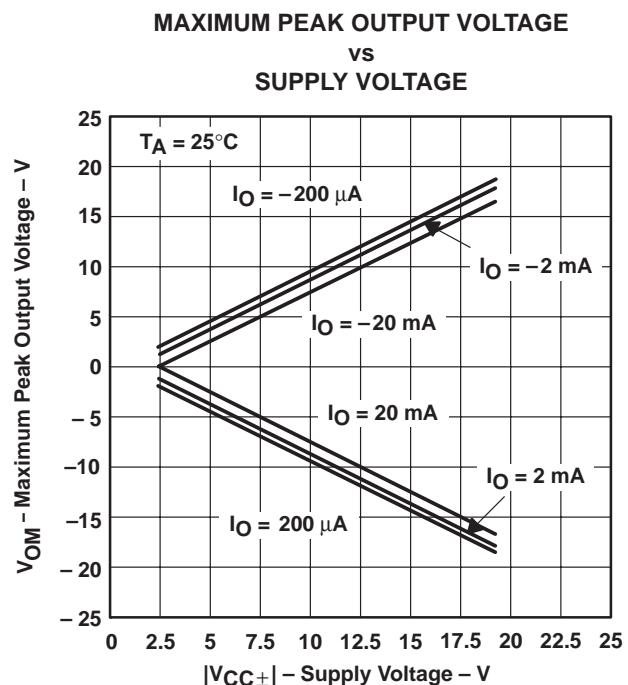


Figure 26

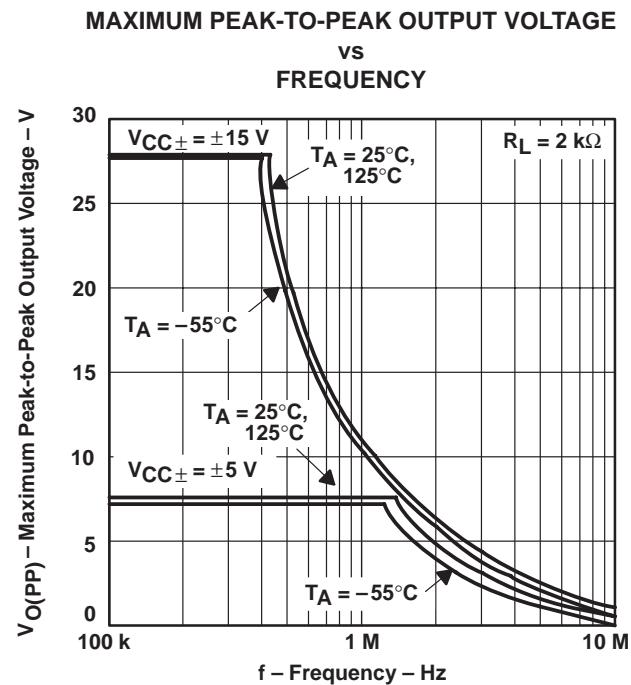


Figure 27

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

**TLE208x, TLE208xA, TLE208xY
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TYPICAL CHARACTERISTICS†

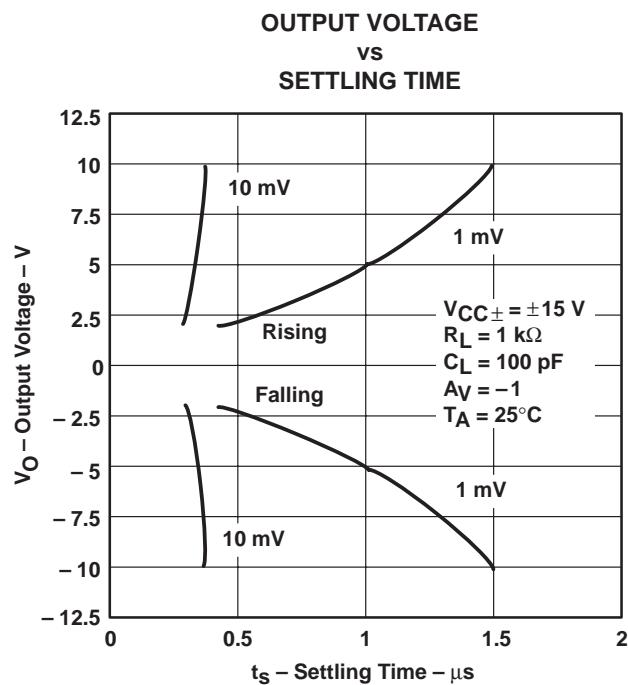


Figure 28

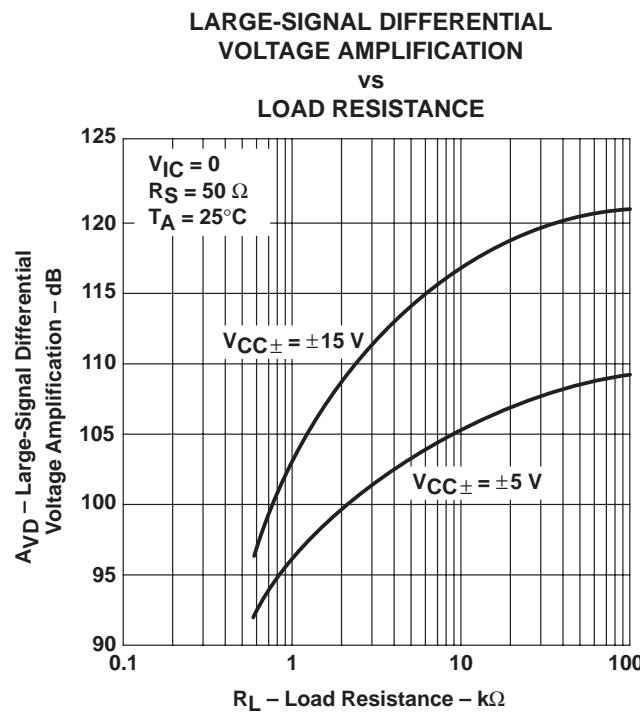


Figure 29

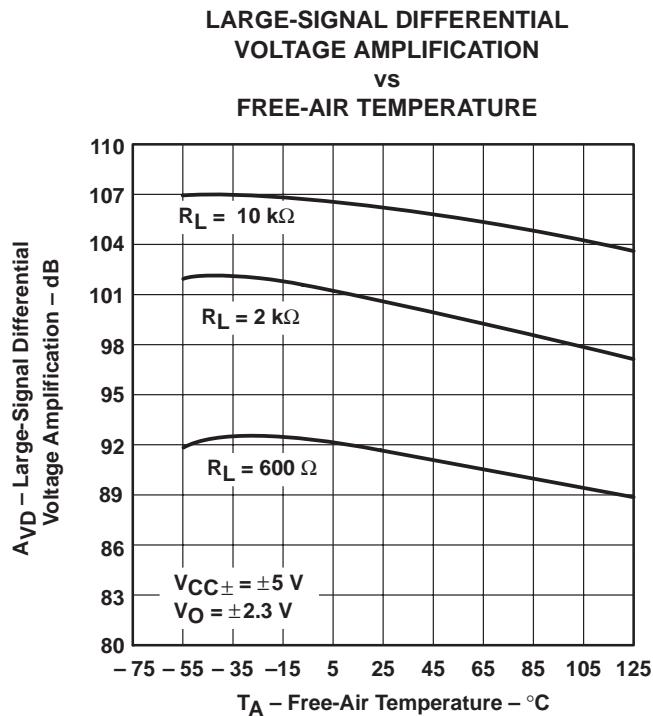


Figure 30

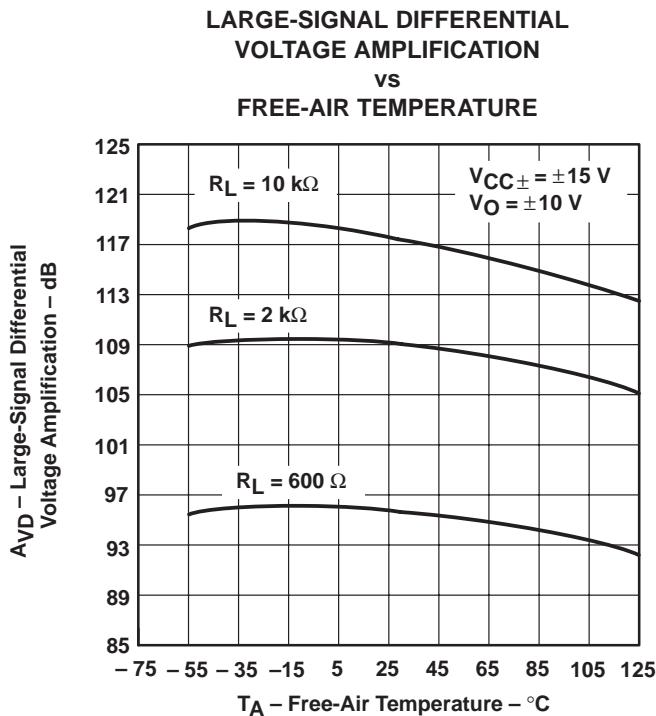


Figure 31

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

SMALL-SIGNAL DIFFERENTIAL VOLTAGE
 AMPLIFICATION AND PHASE SHIFT
 VS
 FREQUENCY

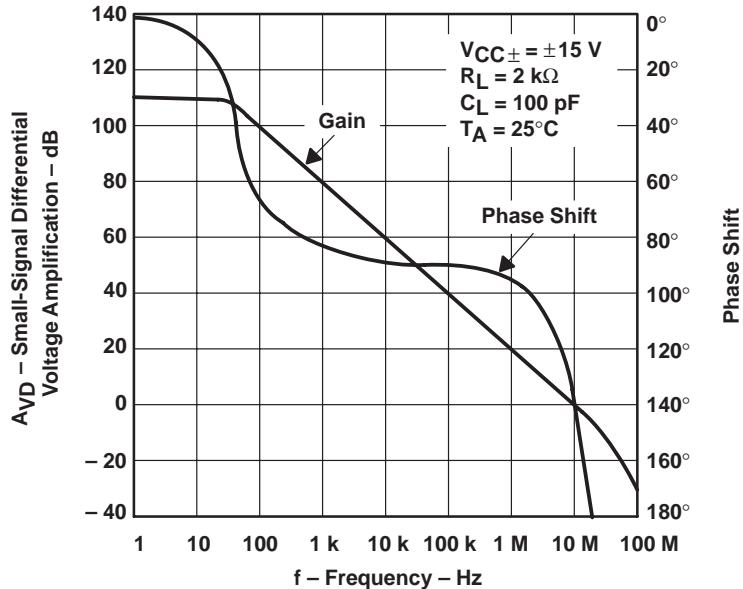


Figure 32

SMALL-SIGNAL DIFFERENTIAL VOLTAGE
 AMPLIFICATION AND PHASE SHIFT
 VS
 FREQUENCY

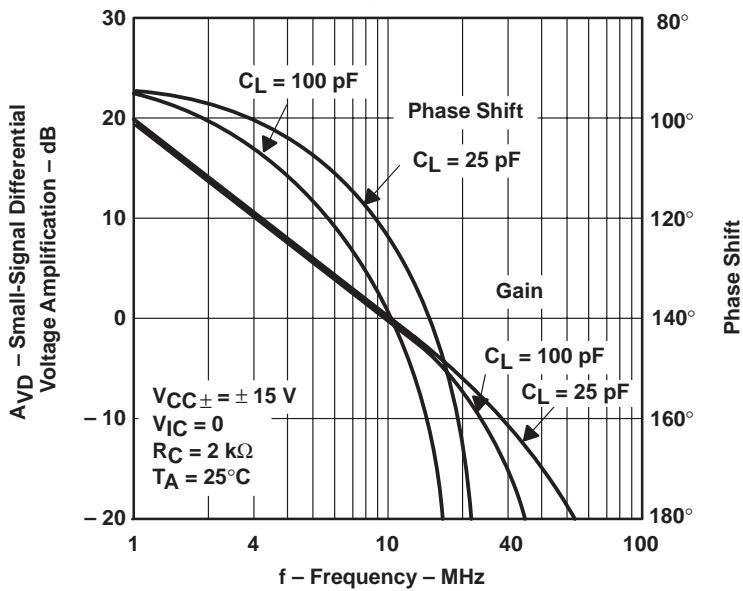


Figure 33

**TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
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TYPICAL CHARACTERISTICS[†]

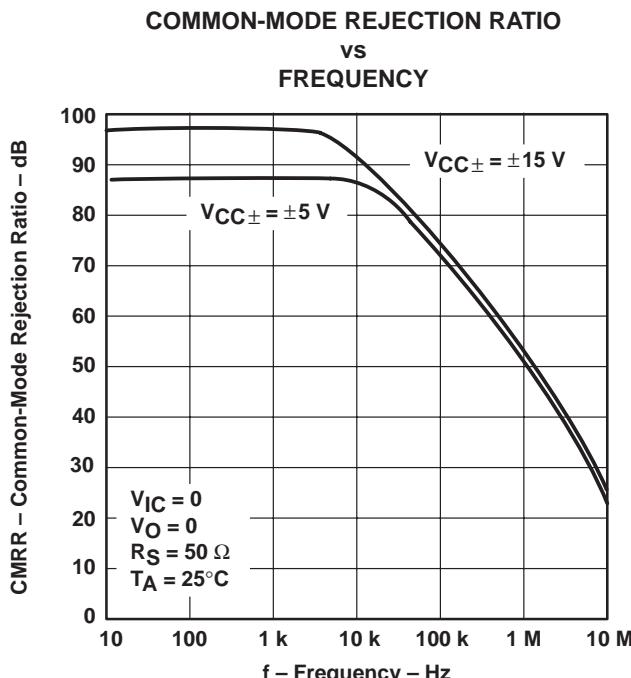


Figure 34

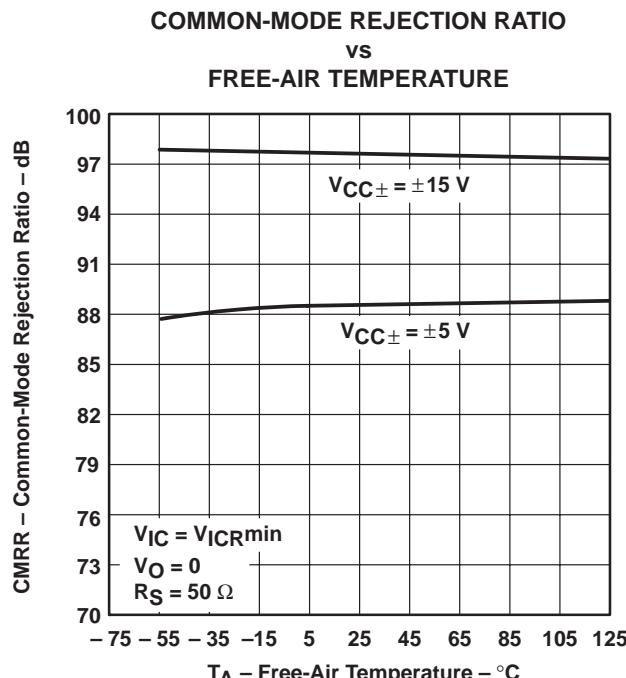


Figure 35

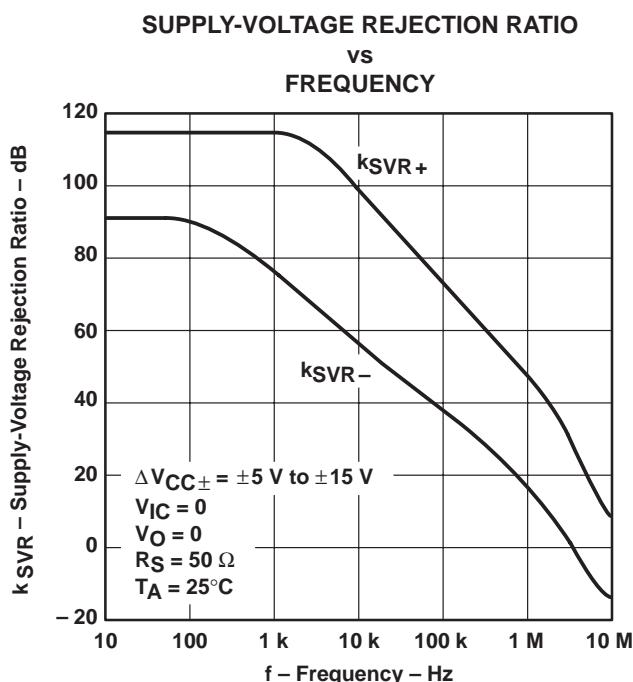


Figure 36

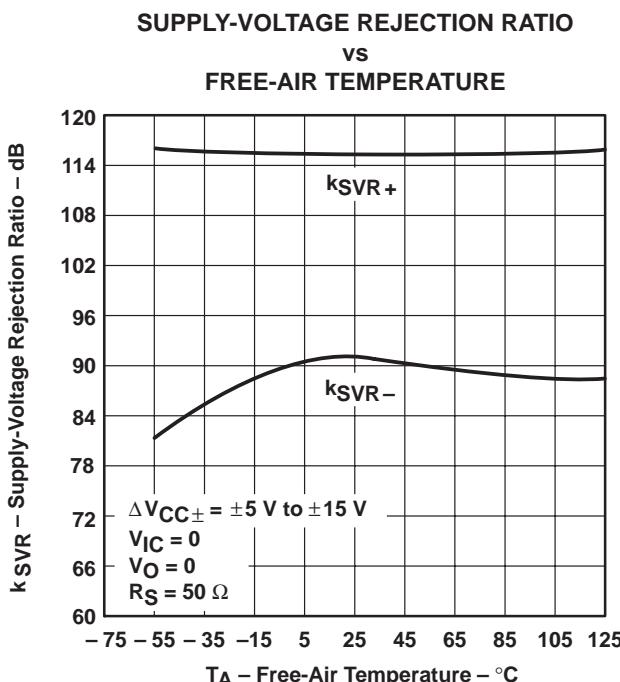


Figure 37

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS[†]

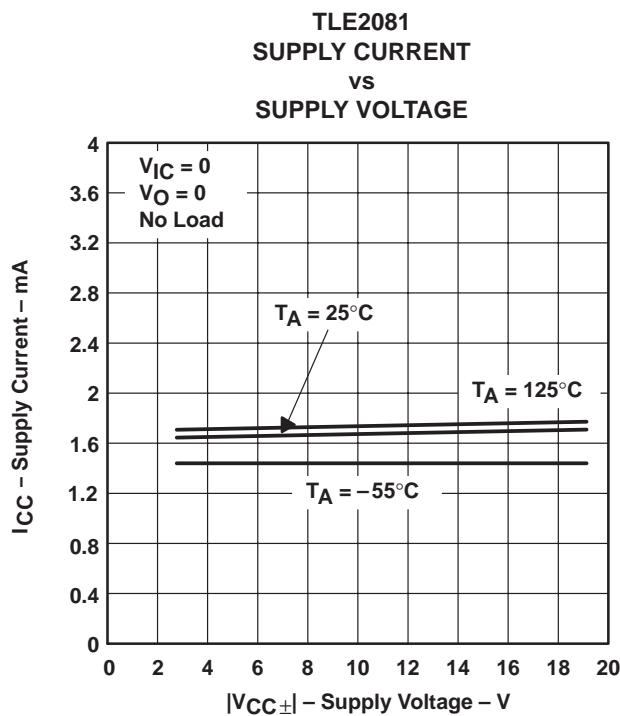


Figure 38

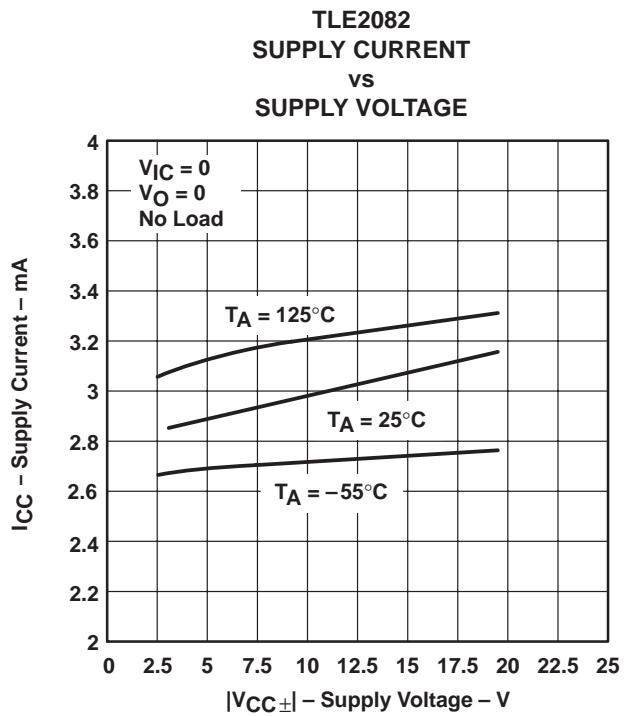


Figure 39

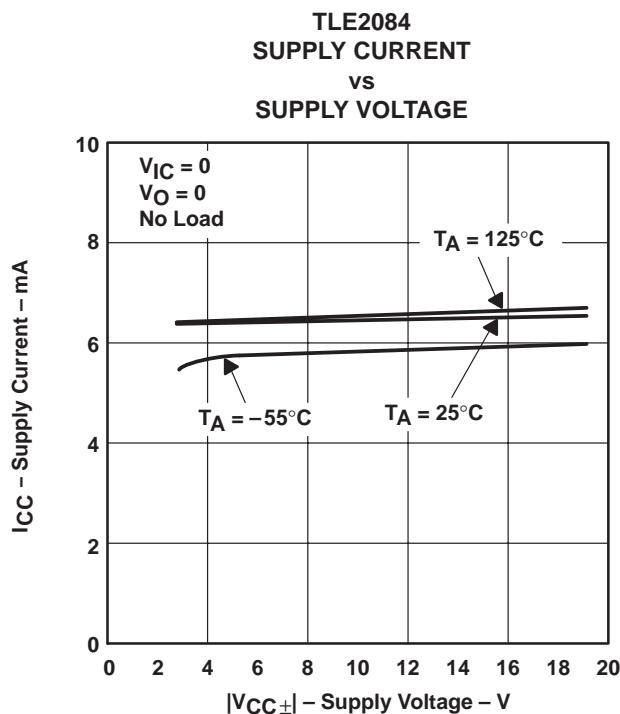


Figure 40

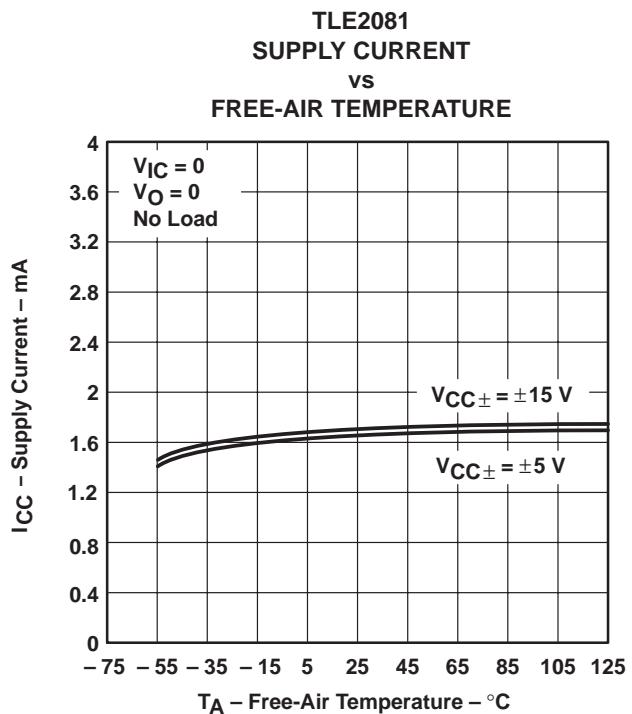


Figure 41

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

**TLE208x, TLE208xA, TLE208xY
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TYPICAL CHARACTERISTICS[†]

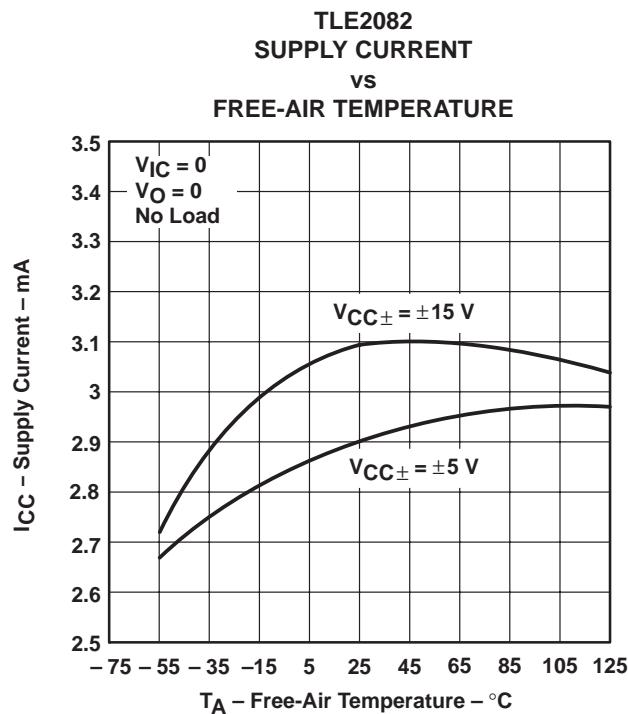


Figure 42

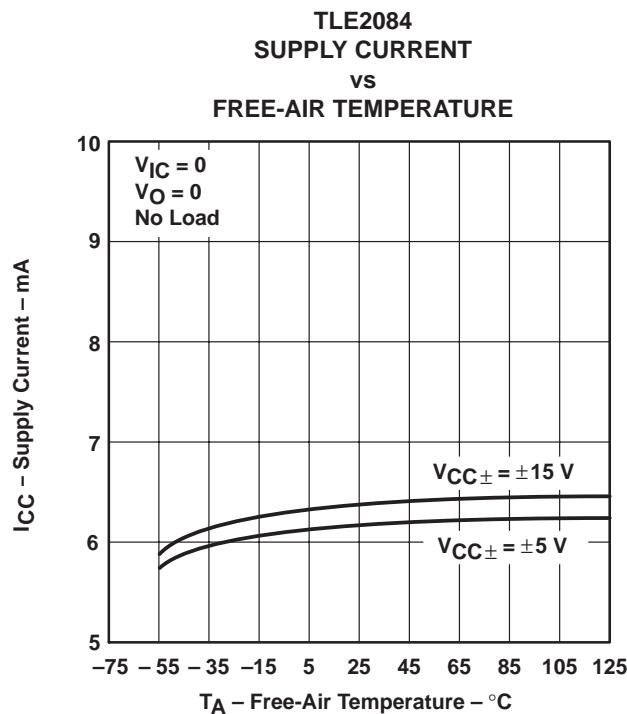


Figure 43

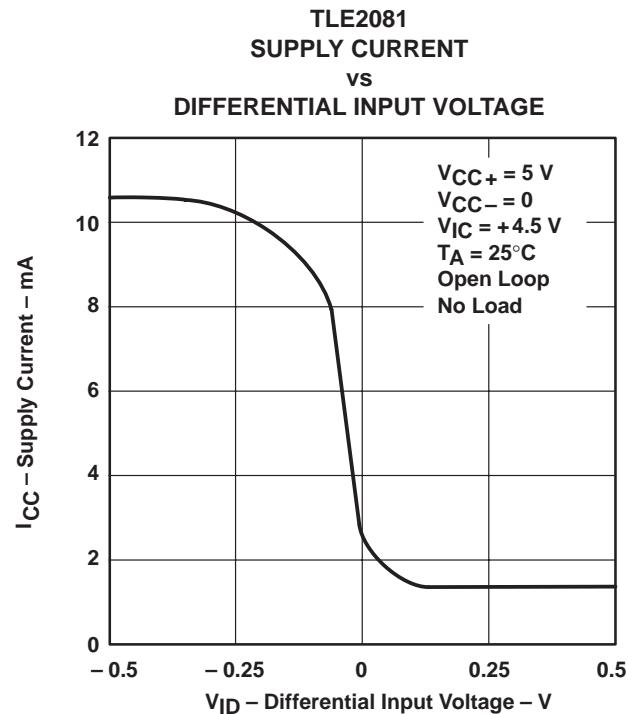


Figure 44

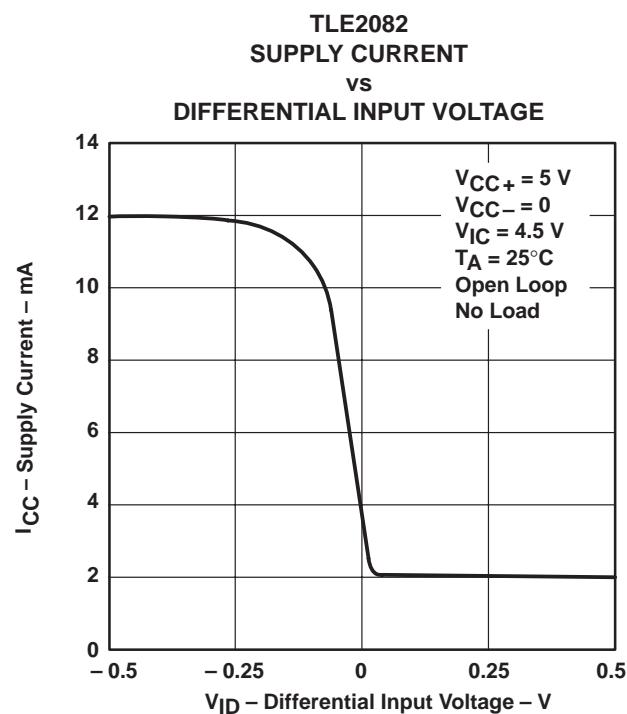


Figure 45

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

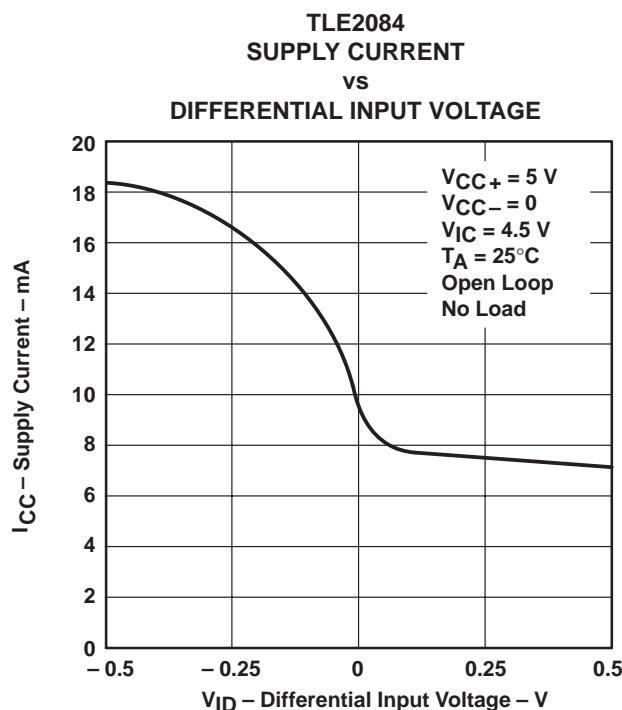


Figure 46

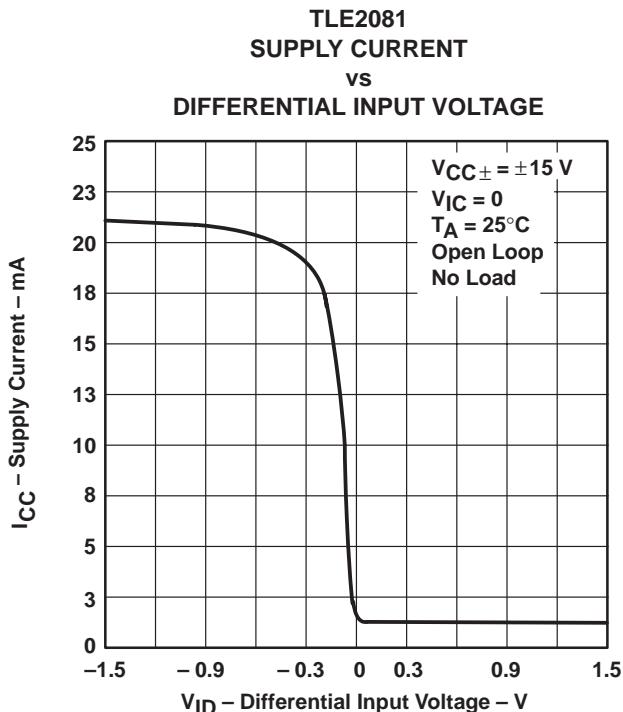


Figure 47

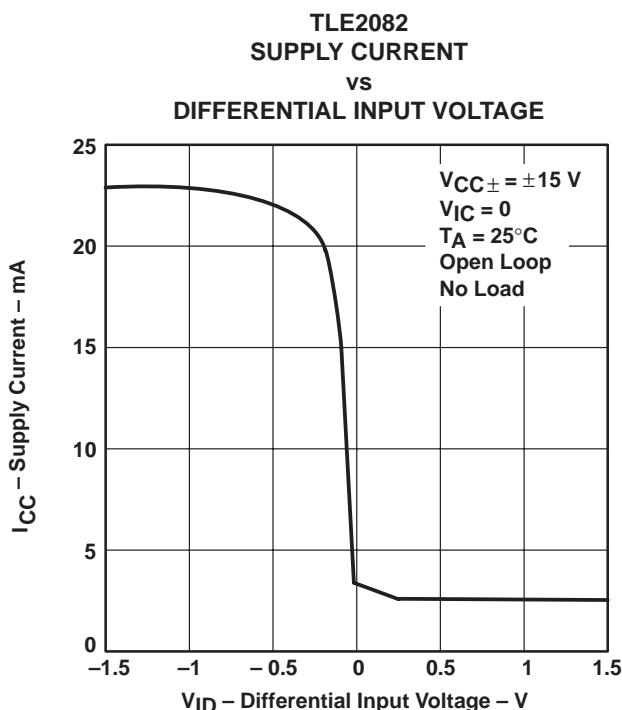


Figure 48

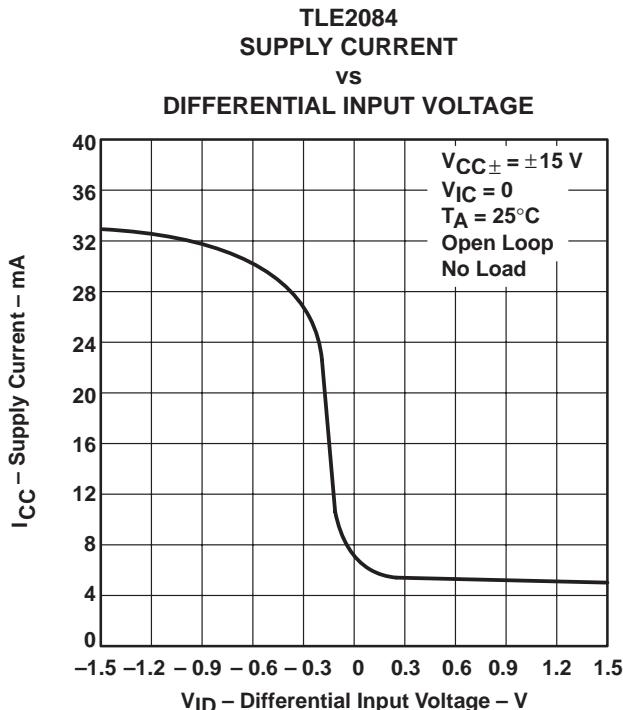


Figure 49

**TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS**

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TYPICAL CHARACTERISTICS[†]

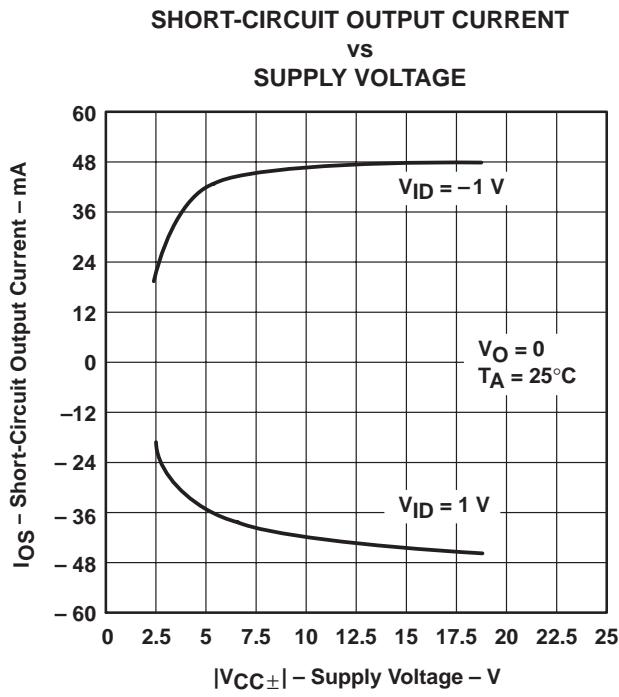


Figure 50

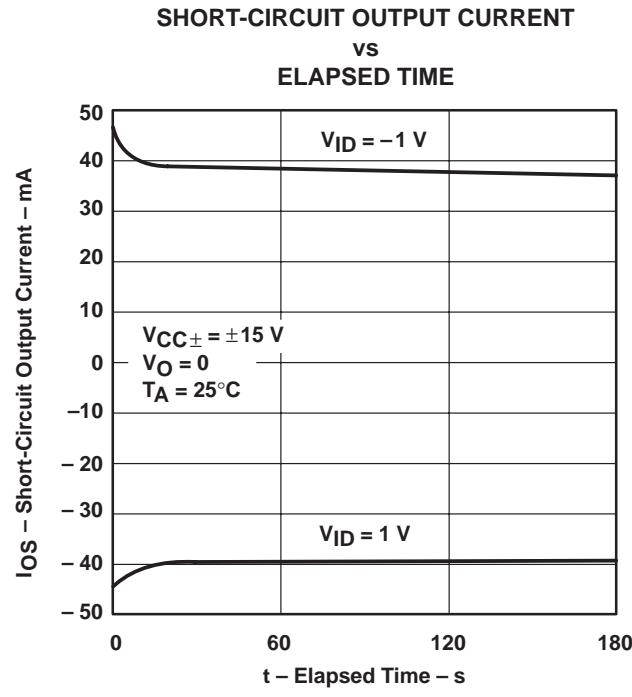


Figure 51

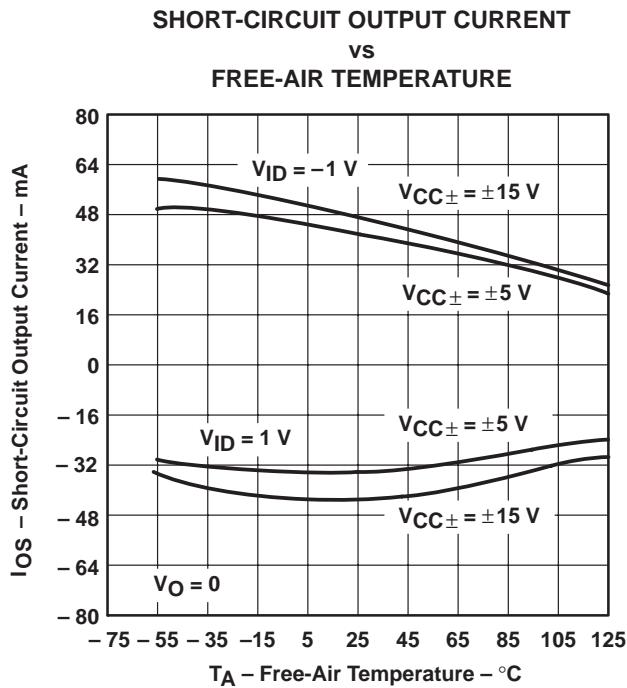


Figure 52

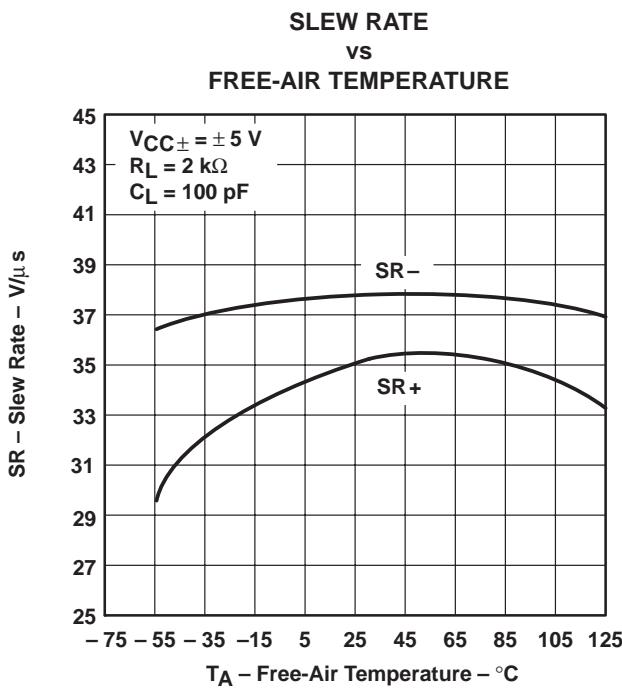
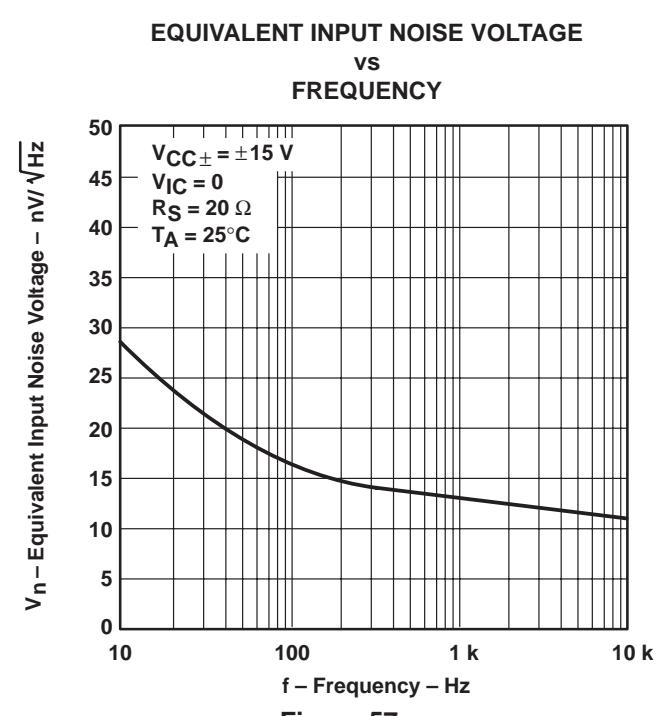
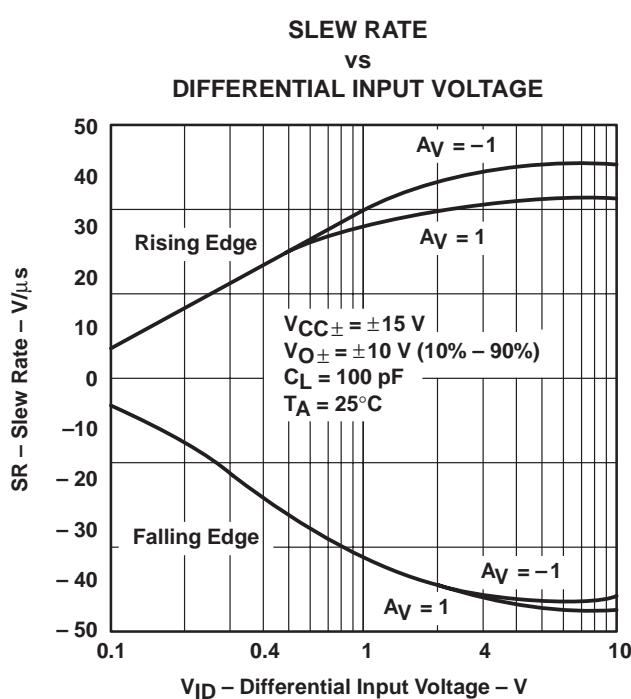
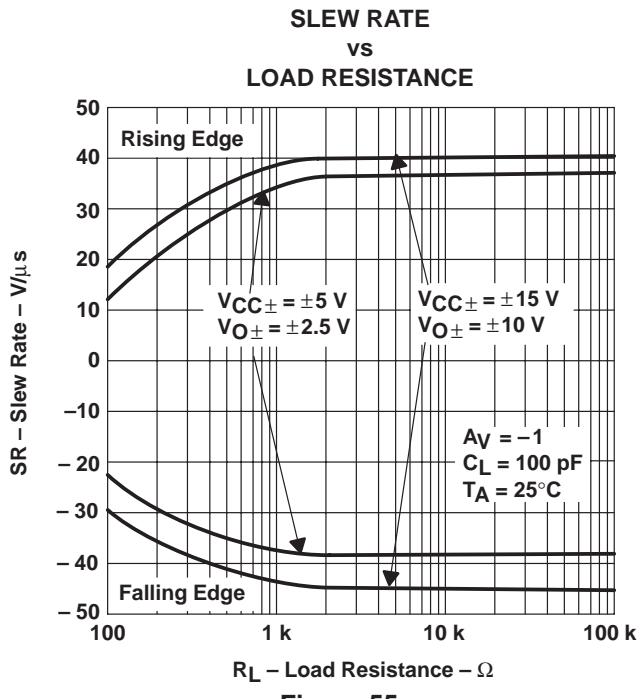
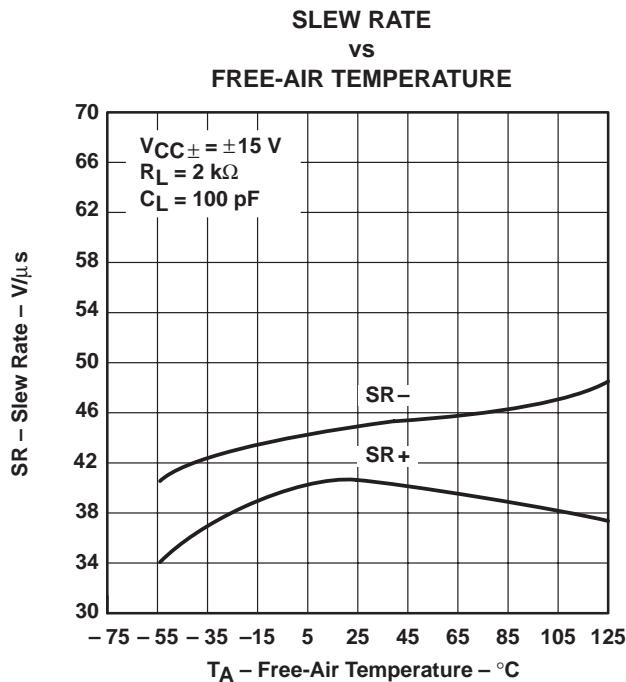


Figure 53

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS[†]



[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

**TLE208x, TLE208xA, TLE208xY
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TYPICAL CHARACTERISTICS

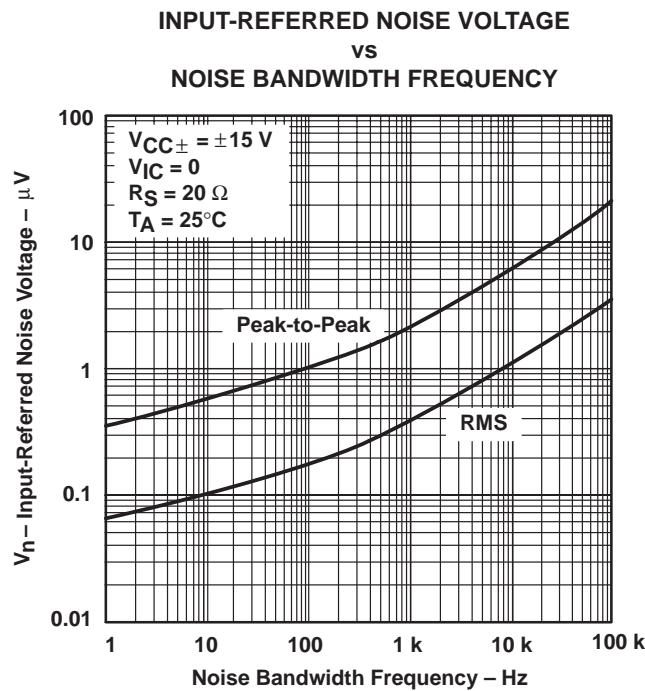


Figure 58

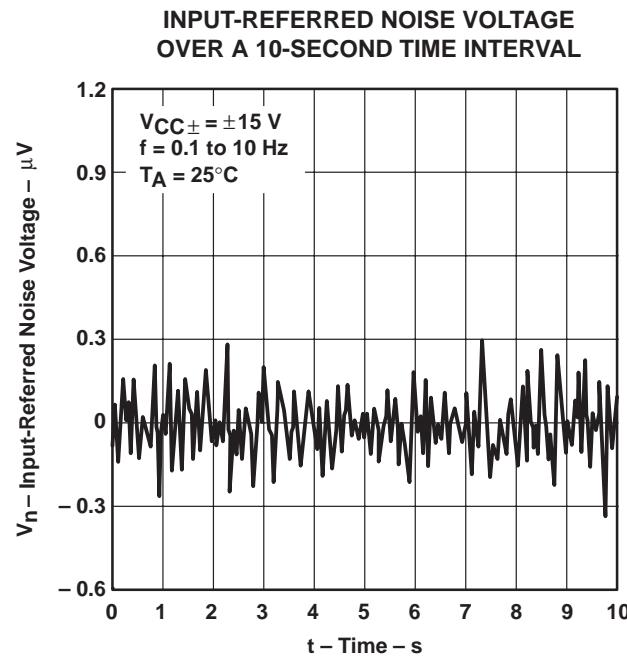


Figure 59

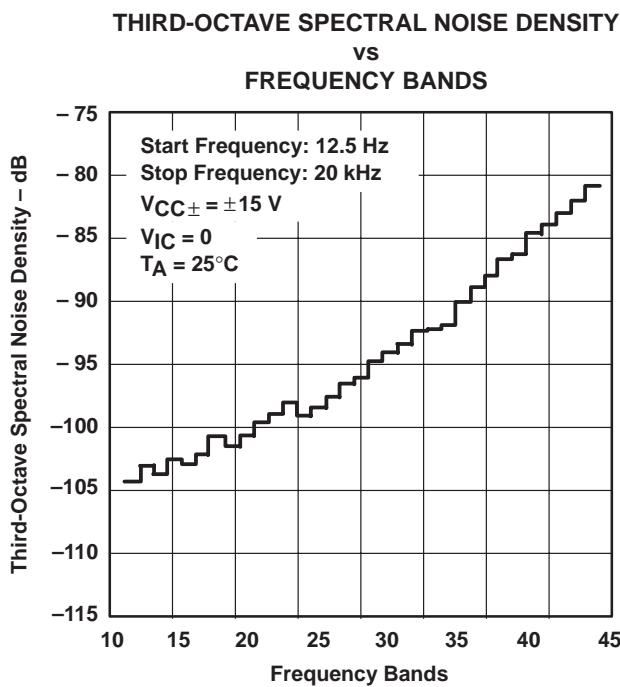


Figure 60

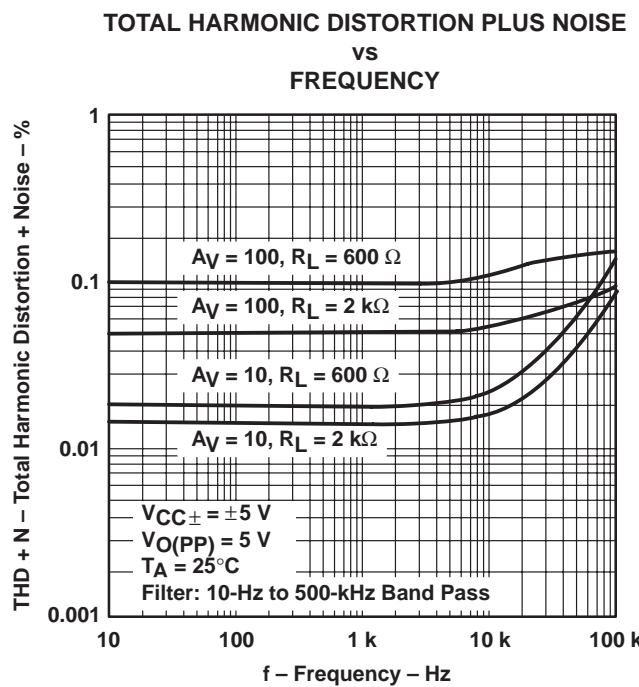


Figure 61

TYPICAL CHARACTERISTICS[†]

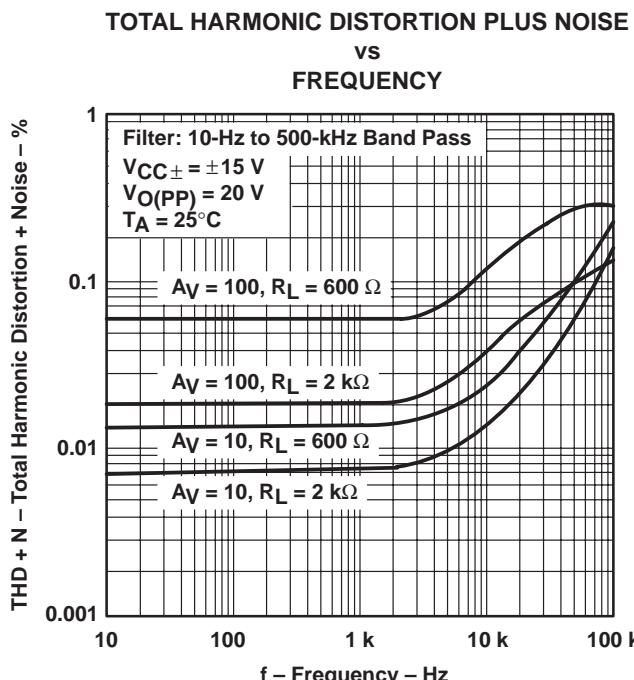


Figure 62

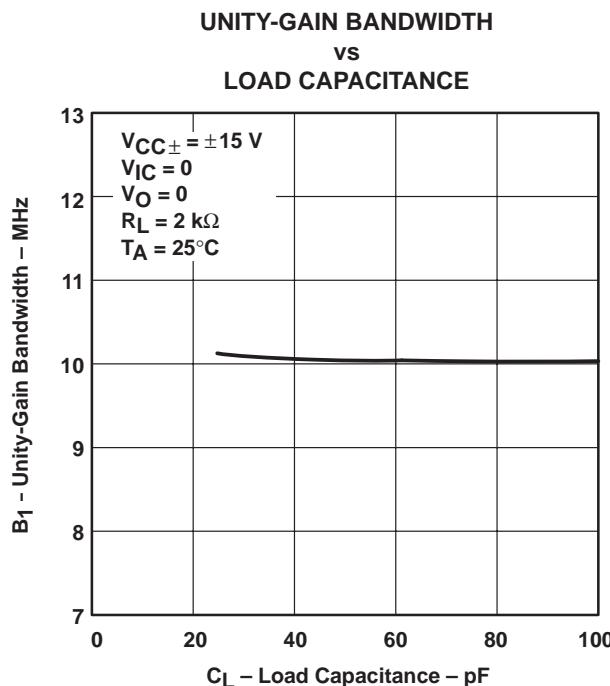


Figure 63

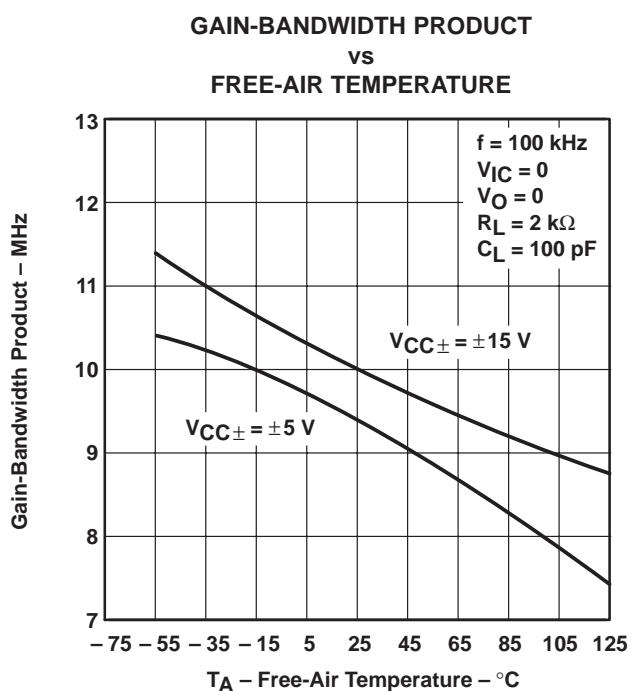


Figure 64

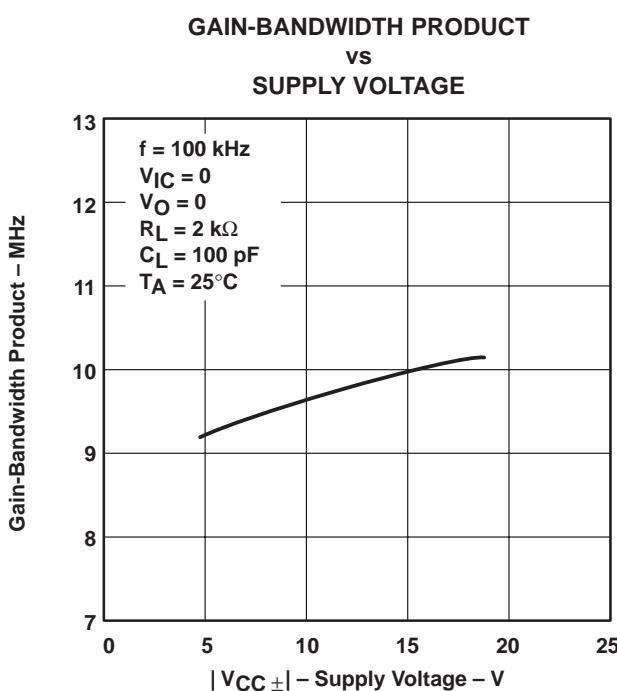


Figure 65

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

**TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS**

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TYPICAL CHARACTERISTICS[†]

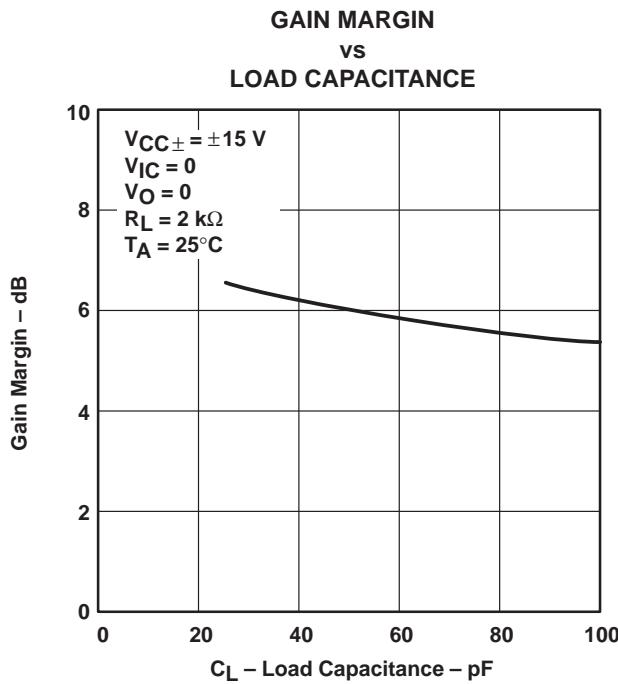


Figure 66

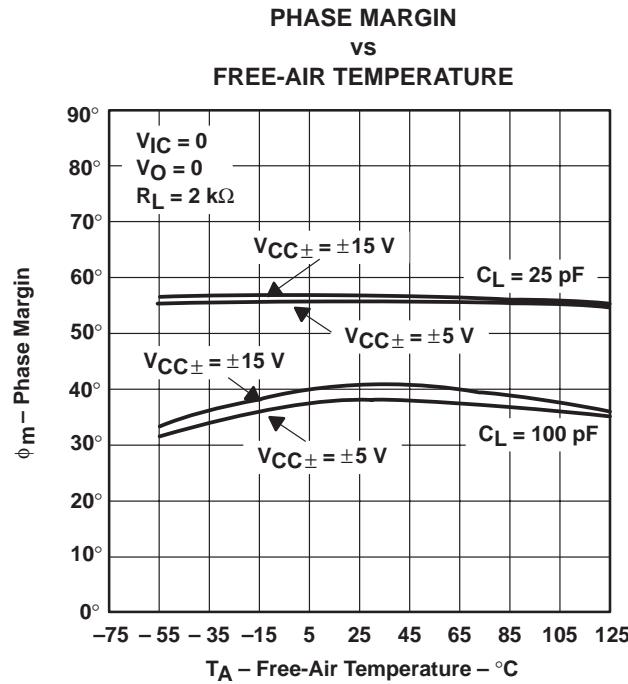


Figure 67

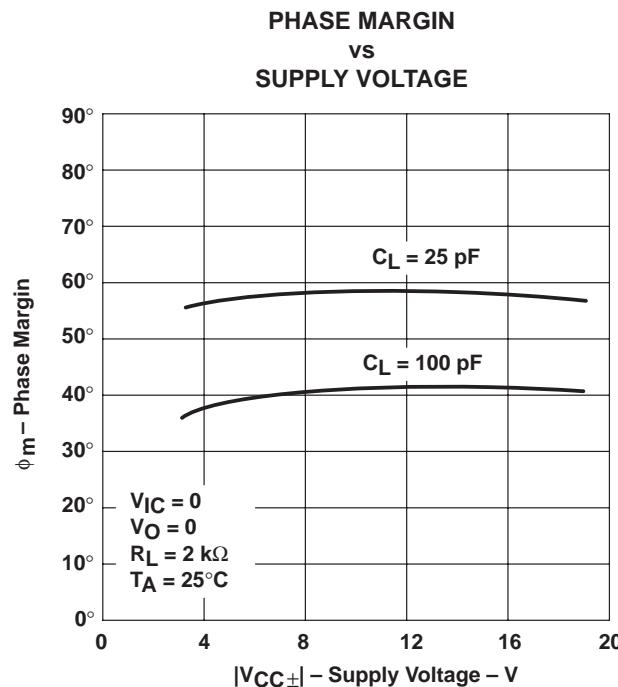


Figure 68

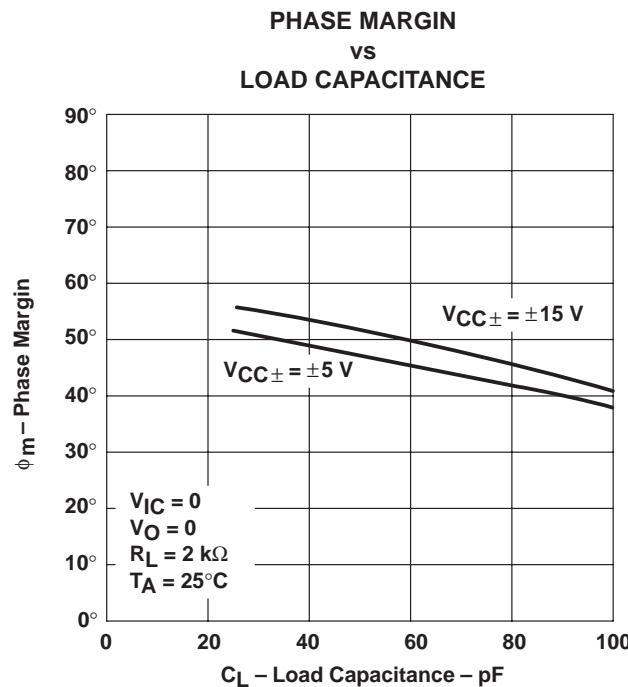


Figure 69

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS[†]

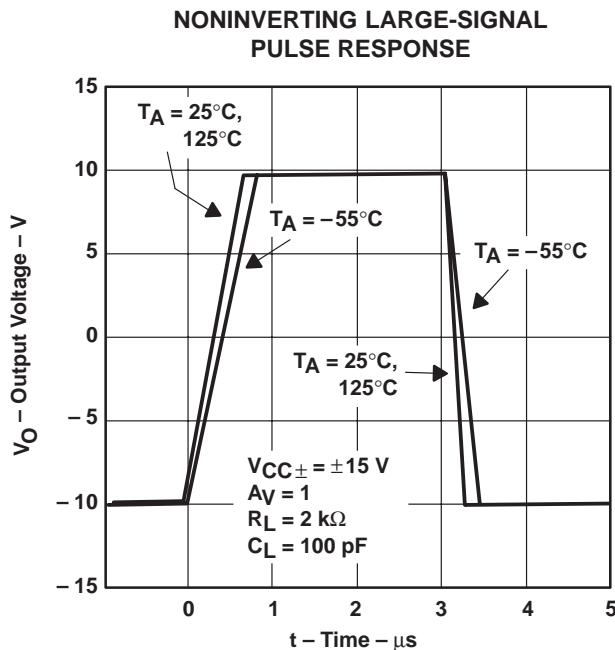


Figure 70

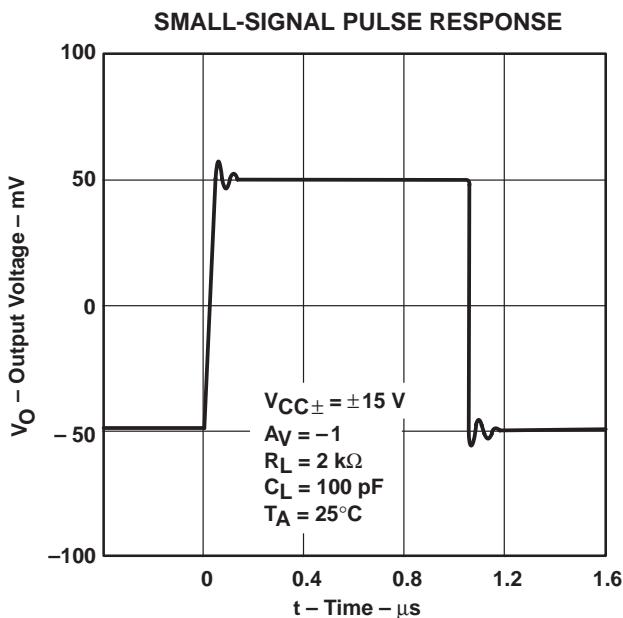


Figure 71

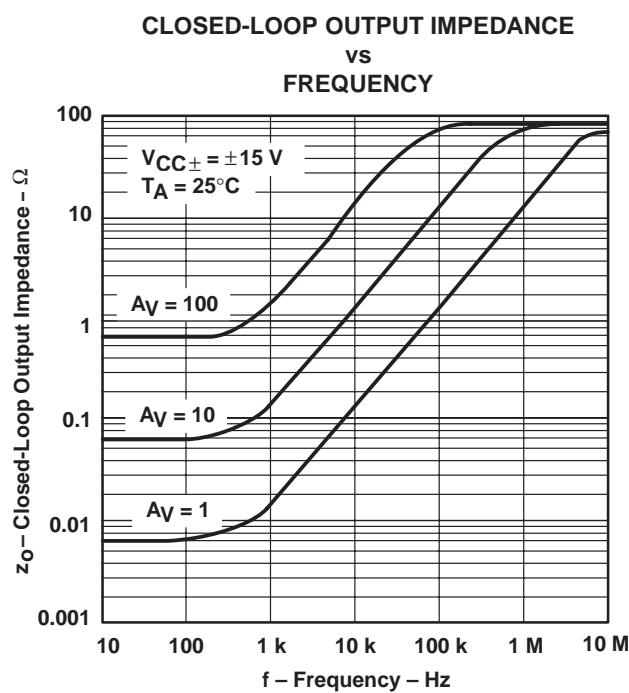


Figure 72

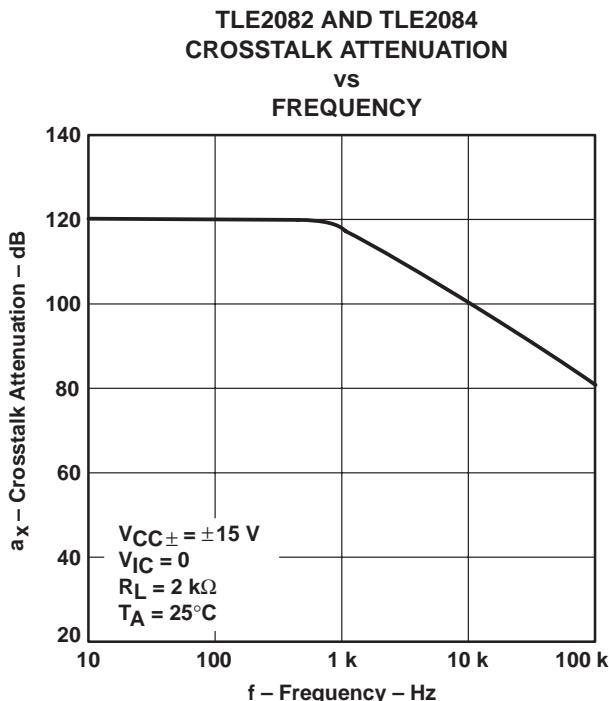


Figure 73

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

**TLE208x, TLE208xA, TLE208xB
EXCALIBUR HIGH-SPEED JFET-INPUT
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APPLICATION INFORMATION

input characteristics

The TLE208x, TLE208xA, and TLE208xB are specified with a minimum and a maximum input voltage that if exceeded at either input could cause the device to malfunction. Because of the extremely high input impedance and resulting low bias current requirements, the TLE208x, TLE208xA, and TLE208xB are well suited for low-level signal processing; however, leakage currents on printed-circuit boards and sockets can easily exceed bias current requirements and cause degradation in system performance. It is good practice to include guard rings around inputs (see Figure 74). These guards should be driven from a low-impedance source at the same voltage level as the common-mode input.

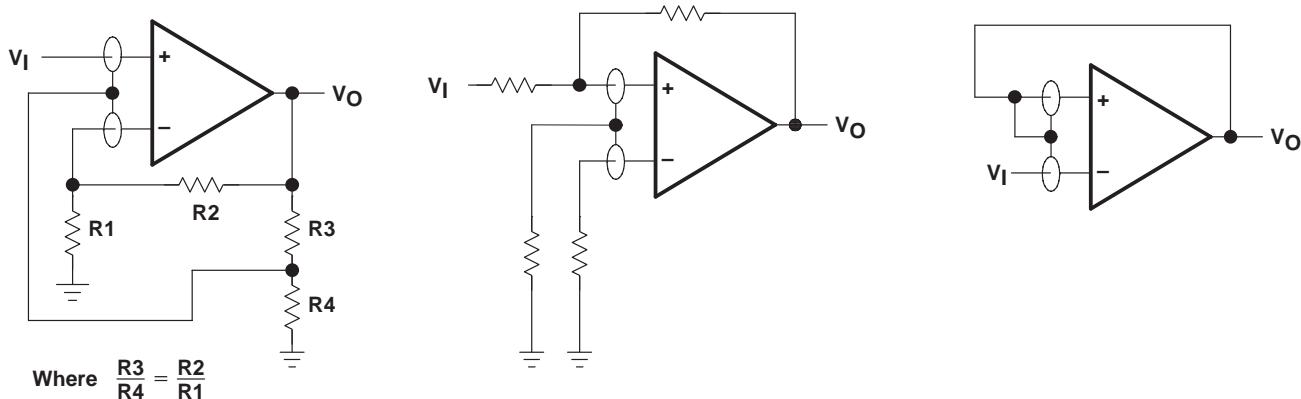


Figure 74. Use of Guard Rings

TLE2081 input offset voltage nulling

The TLE2081 series offers external null pins that can be used to further reduce the input offset voltage. The circuit of Figure 75 can be connected as shown if the feature is desired. When external nulling is not needed, the null pins may be left unconnected.

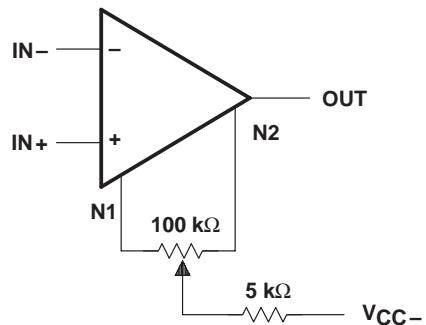


Figure 75. Input Offset Voltage Nulling

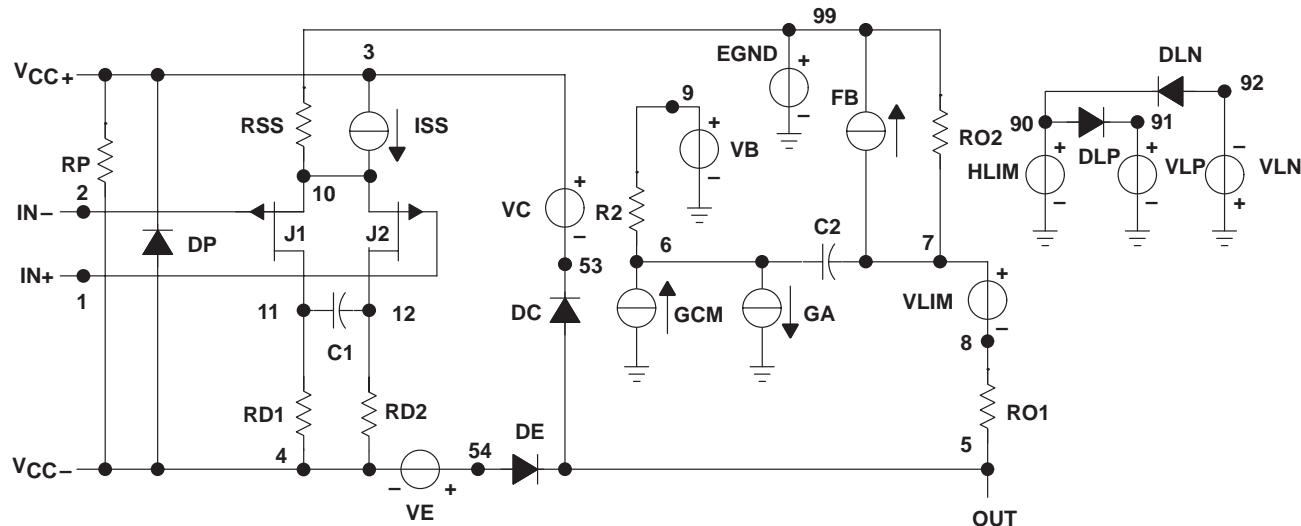
APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using *PSpice™ Parts™* model generation software. The Boyle macromodel (see Note 4) and subcircuit in Figure 58 were generated using the TLE208x typical electrical and operating characteristics at $T_A = 25^\circ\text{C}$. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 4: G.R. Boyle, B.M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).



**TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS**

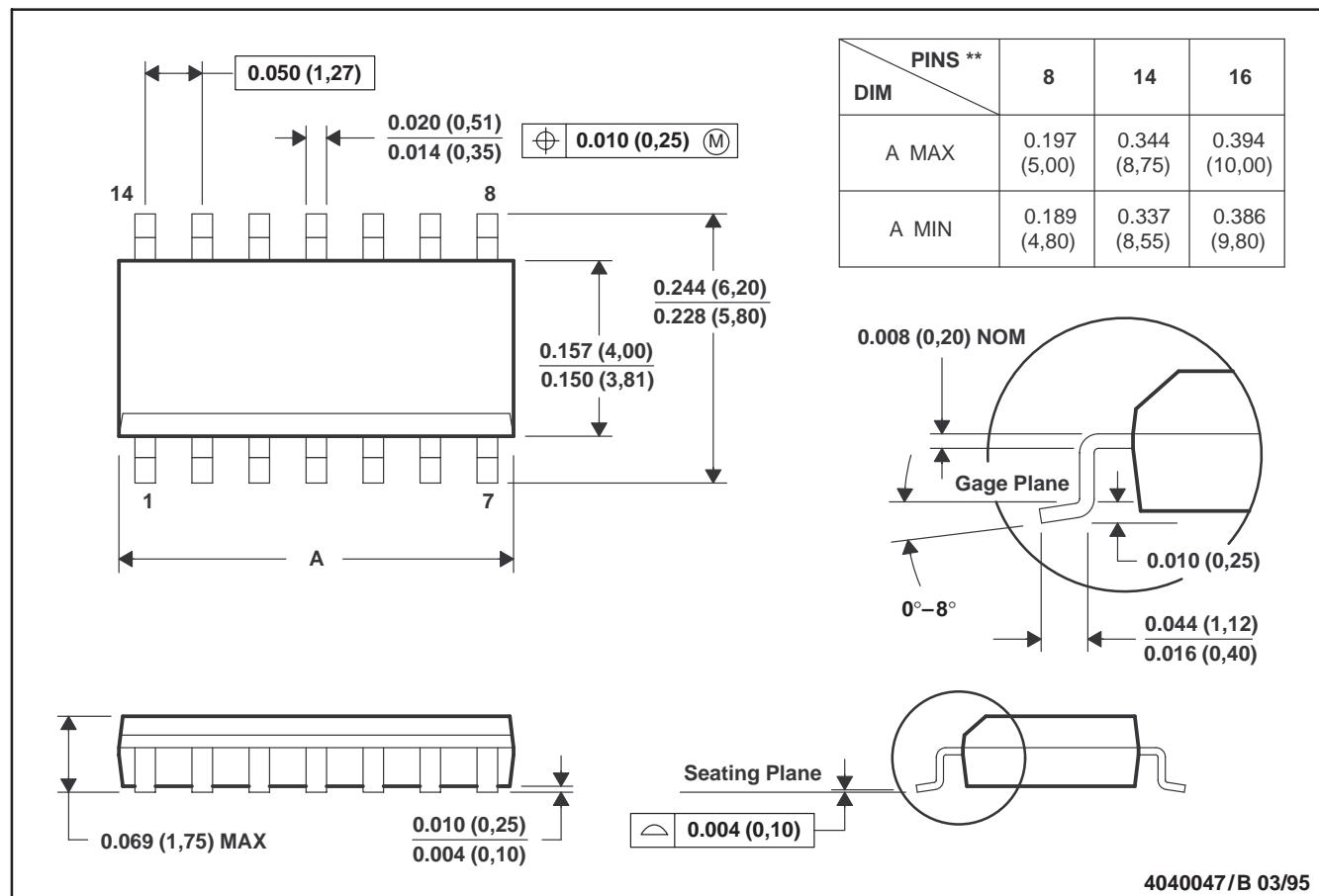
SLOS182 – FEBRUARY 1997

MECHANICAL INFORMATION

D (R-PDSO-G)**

14 PIN SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



4040047/B 03/95

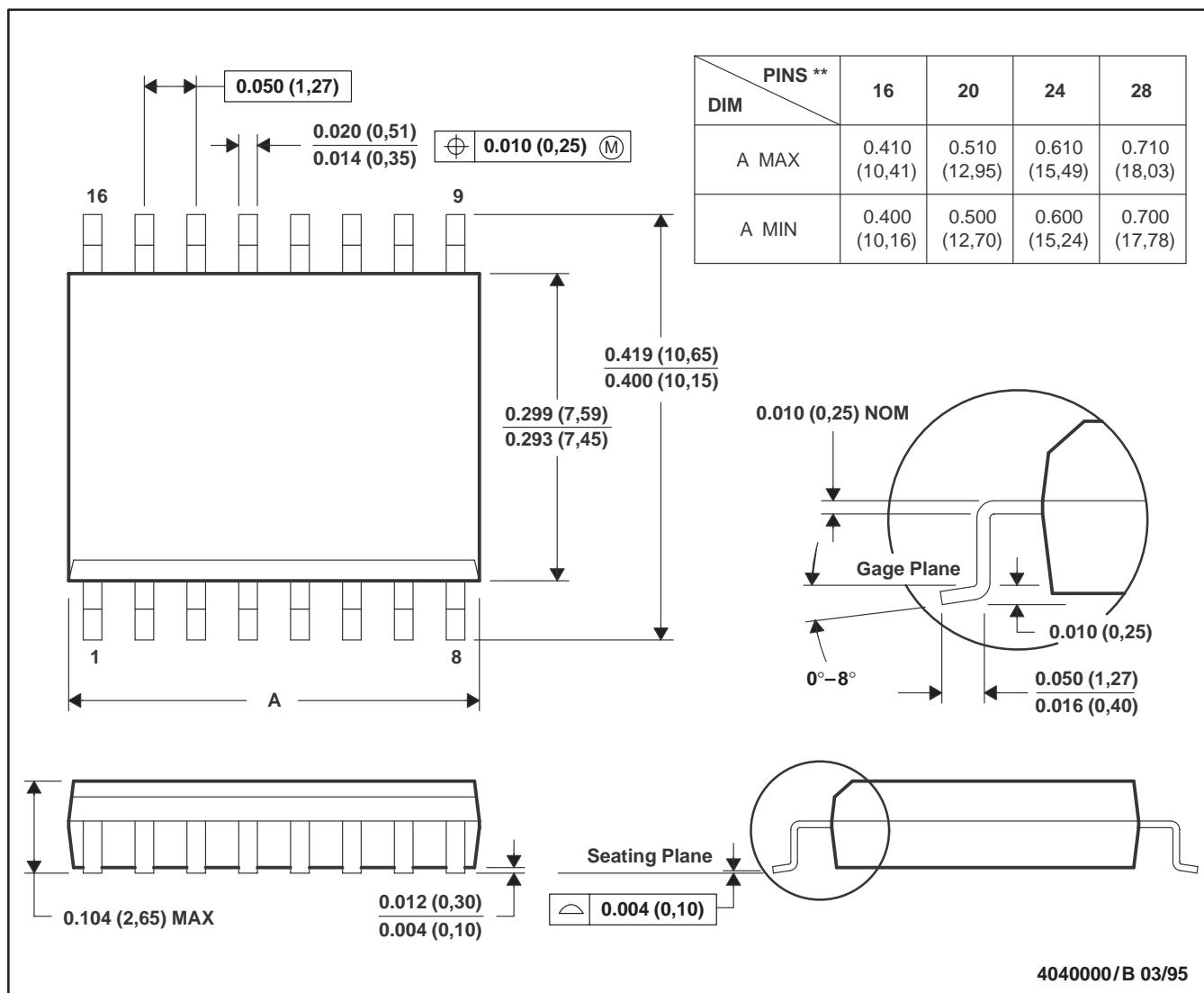
- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
 D. Four center pins are connected to die mount pad.
 E. Falls within JEDEC MS-012

MECHANICAL INFORMATION

DW (R-PDSO-G**)

16 PIN SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - Falls within JEDEC MS-013

**TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS**

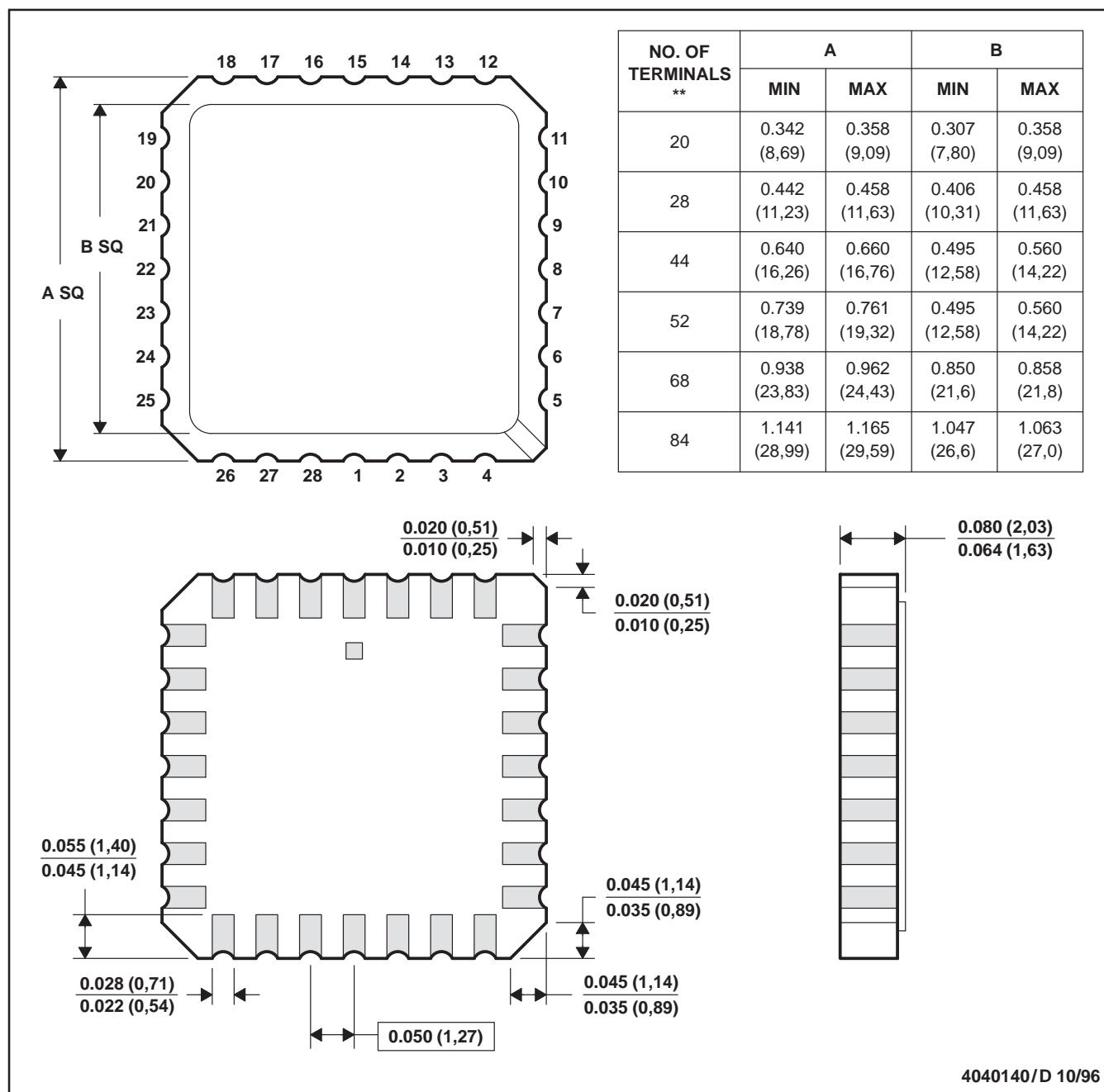
SLOS182 – FEBRUARY 1997

MECHANICAL INFORMATION

FK (S-CQCC-N)**

28 TERMINAL SHOWN

LEADLESS CERAMIC CHIP CARRIER



4040140/D 10/96

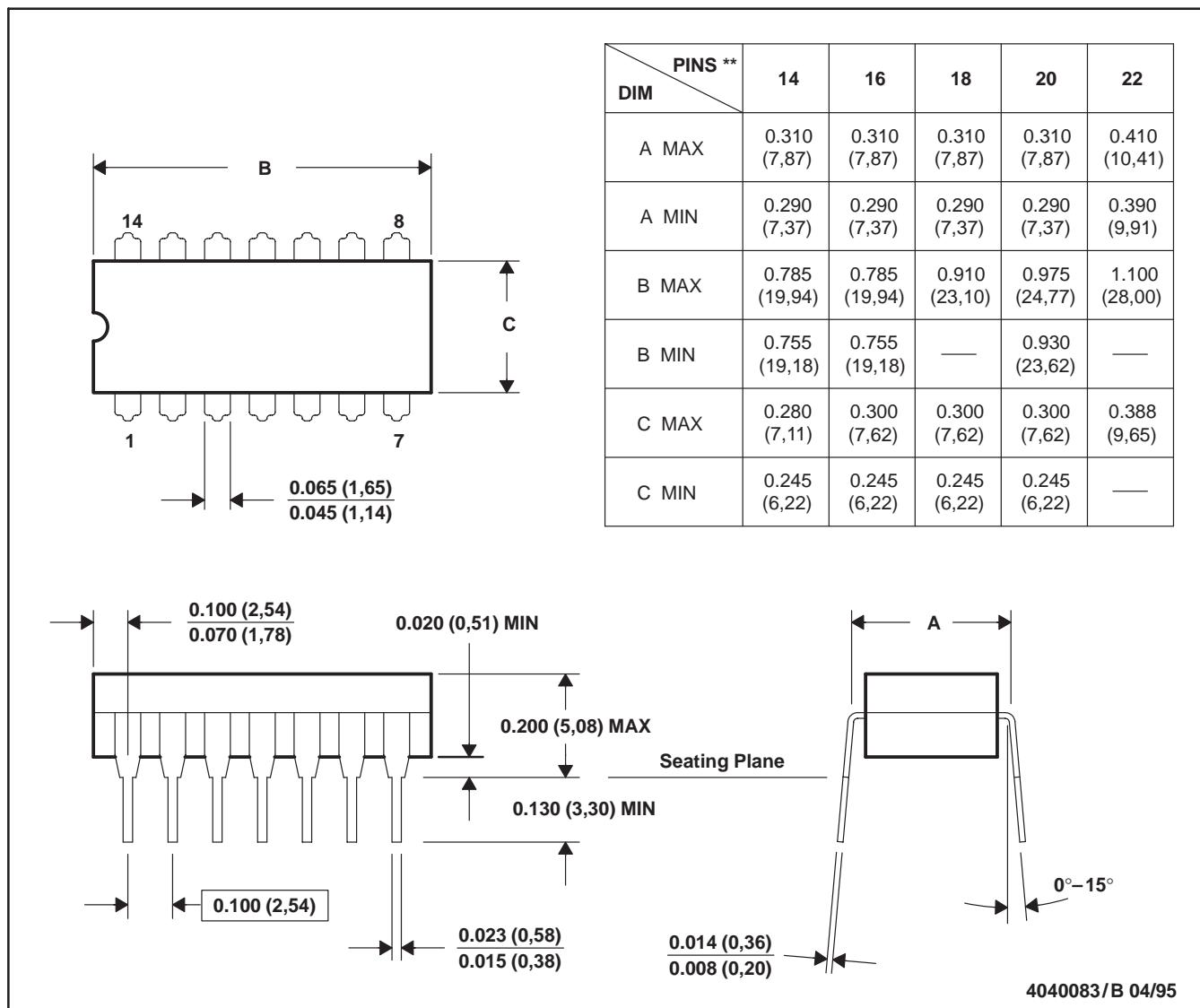
- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. This package can be hermetically sealed with a metal lid.
 D. The terminals are gold plated.
 E. Falls within JEDEC MS-004

MECHANICAL INFORMATION

J (R-GDIP-T)**

CERAMIC DUAL-IN-LINE PACKAGE

14 PIN SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. This package can be hermetically sealed with a ceramic lid using glass frit.
 D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 E. Falls within MIL-STD-1835 GDIP1-T14, GDIP1-T16, GDIP1-T18, GDIP1-T20, and GDIP1-T22

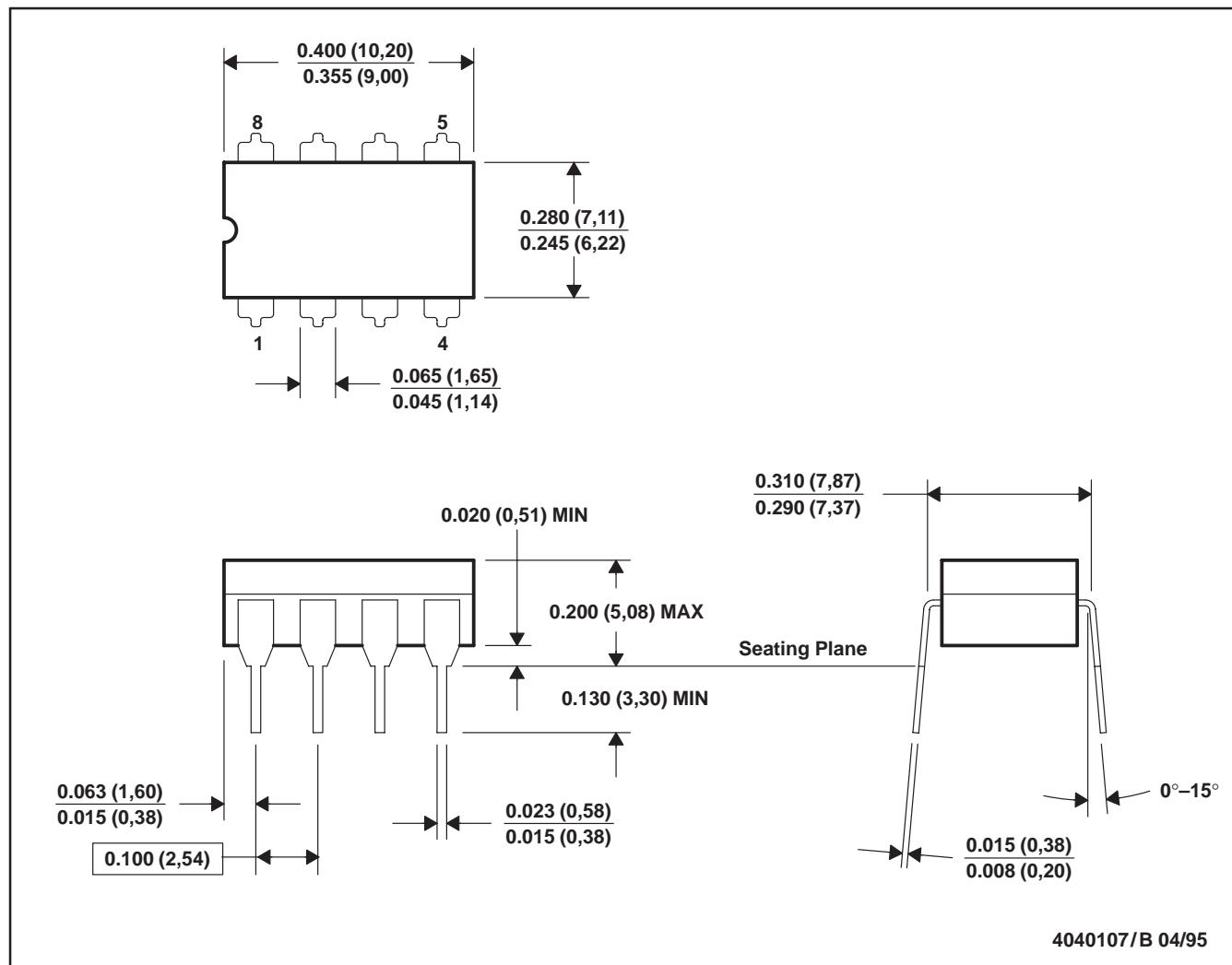
**TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS**

SLOS182 – FEBRUARY 1997

MECHANICAL INFORMATION

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE PACKAGE



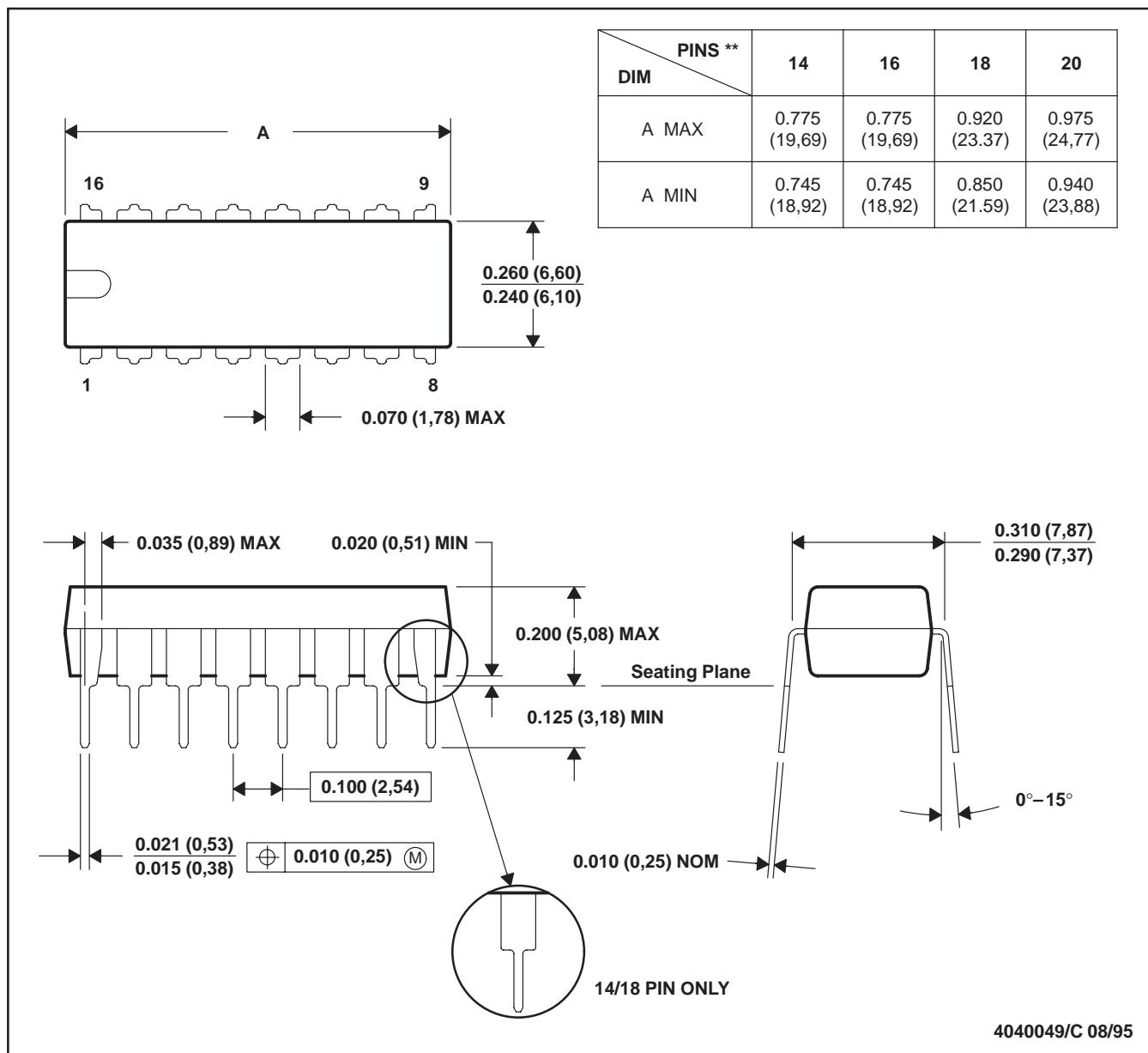
- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - This package can be hermetically sealed with a ceramic lid using glass frit.
 - Index point is provided on cap for terminal identification only on press ceramic glass frit seal only
 - Falls within MIL-STD-1835 GDIP1-T8

MECHANICAL INFORMATION

N (R-PDIP-T)**

16 PIN SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - Falls within JEDEC MS-001 (20 pin package is shorter than MS-001.)

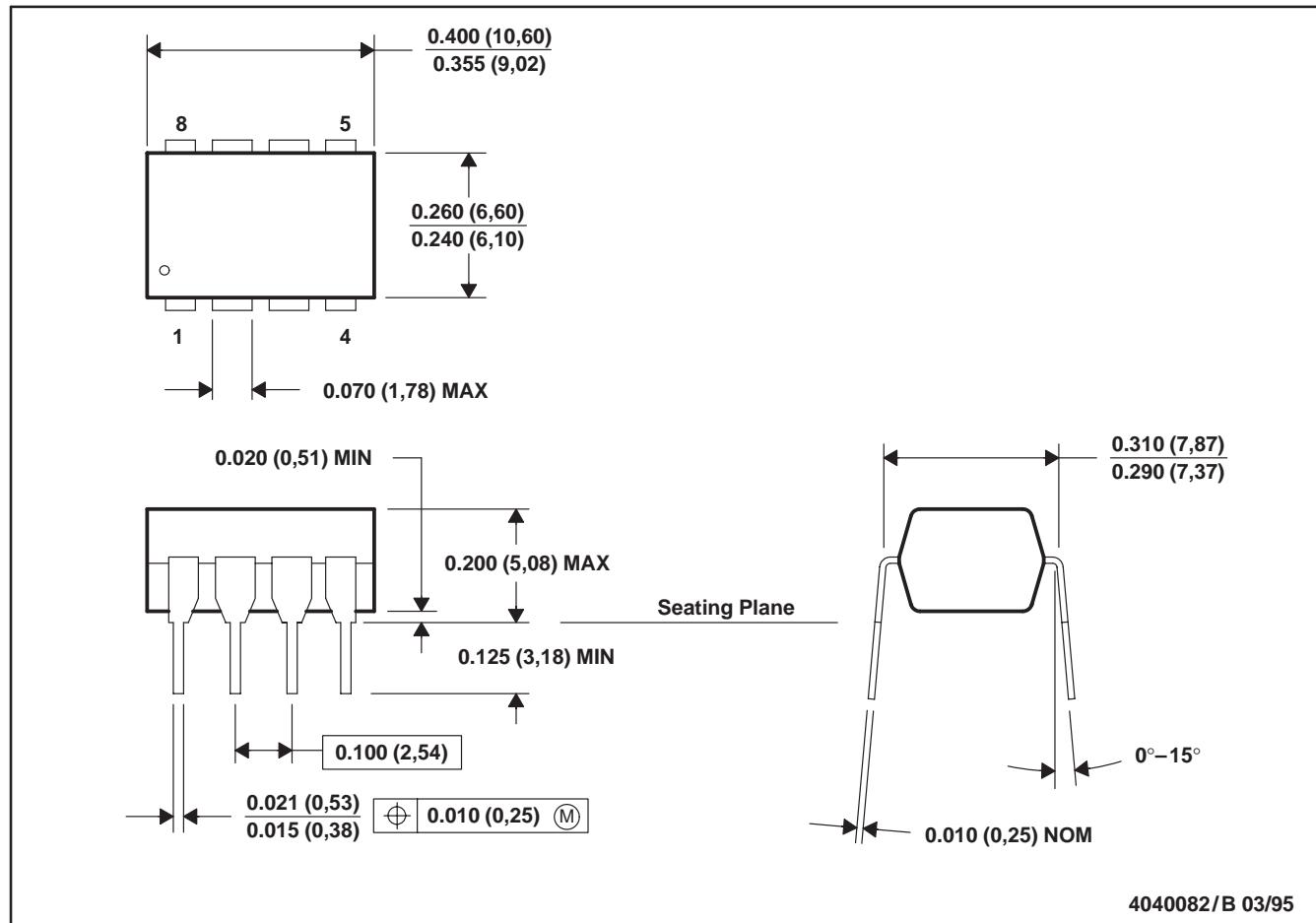
**TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS**

SLOS182 – FEBRUARY 1997

MECHANICAL INFORMATION

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-001

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